

Ultra low power 64 MHz Arm® Cortex®-M23 core, up to 64-KB code flash memory, 8-KB SRAM, 12-bit A/D Converter, High Speed Analog Comparator, Safety features.

## Features

### ■ Arm Cortex-M23 Core

- Armv8-M architecture
- Maximum operating frequency: 64 MHz
- Arm Memory Protection Unit (Arm MPU) with 8 regions
- Debug and Trace: DWT, FPB, CoreSight™ MTB-M23
- CoreSight Debug Port: SW-DP

### ■ Memory

- Up to 64-KB code flash memory
- 2-KB data flash memory (100,000 program/erase (P/E) cycles)
- 8-KB SRAM
- Memory protection units (MPU)
- 128-bit unique ID

### ■ Connectivity

- Serial Communications Interface (SCI) × 4
  - Asynchronous interfaces
  - 8-bit clock synchronous interface
  - Simple IIC
  - Simple SPI
  - Smart card interface
- Serial Peripheral Interface (SPI) × 1
- I<sup>2</sup>C bus interface (IIC) × 1

### ■ Analog

- 12-Bit A/D Converter (ADC12) with 3 sample-and-hold circuits
- Temperature Sensor (TSN)
- High Speed Analog Comparator (ACMPHS) × 2

### ■ Timers

- General PWM Timer 16-bit (GPT16) × 4
- 32-bit Low Power Asynchronous General Purpose Timer (AGTW)  
  × 2
- Watchdog Timer (WDT)

### ■ Safety

- SRAM parity error check
- Flash area protection
- ADC self-diagnosis function
- Clock Frequency Accuracy Measurement Circuit (CAC)
- Cyclic Redundancy Check (CRC) calculator
- Data Operation Circuit (DOC)
- Port Output Enable for GPT (POEG)
- Independent Watchdog Timer (IWDT)
- GPIO readback level detection
- Register write protection
- Main oscillator stop detection
- Illegal memory access detection

### ■ System and Power Management

- Low power modes
- Event Link Controller (ELC)
- Data Transfer Controller (DTC)
- Key Interrupt Function (KINT)
- Power-on reset
- Low Voltage Detection (LVD) with voltage settings

### ■ Multiple Clock Sources

- Main clock oscillator (MOSC) (1 to 20 MHz)
- High-speed on-chip oscillator (HOCO) (24/32/48/64 MHz)
- Middle-speed on-chip oscillator (MOCO) (8 MHz)
- Low-speed on-chip oscillator (LOCO) (32.768 kHz)
- Clock trim function for HOCO/MOCO/LOCO
- IWDT-dedicated on-chip oscillator (15 kHz)
- Clock out support

### ■ Up to 40 pins for general I/O ports

- 5-V tolerance, open drain, input pull-up, switchable driving ability

### ■ Operating Voltage

- VCC: 1.6 to 5.5 V

### ■ Operating Temperature and Packages

- Ta = -40°C to +105°C
  - 48-pin LQFP (7 mm × 7 mm, 0.5 mm pitch)
  - 48-pin HWQFN (7 mm × 7 mm, 0.5 mm pitch)
  - 32-pin LQFP (7 mm × 7 mm, 0.8 mm pitch)
  - 32-pin HWQFN (5 mm × 5 mm, 0.5 mm pitch)
  - 24-pin HWQFN (4 mm × 4 mm, 0.5 mm pitch)
- Ta = -40°C to +125°C
  - 48-pin LQFP (7 mm × 7 mm, 0.5 mm pitch)
  - 48-pin HWQFN (7 mm × 7 mm, 0.5 mm pitch)
  - 32-pin LQFP (7 mm × 7 mm, 0.8 mm pitch)
  - 32-pin HWQFN (5 mm × 5 mm, 0.5 mm pitch)
  - 24-pin HWQFN (4 mm × 4 mm, 0.5 mm pitch)

## 1. Overview

The MCU integrates multiple series of software- and pin-compatible Arm®-based 32-bit cores that share a common set of Renesas peripherals to facilitate design scalability.

The MCU in this series incorporates an energy-efficient Arm Cortex®-M23 32-bit core, that is particularly well suited for cost-sensitive and low-power applications, with the following features:

- Up to 64-KB code flash memory
- 8-KB SRAM
- 12-bit A/D Converter (ADC12)

### 1.1 Function Outline

**Table 1.1 Arm core**

Feature	Functional description
Arm Cortex-M23 core	<ul style="list-style-type: none"> <li>● Maximum operating frequency: up to 64 MHz</li> <li>● Arm Cortex-M23 core: <ul style="list-style-type: none"> <li>– Revision: r1p0-00rel0</li> <li>– Armv8-M architecture profile</li> <li>– Single-cycle integer multiplier</li> <li>– 19-cycle integer divider</li> </ul> </li> <li>● Arm Memory Protection Unit (Arm MPU): <ul style="list-style-type: none"> <li>– Armv8 Protected Memory System Architecture</li> <li>– 8 protect regions</li> </ul> </li> <li>● SysTick timer: <ul style="list-style-type: none"> <li>– Driven by SYSTICKCLK (LOCO) or ICLK</li> </ul> </li> </ul>

**Table 1.2 Memory**

Feature	Functional description
Code flash memory	Maximum 64-KB of code flash memory.
Data flash memory	2-KB of data flash memory.
Option-setting memory	The option-setting memory determines the state of the MCU after a reset.
SRAM	On-chip high-speed SRAM with parity bit.

**Table 1.3 System (1 of 2)**

Feature	Functional description
Operating modes	Two operating modes: <ul style="list-style-type: none"> <li>● Single-chip mode</li> <li>● SCI boot mode</li> </ul>
Resets	The MCU provides 12 resets (RES pin reset, power-on reset, independent watchdog timer reset, watchdog timer reset, voltage monitor 0/1/2 resets, SRAM parity error reset, bus master/slave MPU error resets, CPU stack pointer error reset, software reset).
Low Voltage Detection (LVD)	The Low Voltage Detection (LVD) module monitors the voltage level input to the VCC pin. The detection level can be selected by register settings. The LVD module consists of three separate voltage level detectors (LVD0, LVD1, LVD2). LVD0, LVD1, and LVD2 measure the voltage level input to the VCC pin. LVD registers allow your application to configure detection of VCC changes at various voltage thresholds.
Clocks	<ul style="list-style-type: none"> <li>● Main clock oscillator (MOSC)</li> <li>● High-speed on-chip oscillator (HOCO)</li> <li>● Middle-speed on-chip oscillator (MOCO)</li> <li>● Low-speed on-chip oscillator (LOCO)</li> <li>● IWDT-dedicated on-chip oscillator</li> <li>● Clock out support</li> </ul>

**Table 1.3 System (2 of 2)**

Feature	Functional description
Clock Frequency Accuracy Measurement Circuit (CAC)	The Clock Frequency Accuracy Measurement Circuit (CAC) counts pulses of the clock to be measured (measurement target clock) within the time generated by the clock selected as the measurement reference (measurement reference clock), and determines the accuracy depending on whether the number of pulses is within the allowable range. When measurement is complete or the number of pulses within the time generated by the measurement reference clock is not within the allowable range, an interrupt request is generated.
Interrupt Controller Unit (ICU)	The Interrupt Controller Unit (ICU) controls which event signals are linked to the Nested Vector Interrupt Controller (NVIC), and the Data Transfer Controller (DTC) modules. The ICU also controls non-maskable interrupts.
Key Interrupt Function (KINT)	The key interrupt function (KINT) generates the key interrupt by detecting rising or falling edge on the key interrupt input pins.
Low power modes	Power consumption can be reduced in multiple ways, including setting clock dividers, stopping modules, selecting power control mode in normal operation, and transitioning to low power modes.
Register write protection	The register write protection function protects important registers from being overwritten due to software errors. The registers to be protected are set with the Protect Register (PRCR).
Memory Protection Unit (MPU)	The MCU has four Memory Protection Units (MPUs) and a CPU stack pointer monitor function are provided.
Watchdog Timer (WDT)	The Watchdog Timer (WDT) is a 14-bit down counter that can be used to reset the MCU when the counter underflows because the system has run out of control and is unable to refresh the WDT. In addition, the WDT can be used to generate a non-maskable interrupt or an underflow interrupt or watchdog timer reset.
Independent Watchdog Timer (IWDT)	The Independent Watchdog Timer (IWDT) consists of a 14-bit down counter that must be serviced periodically to prevent counter underflow. The IWDT provides functionality to reset the MCU or to generate a non-maskable interrupt or an underflow interrupt. Because the timer operates with an independent, dedicated clock source, it is particularly useful in returning the MCU to a known state as a fail-safe mechanism when the system runs out of control. The IWDT can be triggered automatically by a reset, underflow, refresh error, or a refresh of the count value in the registers.

**Table 1.4 Event link**

Feature	Functional description
Event Link Controller (ELC)	The Event Link Controller (ELC) uses the event requests generated by various peripheral modules as source signals to connect them to different modules, allowing direct link between the modules without CPU intervention.

**Table 1.5 Direct memory access**

Feature	Functional description
Data Transfer Controller (DTC)	A Data Transfer Controller (DTC) module is provided for transferring data when activated by an interrupt request.

**Table 1.6 Timers**

Feature	Functional description
General PWM Timer (GPT)	The General PWM Timer (GPT) is a 16-bit timer with GPT16 × 4 channels. PWM waveforms can be generated by controlling the up-counter, down-counter, or the up- and down-counter. In addition, PWM waveforms can be generated for controlling brushless DC motors. The GPT can also be used as a general-purpose timer.
Port Output Enable for GPT (POEG)	The POEG issues requests to stop output from output pins of the general PWM timer (GPT).
Low power Asynchronous General Purpose Timer (AGTW)	The Low Power Asynchronous General Purpose Timer (AGTW) is a 32-bit timer that can be used for pulse output, external pulse width or period measurement, and counting external events. This timer consists of a reload register and a down counter. The reload register and the down counter are allocated to the same address, and can be accessed with the AGTW register.

**Table 1.7 Communication interfaces**

Feature	Functional description
Serial Communications Interface (SCI)	<p>The Serial Communications Interface (SCI) × 4 channels have asynchronous and synchronous serial interfaces:</p> <ul style="list-style-type: none"> <li>Asynchronous interfaces (UART and Asynchronous Communications Interface Adapter (ACIA))</li> <li>8-bit clock synchronous interface</li> <li>Simple IIC (master-only)</li> <li>Simple SPI</li> <li>Smart card interface</li> </ul> <p>The smart card interface complies with the ISO/IEC 7816-3 standard for electronic signals and transmission protocol. SCIn (n = 0) has FIFO buffers to enable continuous and full-duplex communication, and the data transfer speed can be configured independently using an on-chip baud rate generator.</p>
I <sup>2</sup> C bus interface (IIC)	The I <sup>2</sup> C bus interface (IIC) has 1 channel. The IIC module conforms with and provides a subset of the NXP I <sup>2</sup> C (Inter-Integrated Circuit) bus interface functions.
Serial Peripheral Interface (SPI)	The Serial Peripheral Interface (SPI) has 1 channel. The SPI provides high-speed full-duplex synchronous serial communications with multiple processors and peripheral devices.

**Table 1.8 Analog**

Feature	Functional description
12-bit A/D Converter (ADC12)	A 12-bit successive approximation A/D converter is provided. Up to 13 analog input channels are selectable. Temperature sensor output and internal reference voltage are selectable for conversion.
Temperature Sensor (TSN)	The on-chip Temperature Sensor (TSN) determines and monitors the die temperature for reliable operation of the device. The sensor outputs a voltage directly proportional to the die temperature, and the relationship between the die temperature and the output voltage is fairly linear. The output voltage is provided to the ADC12 for conversion and can be further used by the end application.
High-Speed Analog Comparator (ACMPHS)	The High-Speed Analog Comparator (ACMPHS) compares a reference input voltage with an analog input voltage. Comparator channels ACMPHS0 and ACMPHS1 are independent of each other. The comparison result of the reference input voltage and analog input voltage can be read by software. The comparison result can also be output externally. The reference input voltage can be selected from an input to the CMPREF <sub>i</sub> ( <sub>i</sub> = 0, 1) pin, input to the CMPIN <sub>Oj</sub> ( <sub>j</sub> = 0, 1, 2) pin or the internal reference voltage ( $V_{ref}$ ) generated internally in the MCU.

**Table 1.9 Data processing**

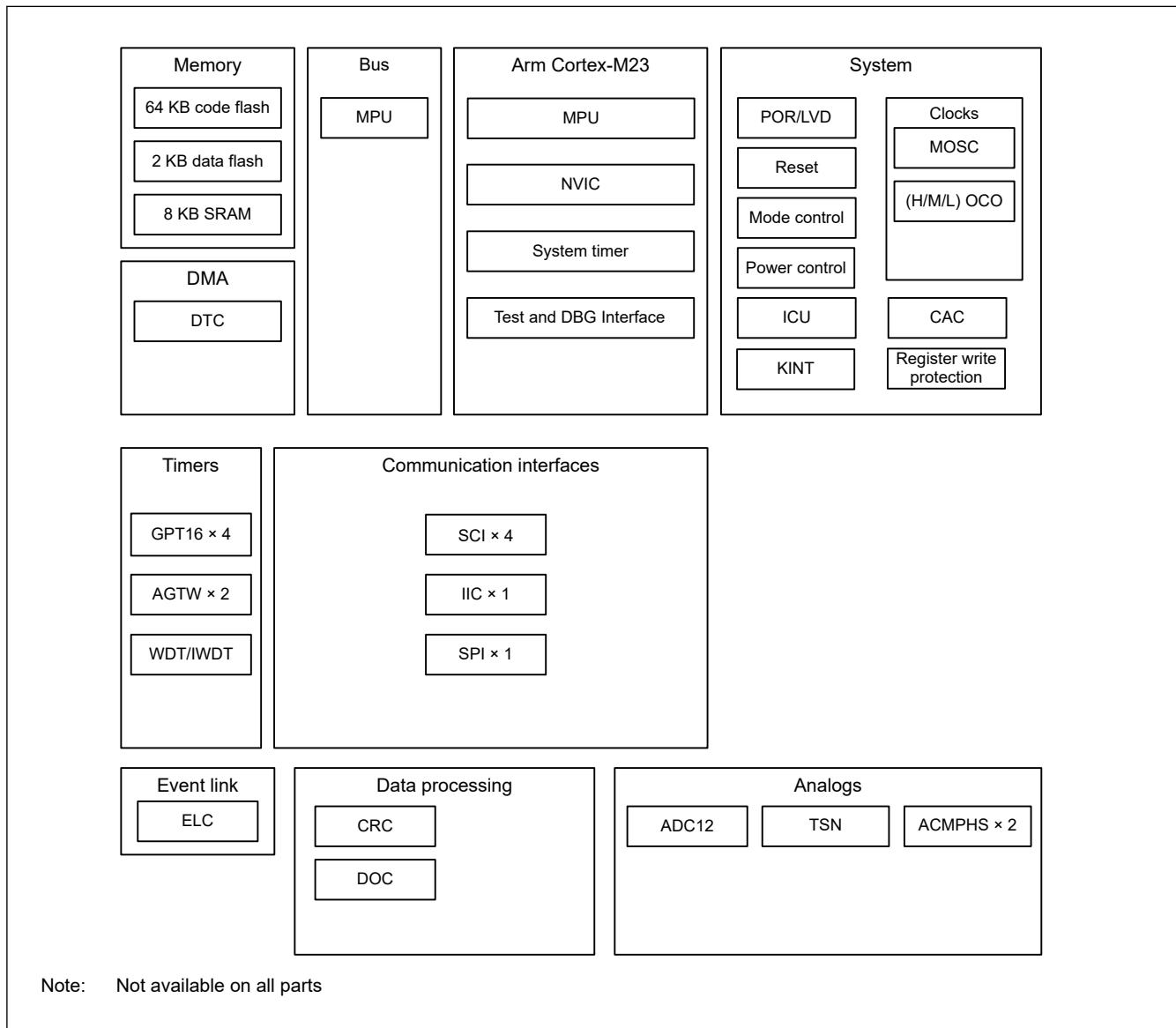
Feature	Functional description
Cyclic Redundancy Check (CRC) calculator	The Cyclic Redundancy Check (CRC) generates CRC codes to detect errors in the data. The bit order of CRC calculation results can be switched for LSB-first or MSB-first communication. Additionally, various CRC-generation polynomials are available. The snoop function allows to monitor the access to specific addresses. This function is useful in applications that require CRC code to be generated automatically in certain events, such as monitoring writes to the serial transmit buffer and reads from the serial receive buffer.
Data Operation Circuit (DOC)	The Data Operation Circuit (DOC) compares, adds, and subtracts 16-bit data. When a selected condition applies, 16-bit data is compared and an interrupt can be generated.

**Table 1.10 I/O ports**

Feature	Functional description
I/O ports	<ul style="list-style-type: none"><li>● I/O ports for the 48-pin LQFP/HWQFN<ul style="list-style-type: none"><li>– I/O pins: 39</li><li>– Input pins: 1</li><li>– Pull-up resistors: 39</li><li>– N-ch open-drain outputs: 28</li><li>– 5-V tolerance: 2</li></ul></li><li>● I/O ports for the 32-pin LQFP/HWQFN<ul style="list-style-type: none"><li>– I/O pins: 25</li><li>– Input pins: 1</li><li>– Pull-up resistors: 25</li><li>– N-ch open-drain outputs: 17</li></ul></li><li>● I/O ports for the 24-pin HWQFN<ul style="list-style-type: none"><li>– I/O pins: 17</li><li>– Input pins: 1</li><li>– Pull-up resistors: 17</li><li>– N-ch open-drain outputs: 10</li></ul></li></ul>

## 1.2 Block Diagram

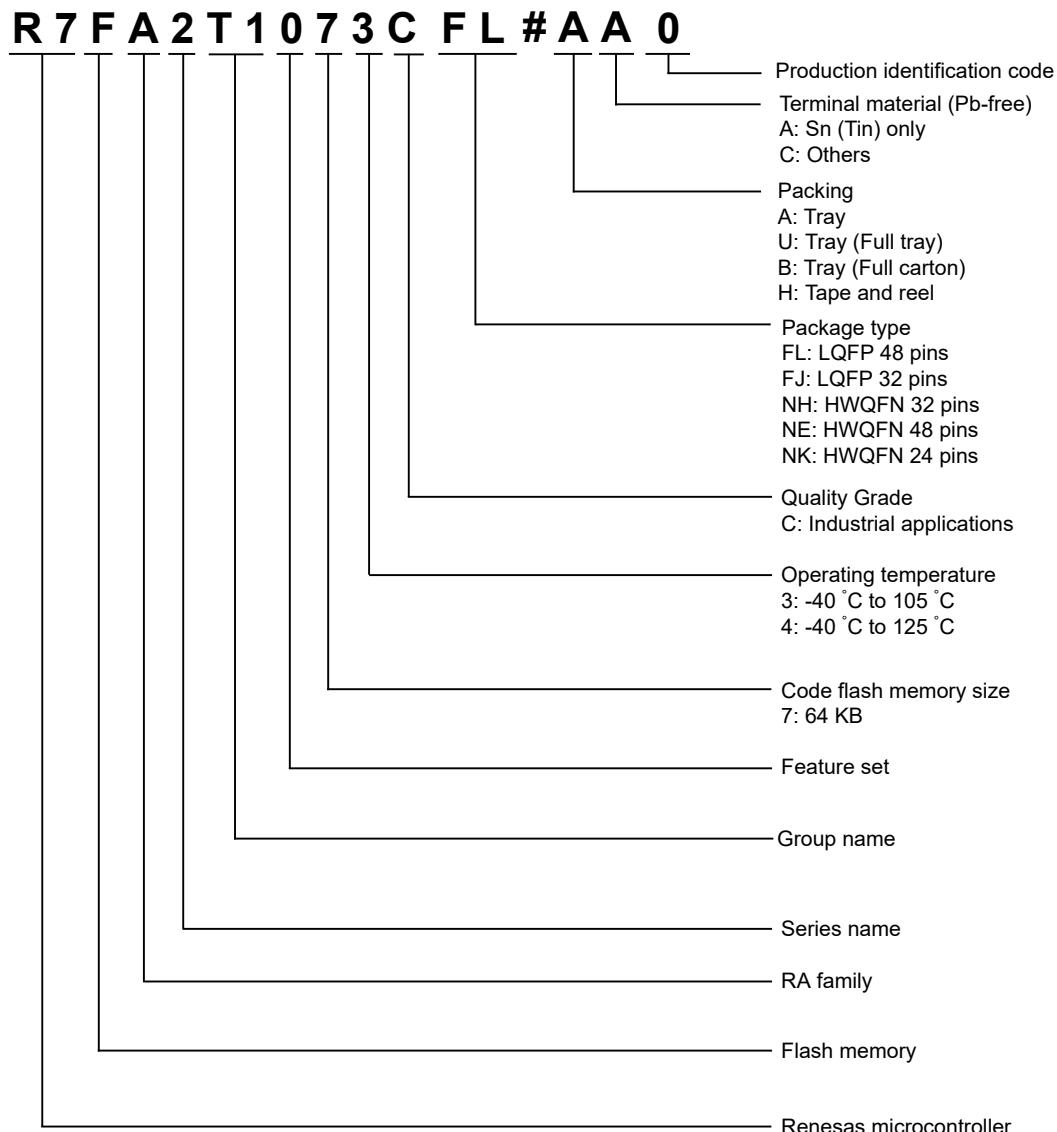
[Figure 1.1](#) shows a block diagram of the MCU superset. Some individual devices within the group have a subset of the features.



**Figure 1.1 Block diagram**

## 1.3 Part Numbering

[Figure 1.2](#) shows the product part number information, including memory capacity and package type. [Table 1.11](#) shows a list of products.



Note: Check the order screen for each product on the Renesas website for valid symbols after the #.

**Figure 1.2 Part numbering scheme**

**Table 1.11 Product list**

<b>Product part number</b>	<b>Package code</b>	<b>Code flash</b>	<b>Data flash</b>	<b>SRAM</b>	<b>Operating temperature</b>
R7FA2T1073CFL	PLQP0048KB-B	64	2	8	-40 to +105 °C
R7FA2T1073CFJ	PLQP0032GB-A				-40 to +125 °C
R7FA2T1073CNH	PWQN0032KE-A				
R7FA2T1073CNE	PWQN0048KC-A				
R7FA2T1073CNK	PWQN0024KG-A				
R7FA2T1074CFL	PLQP0048KB-B				
R7FA2T1074CFJ	PLQP0032GB-A				
R7FA2T1074CNH	PWQN0032KE-A				
R7FA2T1074CNE	PWQN0048KC-A				
R7FA2T1074CNK	PWQN0024KG-A				

## 1.4 Function Comparison

**Table 1.12 Function comparison**

Parts number	R7FA2T107xxFL	R7FA2T107xxNE	R7FA2T107xxFJ	R7FA2T107xxNH	R7FA2T107xCNK
Pin count	48		32		24
Package	LQFP	WQFN	LQFP	WQFN	WQFN
Code flash memory			64 KB		
Data flash memory			2 KB		
SRAM			8 KB		
System	CPU clock		64 MHz		
	ICU		Yes		
	KINT	5		4	
Event control	ELC		Yes		
DMA	DTC		Yes		
Timers	GPT (POEG)		2		
	GPT16		4		
	AGTW		2		
	WDT/IWDT		Yes		
Communication	SCI		4		
	IIC		1		
	SPI		1		
Analog	ADC12	13		10	9
	ACMPHS		2		
	TSN		Yes		
Data processing	CRC		Yes		
	DOC		Yes		
I/O ports	I/O pins	39		25	17
	Input pins		1		
	Pull-up resistors	39		25	17
	N-ch open-drain outputs	28		17	10
	5-V tolerance	2		0	0

## 1.5 Pin Functions

**Table 1.13 Pin functions (1 of 3)**

Function	Signal	I/O	Description
Power supply	VCC	Input	Power supply pin. Connect it to the system power supply. Connect this pin to VSS by a 0.1- $\mu$ F capacitor. Place the capacitor close to the pin.
	VCL	I/O	Connect this pin to the VSS pin by the smoothing capacitor used to stabilize the internal power supply. Place the capacitor close to the pin.
	VSS	Input	Ground pin. Connect it to the system power supply (0 V).
Clock	XTAL	Output	Pins for a crystal resonator. An external clock signal can be input through the EXTAL pin.
	EXTAL	Input	
	CLKOUT	Output	Clock output pin
Operating mode control	MD	Input	Pin for setting the operating mode. The signal level on this pin must not be changed during operation mode transition or release from the reset state.
System control	RES	Input	Reset signal input pin. The MCU enters the reset state when this signal goes low.
CAC	CACREF	Input	Measurement reference clock input pin
On-chip debug	SWDIO	I/O	Serial wire debug data input/output pin
	SWCLK	Input	Serial wire clock pin
Interrupt	NMI	Input	Non-maskable interrupt request pin
	IRQ0 to IRQ7	Input	Maskable interrupt request pins
GPT16	GTETRGA, GTETRGB	Input	External trigger input pins
	GTADSM0	Output	A/D conversion start request monitor 0 output pin
	GTADSM1	Output	A/D conversion start request monitor 1 output pin
	GTIOCnA, GTIOCnB	I/O	Input capture, output compare, or PWM output pins
	GTCPPOK	Output	Toggle output synchronized with PWM period
	GTIU	Input	Hall sensor input pin U
	GTIV	Input	Hall sensor input pin V
	GTIW	Input	Hall sensor input pin W
	GTOUUP	Output	3-phase PWM output for BLDC motor control (positive U phase)
	GTOULO	Output	3-phase PWM output for BLDC motor control (negative U phase)
	GTOVUP	Output	3-phase PWM output for BLDC motor control (positive V phase)
	GTOVLO	Output	3-phase PWM output for BLDC motor control (negative V phase)
AGTW	GTOWUP	Output	3-phase PWM output for BLDC motor control (positive W phase)
	GTOWLO	Output	3-phase PWM output for BLDC motor control (negative W phase)
	AGTEE0, AGTEE1	Input	External event input enable signals
	AGTIO0, AGTIO1	I/O	External event input and pulse output pins
	AGTO0	Output	Pulse output pins
AGTOA0, AGTOA1	AGTOA0, AGTOA1	Output	Output compare match A output pins
	AGTOB0	Output	Output compare match B output pins

**Table 1.13 Pin functions (2 of 3)**

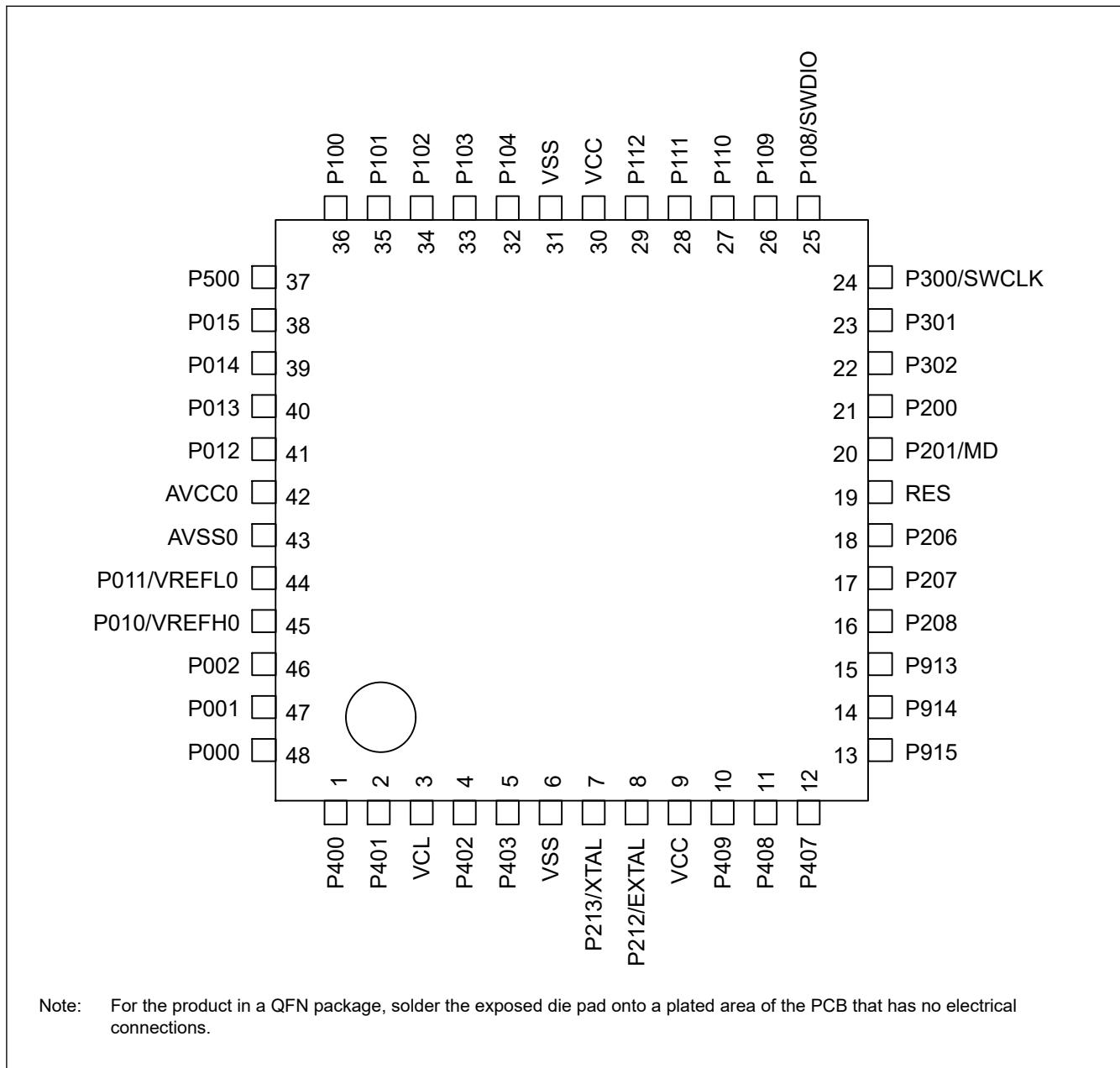
Function	Signal	I/O	Description
SCI	SCKn (n = 0 to 2, 9)	I/O	Input/output pins for the clock (clock synchronous mode)
	RXDn (n = 0 to 2, 9)	Input	Input pins for received data (asynchronous mode/clock synchronous mode)
	TXDn (n = 0 to 2, 9)	Output	Output pins for transmitted data (asynchronous mode/clock synchronous mode)
	CTSn_RTn (n = 0 to 2, 9)	I/O	Input/output pins for controlling the start of transmission and reception (asynchronous mode/clock synchronous mode), active-low.
	SCLn (n = 0 to 2, 9)	I/O	Input/output pins for the IIC clock (simple IIC mode)
	SDAn (n = 0 to 2, 9)	I/O	Input/output pins for the IIC data (simple IIC mode)
	SCKn (n = 0 to 2, 9)	I/O	Input/output pins for the clock (simple SPI mode)
	MISOn (n = 0 to 2, 9)	I/O	Input/output pins for slave transmission of data (simple SPI mode)
	MOSIn (n = 0 to 2, 9)	I/O	Input/output pins for master transmission of data (simple SPI mode)
	SSn (n = 0 to 2, 9)	Input	Chip-select input pins (simple SPI mode), active-low
IIC	SCLn (n = 0)	I/O	Input/output pins for the clock
	SDAn (n = 0)	I/O	Input/output pins for data
SPI	RSPCKA	I/O	Clock input/output pin
	SSLA0	I/O	Input or output pin for slave selection
	SSLA1	Output	Output pins for slave selection
	MOSIA	I/O	Input or output pins for data output from the master
	MISOA	I/O	Input or output pins for data output from the slave
Analog power supply	AVCC0	Input	Analog power supply pin for the ADC12
	AVSS0	Input	Analog ground pin for the ADC12
	VREFH0	Input	Analog reference voltage supply pin for the ADC12. Connect this pin to AVCC0 when not using the ADC12.
	VREFL0	Input	Analog reference ground pin for the ADC12. Connect this pin to AVSS0 when not using the ADC12.
ADC12	AN000 to AN002 (3ch S/H), AN005 to AN010, AN019 to AN022	Input	Input pins for the analog signals to be processed by the A/D converter.
	ADTRG0_A, ADTRG0_B	Input	Input pin for the external trigger signals that start the A/D conversion, active-low.
KINT	KR00 to KR04	Input	Key interrupt input pins
I/O ports	P000 to P002, P010 to P015	I/O	General-purpose input/output pins
	P100 to P104, P108 to P112	I/O	General-purpose input/output pins
	P200	Input	General-purpose input pin
	P201, P206 to P208, P212, P213	I/O	General-purpose input/output pins
	P300 to P302	I/O	General-purpose input/output pins
	P400 to P403, P407 to P409	I/O	General-purpose input/output pins
	P500	I/O	General-purpose input/output pins
	P913 to P915	I/O	General-purpose input/output pins

**Table 1.13 Pin functions (3 of 3)**

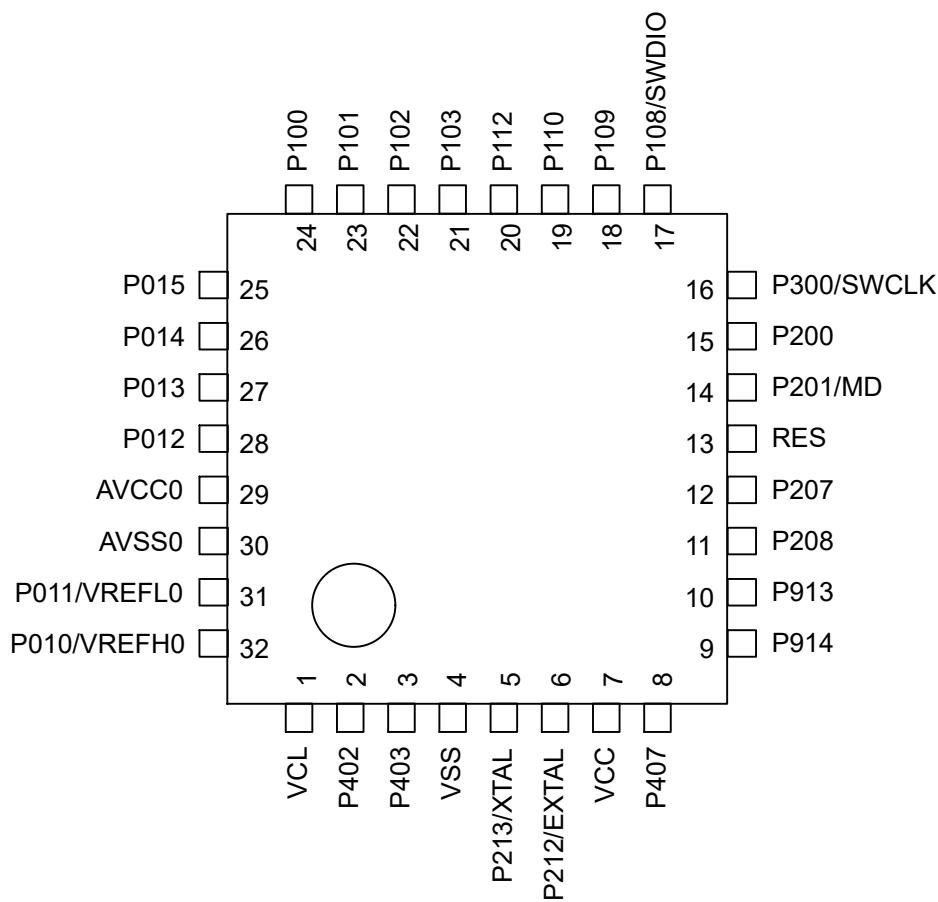
Function	Signal	I/O	Description
ACMPHS	CMPIN0n (n = 1, 2, 3), CMPIN1	Input	Reference and Analog voltage input pin
	CMPREFn (n = 0, 1)	Input	Reference and Analog voltage input pin
	VCOUT	Output	ACMPHS0 and ACMPHS1 compare outputs are bundled on the VCOUT pin

## 1.6 Pin Assignments

[Figure 1.3](#) to [Figure 1.5](#) show the pin assignments from the top view.

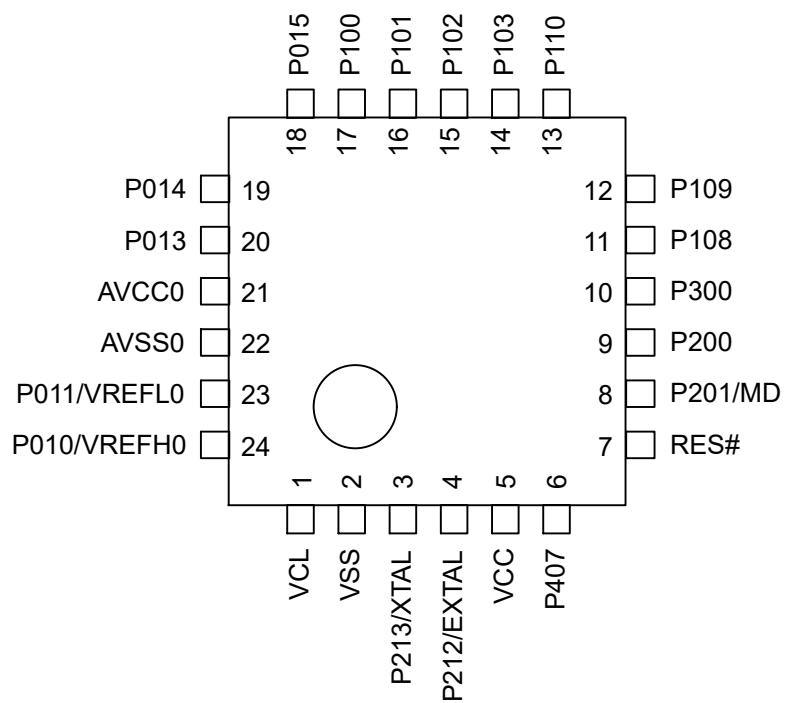


**Figure 1.3 Pin assignment for LQFP/QFN 48-pin (top view)**



Note: For the product in a QFN package, solder the exposed die pad onto a plated area of the PCB that has no electrical connections.

**Figure 1.4 Pin assignment for LQFP/QFN 32-pin (top view)**



Note: For the product in a QFN package, solder the exposed die pad onto a plated area of the PCB that has no electrical connections.

**Figure 1.5 Pin assignment for QFN 24-pin (top view)**

## 1.7 Pin Lists

**Table 1.14 Pin list (1 of 2)**

Pin number	LQFP/QFN 48-pin	LQFP/QFN 32-pin	LQFP/QFN 24-pin	Power, System, Clock, Debug, CAC	I/O ports	Timers			Communication interfaces			Analogs		HMI
						AGTW	GPT_OPS, POEG	GPT	SCI	IIC	SPI	ADC	ACMPHS	Interrupt
1	—	—	—	CACREF_C	P400	AGTIO1_C	—	GTIOC3A_B	SCK0_B/ SCK1_B	SCL0_A	—	—	—	IRQ0_A
2	—	—	—		P401	—	GTETRGA_B	GTIOC3B_B	CTS0_RTS0_B/ SS0_B	SDA0_A	—	—	—	IRQ5_C
3	1	1	—	VCL		—	—	—	—	—	—	—	—	—
4	2	—	—		P402	—	—	GTADSM0	—	—	—	—	—	—
5	3	—	—		P403	—	—	GTADSM1	—	—	—	—	—	—
6	4	2	—	VSS		—	—	—	—	—	—	—	—	—
7	5	3	—	XTAL	P213	—	GTOUUP_A	GTIOC0A_A	—	—	—	—	—	IRQ2_B
8	6	4	—	EXTAL	P212	AGTEE1_A	GTOULO_A	GTIOC0B_A	—	—	—	—	—	IRQ7_C
9	7	5	—	VCC		—	—	—	—	—	—	—	—	—
10	—	—	—		P409	—	GTIV_B	—	—	—	—	—	—	IRQ6_B
11	—	—	—		P408	—	GTIW_B	—	CTS1_RTS1_D/ SS1_D	SCL0_C	—	—	—	IRQ7_B
12	8	6	—		P407	AGTIO0_C	GTOULO_B/ GTCPP0	GTIOC0B_B	CTS0_RTS0_D/ SS0_D	SDA0_B	—	ADTRG0_B	CMPREF1	—
13	—	—	—		P915	—	—	—	—	—	—	—	—	—
14	9	—	—		P914	AGTOA1_A	GTOVUP_A	GTIOC1A_A	—	—	—	—	—	—
15	10	—	—		P913	AGTIO1_F	GTVOLO_A	GTIOC1B_A	—	—	—	—	—	—
16	11	—	—		P208	AGTOB0_A	GTOUUP_B	GTIOC0A_B	—	—	—	—	—	—
17	12	—	—		P207	—	—	—	—	—	—	—	—	—
18	—	—	—		P206	—	GTIU_B	—	TXD0_C/ MOSI0_C/ SDA0_C	—	—	—	—	IRQ0_B
19	13	7	—	RES		—	—	—	—	—	—	—	—	—
20	14	8	—	MD	P201	—	—	—	—	—	—	—	—	—
21	15	9	—		P200	—	—	—	—	—	—	—	—	NMI
22	—	—	—		P302	—	GTETRGA_D	—	TXD2_A/ MOSI2_A/ SDA2_A	—	—	—	—	IRQ5_A
23	—	—	—		P301	AGTIO0_D	GTETRGB_A	—	RXD2_A/ MISO2_A/ SCL2_A/ CTS9_RTS9_D/ SS9_D	—	—	—	—	IRQ6_A
24	16	10	—	SWCLK	P300	—	GTETRGA_C/ GTCPP01	GTIOC3A_A	TXD1/MOSI1/ SDA1	—	—	—	—	IRQ5_B
25	17	11	—	SWDIO	P108	AGTEE1_B	GTETRGB_C/ GTCPP02	GTIOC3B_A	RXD1/MISO1/ SCL1/ CTS9_RTS9_B/ SS9_B	—	—	—	—	IRQ6_C
26	18	12	—	CLKOUT_B	P109	AGTOA1_B	GTOWUP_A	GTIOC2A_B	SCK1_E/ TXD9_B/ MOSI9_B/ SDA9_B	—	—	—	—	—
27	19	13	—	VCOUT	P110	AGTIO1_A	GTOWLO_A	GTIOC2B_B	CTS2_RTS2_B/ SS2_B/ RXD9_B/ MISO9_B/ SCL9_B	—	—	—	—	IRQ3_A
28	—	—	—		P111	AGTOA0	—	GTIOC1A_C	SCK2_B/ SCK9_B	—	—	—	—	IRQ4_A
29	20	—	—		P112	AGTOB0	—	GTIOC1B_C	SCK1_D	—	—	—	—	—
30	—	—	—	VCC		—	—	—	—	—	—	—	—	—
31	—	—	—	VSS		—	—	—	—	—	—	—	—	—
32	—	—	—		P104	—	GTETRGB_B	—	RXD0_C/ MISO0_C/ SCL0_C	—	SSLA1_A	—	—	KRM04/IRQ1_B
33	21	14	—		P103	—	GTOUUP_B/ GTCPP03	GTIOC2A_A	CTS0_RTS0_A/ SS0_A/ RXD2_D/ MISO2_D/ SCL2_D	—	SSLA0_A	AN019	CMPIN1	KRM03/IRQ4_B

**Table 1.14 Pin list (2 of 2)**

Pin number	LQFP/QFN 48-pin	LQFP/QFN 32-pin	LQFP/QFN 24-pin	Power, System, Clock, Debug, CAC	I/O ports	Timers			Communication interfaces			Analogs		HMI
						AGTW	GPT_OPS, POEG	GPT	SCI	IIC	SPI	ADC	ACMPHS	Interrupt
34	22	15		P102	AGTO0	GTOWLO_B	GTIOC2B_A		SCK0_A/ TXD2_D/ MOSI2_D/ SDA2_D	—	RSPCKA_A	ADTRG0_A/ AN020	CMPREF0	KRM02/IRQ1_A
35	23	16		P101	AGTEE0	GTOVUP_B	GTIOC1A_B		TxD0_A/ MOSI0_A/ SDA0_A/ CTS1_RTS1_A/ SS1_A	SDA0_C	MOSIA_A	AN021	—	KRM01/IRQ2_A
36	24	17		P100	AGTIO0_A	GTOVLO_B	GTIOC1B_B		RXD0_A/ MISO0_A/ SCL0_A/ SCK1_A	SCL0_D	MISOA_A	AN022	—	KRM00/IRQ0_C
37	—	—		P500	—	GTETRGA_A	GTIOC2A_C	—	—	—	—	—	—	—
38	25	18		P015	—	GTIU_A	—	—	—	—	—	AN002 (3ch S/H)	CMPIN01	IRQ2_C
39	26	19		P014	—	GTIV_A	—	—	—	—	—	AN001 (3ch S/H)	CMPIN02	IRQ3_B
40	27	20		P013	—	GTIW_A	—	—	—	—	—	AN000 (3ch S/H)	CMPIN03	IRQ1_C
41	28	—		P012	—	—	—	—	—	—	—	AN007	—	—
42	29	21	AVCC0	AVCC0	—	—	—	—	—	—	—	—	—	—
43	30	22	AVSS0	AVSS0	—	—	—	—	—	—	—	—	—	—
44	31	23	VREFL0	P011	—	—	—	—	—	—	—	AN006	—	—
45	32	24	VREFH0	P010	—	—	—	—	—	—	—	AN005	—	—
46	—	—		P002	—	—	—	—	—	—	—	AN010	—	—
47	—	—		P001	—	—	—	—	—	—	—	AN009	—	IRQ7_A
48	—	—		P000	—	—	—	—	—	—	—	AN008	—	—

Note: Several pin names have the added suffix of \_A, \_B, \_C, \_D, \_E and \_F. The suffix can be ignored when assigning functionality.

## 2. Electrical Characteristics

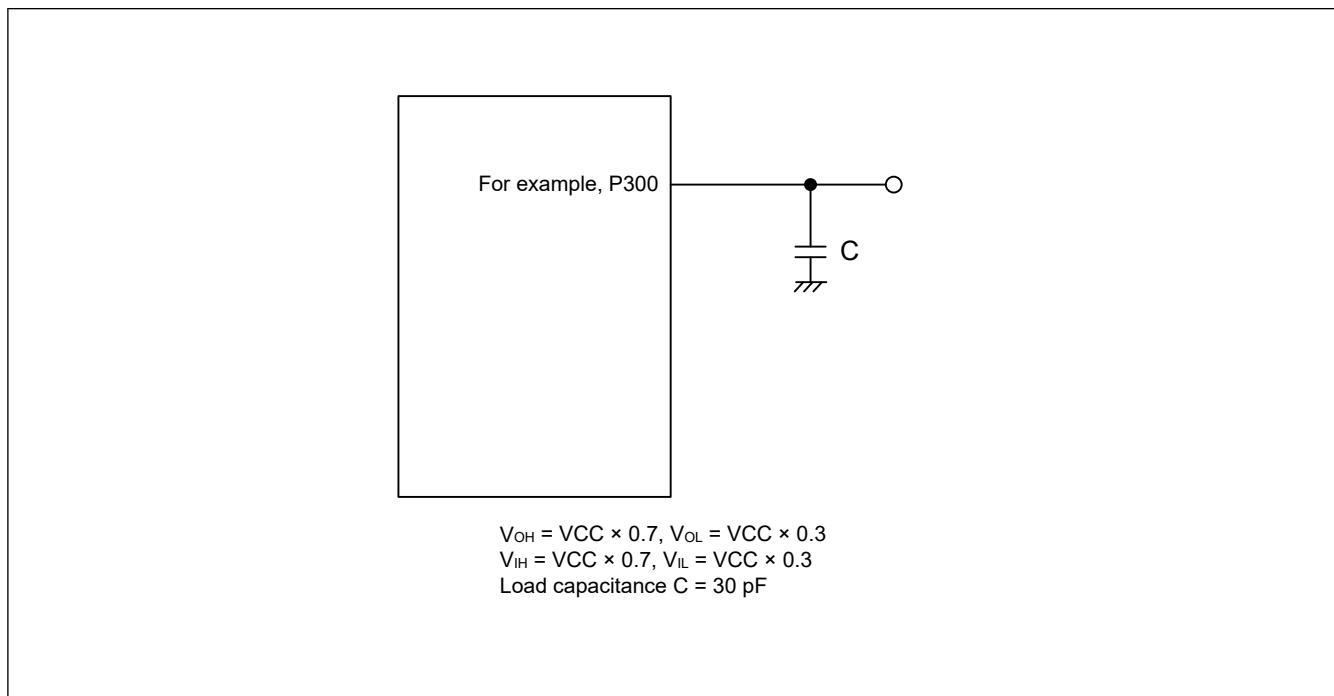
Unless otherwise specified, the electrical characteristics of the MCU are defined under the following conditions:

$$VCC^{*1} = AVCC0 = 1.6 \text{ to } 5.5 \text{ V}, VREFH0 = 1.6 \text{ V to } AVCC0$$

$$VSS = AVSS0 = VREFL0 = 0 \text{ V}, Ta = T_{opr}$$

Note 1. The typical condition is set to  $VCC = 3.3 \text{ V}$ .

[Figure 2.1](#) shows the timing conditions.



**Figure 2.1 Input or output timing measurement conditions**

The measurement conditions of the timing specifications for each peripheral are recommended for the best peripheral operation. However, make sure to adjust driving abilities for each pin to meet the conditions of your system.

Each function pin used for the same function must select the same drive ability. If the I/O drive ability of each function pin is mixed, the AC characteristics of each function are not guaranteed.

### 2.1 Absolute Maximum Ratings

**Table 2.1 Absolute maximum ratings (1 of 2)**

Parameter	Symbol	Value	Unit
Power supply voltage	VCC	-0.5 to +6.5	V
Input voltage	5V-tolerant ports <sup>*1</sup> V <sub>in</sub>	-0.3 to +6.5	V
	P000 to P002, P010 to P015 V <sub>in</sub>	-0.3 to AVCC0 + 0.3	V
	Others V <sub>in</sub>	-0.3 to VCC + 0.3	V
Reference power supply voltage	VREFH0	-0.3 to +6.5	V
Analog power supply voltage	AVCC0	-0.5 to +6.5	V
Analog input voltage	When AN000 to AN002, AN005 to AN010 are used V <sub>AN</sub>	-0.3 to AVCC0 + 0.3	V
	When AN019 to AN022 are used	-0.3 to VCC + 0.3	V
Operating temperature <sup>*2 *3 *4</sup>	T <sub>opr</sub>	-40 to +105 -40 to +125	°C

**Table 2.1 Absolute maximum ratings (2 of 2)**

Parameter	Symbol	Value	Unit
Storage temperature	T <sub>stg</sub>	-55 to +140	°C

Note 1. Ports P400, P401 are 5V-tolerant.

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up might cause malfunction and the abnormal current that passes in the device at this time might cause degradation of internal elements.

Note 2. See [section 2.2.1. T<sub>j</sub>/T<sub>a</sub> Definition](#).

Note 3. Contact Renesas Electronics sales office for information on derating operation under T<sub>a</sub> = +105°C to +125°C.

Derating is the systematic reduction of load for improved reliability.

Note 4. The upper limit of the operating temperature is 105°C or 125°C, depending on the product.

**Caution: Permanent damage to the MCU may result if absolute maximum ratings are exceeded.**

To preclude any malfunctions due to noise interference, insert capacitors with high frequency characteristics between the VCC and VSS pins, between the AVCC0 and AVSS0 pins, and between the VREFH0 and VREFL0 pins when VREFH0 is selected as the high potential reference voltage for the ADC12. Place capacitors of the following value as close as possible to every power supply pin and use the shortest and heaviest possible traces:

- VCC and VSS: about 0.1 µF
- AVCC0 and AVSS0: about 0.1 µF
- VREFH0 and VREFL0: about 0.1 µF

Also, connect capacitors as stabilization capacitance.

Connect the VCL pin to a VSS pin by a 4.7 µF capacitor. Each capacitor must be placed close to the pin.

**Table 2.2 Recommended operating conditions**

Parameter	Symbol	Min	Typ	Max	Unit
Power supply voltages	VCC <sup>*1 *2</sup>	1.6	—	5.5	V
	VSS	—	0	—	V
Analog power supply voltages	AVCC0 <sup>*1 *2</sup>	1.6	—	5.5	V
	AVSS0	—	0	—	V
	VREFH0	When used as ADC12 Reference	1.6	—	AVCC0 V
	VREFL0		—	0	V

Note 1. Use AVCC0 and VCC under the following conditions:

AVCC0 = VCC

Note 2. When powering on the VCC and AVCC0 pins, power them on at the same time or the VCC pin first and then the AVCC0 pins. When powering off the VCC and AVCC0 pins, power them off at the same time or the AVCC0 pin first and then the VCC pins.

## 2.2 DC Characteristics

### 2.2.1 T<sub>j</sub>/T<sub>a</sub> Definition

**Table 2.3 DC characteristics**

Conditions: Products with operating temperature (T<sub>a</sub>) -40 to +125°C

Parameter	Symbol	Typ	Max	Unit	Test conditions
Permissible junction temperature	T <sub>j</sub>	—	140	°C	High-speed mode Middle-speed mode Low-speed mode Subosc-speed mode
			125 <sup>*1</sup>		

Note: Make sure that T<sub>j</sub> = T<sub>a</sub> + θ<sub>ja</sub> × total power consumption (W), where total power consumption = (VCC - V<sub>OH</sub>) × ΣI<sub>OH</sub> + V<sub>OL</sub> × ΣI<sub>OL</sub> + I<sub>CCmax</sub> × VCC.

Note 1. The upper limit of operating temperature is 105°C or 125°C, depending on the product. If the part number shows the operation temperature at 105°C, then the maximum value of T<sub>j</sub> is 125°C, otherwise it is 140°C.

## 2.2.2 I/O $V_{IH}$ , $V_{IL}$

**Table 2.4 I/O  $V_{IH}$ ,  $V_{IL}$**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Ports & Functions	Symbol	Min	Max	Unit	Test Conditions
Input voltage	Input ports pins P000 to P002, P010 to P015	$V_{IH}$	$AVCC0 \times 0.8$	—	V	—
		$V_{IL}$	—	$AVCC0 \times 0.2$		
	Input ports pins except for P000 to P002, P010 to P015	$V_{IH}$	$VCC \times 0.8$	—		
		$V_{IL}$	—	$VCC \times 0.2$		
	EXTAL	$V_{IH}$	$VCC \times 0.8$	—		
		$V_{IL}$	—	$VCC \times 0.2$		
	5V-tolerant ports <sup>*3</sup>	$V_{IH}$	$VCC \times 0.8$	5.8		
		$V_{IL}$	—	$VCC \times 0.2$		
	RES, NMI, IRQ <sup>*4</sup>	$V_{IH}$	$VCC \times 0.8$	—		
		$V_{IL}$	—	$VCC \times 0.2$		
		$\Delta V_T^{*6}$	$VCC \times 0.10$	—		VCC = 2.7 to 5.5 V
			$VCC \times 0.05$	—		VCC = 1.6 to 2.7 V
Peripheral functions <sup>*5</sup>	IIC (except for SMBus) <sup>*1</sup>	$V_{IH}$	$VCC \times 0.7$	5.8 <sup>*7</sup>	—	—
		$V_{IL}$	—	$VCC \times 0.3$		
		$\Delta V_T^{*6}$	$VCC \times 0.10$	—		
			$VCC \times 0.05$	—		
	IIC (SMBus) <sup>*2</sup>	$V_{IH}$	2.2	—		VCC = 2.7 to 5.5 V
		$V_{IL}$	2.0	—		
		$V_{IL}$	—	0.8		
		$V_{IL}$	—	0.5		
	Other peripheral functions	$V_{IH}$	$VCC \times 0.8$	—		VCC = 1.6 to 2.7 V
		$V_{IL}$	—	$VCC \times 0.2$		
		$\Delta V_T^{*6}$	$VCC \times 0.10$	—		
			$VCC \times 0.05$	—		

Note 1. SCL0\_A, SDA0\_A, SDA0\_B (total 3 pins)

Note 2. SCL0\_A, SCL0\_C, SDA0\_A, SDA0\_B, SCL0\_D, SDA0\_C (total 6 pins)

Note 3. P400, P401 (total 2 pins)

Note 4. PmnPFS.ISEL = 1.

Note 5. PmnPFS.PMR = 1.

Note 6. This is the hysteresis characteristic of the Schmitt Trigger circuit.

Note 7. SDA0\_B max spec is VCC.

## 2.2.3 I/O $I_{OH}$ , $I_{OL}$

**Table 2.5 I/O  $I_{OH}$ ,  $I_{OL}$  (1 of 4)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Permissible output current (max value per pin)	$I_{OH}$	—	—	-4.0	mA	
	$I_{OL}$	—	—	8.0	mA	
	$I_{OH}$	—	—	-4.0	mA	
	$I_{OL}$	—	—	20.0	mA	

**Table 2.5 I/O  $I_{OH}$ ,  $I_{OL}$  (2 of 4)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Permissible output current (max value total pins) <sup>*2</sup>	$\Sigma I_{OH}$ (max)	—	—	-30	mA	AVCC0 = 2.7 to 5.5 V
		—	—	-8		AVCC0 = 1.8 to 2.7 V
		—	—	-4		AVCC0 = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	50		AVCC0 = 2.7 to 5.5 V
		—	—	4		AVCC0 = 1.8 to 2.7 V
		—	—	2		AVCC0 = 1.6 to 1.8 V
Permissible output current (max value total pins) <sup>*2</sup>	$\Sigma I_{OH}$ (max)	—	—	-8	mA	VCC = 2.7 to 5.5 V
		—	—	-2		VCC = 1.8 to 2.7 V
		—	—	-1		VCC = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	16.0		VCC = 2.7 to 5.5 V
		—	—	1.2		VCC = 1.8 to 2.7 V
		—	—	0.6		VCC = 1.6 to 1.8 V
Permissible output current (max value total pins) <sup>*2</sup>	$\Sigma I_{OH}$ (max)	—	—	-30	mA	VCC = 2.7 to 5.5 V
		—	—	-8		VCC = 1.8 to 2.7 V
		—	—	-4		VCC = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	50		VCC = 2.7 to 5.5 V
		—	—	4		VCC = 1.8 to 2.7 V
		—	—	2		VCC = 1.6 to 1.8 V
Permissible output current (max value total pins) <sup>*2</sup>	$\Sigma I_{OH}$ (max)	—	—	-30	mA	VCC = 2.7 to 5.5 V
		—	—	-8		VCC = 1.8 to 2.7 V
		—	—	-4		VCC = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	50		VCC = 2.7 to 5.5 V
		—	—	4		VCC = 1.8 to 2.7 V
		—	—	2		VCC = 1.6 to 1.8 V
Total of all output pin	$\Sigma I_{OH}$ (max)	—	—	-60	mA	—
	$\Sigma I_{OL}$ (max)	—	—	100		—

**Table 2.5 I/O  $I_{OH}$ ,  $I_{OL}$  (3 of 4)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Permissible output current (max value total pins) <sup>*2</sup>	$\Sigma I_{OH}$ (max)	—	—	-24	mA	AVCC0 = 2.7 to 5.5 V
		—	—	-6		AVCC0 = 1.8 to 2.7 V
		—	—	-3		AVCC0 = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	48		AVCC0 = 2.7 to 5.5 V
		—	—	3.6		AVCC0 = 1.8 to 2.7 V
		—	—	1.8		AVCC0 = 1.6 to 1.8 V
32 pin products	$\Sigma I_{OH}$ (max)	—	—	-8	mA	VCC = 2.7 to 5.5 V
		—	—	-2		VCC = 1.8 to 2.7 V
		—	—	-1		VCC = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	16.0		VCC = 2.7 to 5.5 V
		—	—	1.2		VCC = 1.8 to 2.7 V
		—	—	0.6		VCC = 1.6 to 1.8 V
Total of ports P010 to P015	$\Sigma I_{OH}$ (max)	—	—	-30	mA	VCC = 4.0 to 5.5 V
		—	—	-20		VCC = 2.7 to 4.0 V
		—	—	-12		VCC = 1.8 to 2.7 V
		—	—	-6		VCC = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	50		VCC = 4.0 to 5.5 V
		—	—	20		VCC = 2.7 to 4.0 V
		—	—	8		VCC = 1.8 to 2.7 V
		—	—	4		VCC = 1.6 to 1.8 V
Total of other output ports	$\Sigma I_{OH}$ (max)	—	—	-54	mA	—
	$\Sigma I_{OL}$ (max)	—	—	98		—
	$\Sigma I_{OH}$ (max)	—	—	-54	mA	—
	$\Sigma I_{OL}$ (max)	—	—	98		—
Total of all output pin						

**Table 2.5 I/O  $I_{OH}$ ,  $I_{OL}$  (4 of 4)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Permissible output current (max value total pins) <sup>*2</sup>	$\Sigma I_{OH}$ (max)	—	—	-20	mA	AVCC0 = 2.7 to 5.5 V
		—	—	-5		AVCC0 = 1.8 to 2.7 V
		—	—	-2.5		AVCC0 = 1.6 to 1.8 V
		—	—	40		AVCC0 = 2.7 to 5.5 V
		—	—	3		AVCC0 = 1.8 to 2.7 V
		—	—	1.5		AVCC0 = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	-8	mA	VCC = 2.7 to 5.5 V
		—	—	-2		VCC = 1.8 to 2.7 V
		—	—	-1		VCC = 1.6 to 1.8 V
		—	—	16.0		VCC = 2.7 to 5.5 V
		—	—	1.2		VCC = 1.8 to 2.7 V
		—	—	0.6		VCC = 1.6 to 1.8 V
Total of other output ports	$\Sigma I_{OH}$ (max)	—	—	-30	mA	VCC = 4.0 to 5.5 V
		—	—	-20		VCC = 2.7 to 4.0 V
		—	—	-12		VCC = 1.8 to 2.7 V
		—	—	-6		VCC = 1.6 to 1.8 V
	$\Sigma I_{OL}$ (max)	—	—	50	mA	VCC = 4.0 to 5.5 V
		—	—	20		VCC = 2.7 to 4.0 V
		—	—	8		VCC = 1.8 to 2.7 V
		—	—	4		VCC = 1.6 to 1.8 V
	$\Sigma I_{OH}$ (max)	—	—	-50	mA	—
		—	—	90		—

Note 1. Ports except for P200 are input.

Note 2. Specification under conditions where the duty factor  $\leq 70\%$ .The output current value that has changed to the duty factor  $> 70\%$  the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).Total output current of pins =  $(I_{OH} \times 0.7)/(n \times 0.01)$ <Example> Where n = 80% and  $I_{OH} = -30.0$  mATotal output current of pins =  $(-30.0 \times 0.7)/(80 \times 0.01) \cong -26.2$  mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

**Caution: To protect the reliability of the MCU, the output current values should not exceed the values in Table 2.5.**

## 2.2.4 I/O $V_{OH}$ , $V_{OL}$ , and Other Characteristics

**Table 2.6 I/O  $V_{OH}$ ,  $V_{OL}$  (1)**

Conditions: VCC = AVCC0 = 4.0 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Output voltage	$V_{OH}$	AVCC0 - 0.8	—	—	V	$I_{OH} = -4.0$ mA
	$V_{OH}$	VCC - 0.8	—	—		$I_{OH} = -4.0$ mA
	$V_{OL}$	—	—	0.8		$I_{OL} = 8.0$ mA
	$V_{OL}$	—	—	0.8		$I_{OL} = 8.0$ mA
	$V_{OL}$	—	—	1.2		$I_{OL} = 20.0$ mA

Note 1. Ports except for P200 are input.

**Table 2.7 I/O  $V_{OH}$ ,  $V_{OL}$  (2)**

Conditions: VCC = AVCC0 = 2.7 to 4.0 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Output voltage	$V_{OH}$	AVCC0 - 0.8	—	—	V	$I_{OH} = -4.0 \text{ mA}$
	$V_{OH}$	VCC - 0.8	—	—		$I_{OH} = -4.0 \text{ mA}$
	$V_{OL}$	—	—	0.8		$I_{OL} = 8.0 \text{ mA}$
	$V_{OL}$	—	—	0.8		$I_{OL} = 8.0 \text{ mA}$

Note 1. Ports except for P200 are input.

**Table 2.8 I/O  $V_{OH}$ ,  $V_{OL}$  (3)**

Conditions: VCC = AVCC0 = 1.6 to 2.7 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Output voltage	$V_{OH}$	AVCC0 - 0.5	—	—	V	$I_{OH} = -1.0 \text{ mA}$ AVCC0 = 1.8 to 2.7 V
		AVCC0 - 0.5	—	—		$I_{OH} = -0.5 \text{ mA}$ AVCC0 = 1.6 to 1.8 V
	$V_{OH}$	VCC - 0.5	—	—		$I_{OH} = -1.0 \text{ mA}$ VCC = 1.8 to 2.7 V
		VCC - 0.5	—	—		$I_{OH} = -0.5 \text{ mA}$ VCC = 1.6 to 1.8 V
	$V_{OL}$	—	—	0.4		$I_{OL} = 0.6 \text{ mA}$ AVCC0 = 1.8 to 2.7 V
		—	—	0.4		$I_{OL} = 0.3 \text{ mA}$ AVCC0 = 1.6 to 1.8 V
	$V_{OL}$	—	—	0.4		$I_{OL} = 0.6 \text{ mA}$ VCC = 1.8 to 2.7 V
		—	—	0.4		$I_{OL} = 0.3 \text{ mA}$ VCC = 1.6 to 1.8 V

Note 1. Ports except for P200 are input.

**Table 2.9 I/O other characteristics**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Input leakage current	$ I_{in} $	—	—	1.0	$\mu\text{A}$	$V_{in} = 0 \text{ V}$ $V_{in} = \text{VCC}$
Three-state leakage current (off state)	$ I_{TSI} $	—	—	1.0	$\mu\text{A}$	$V_{in} = 0 \text{ V}$ $V_{in} = 5.8 \text{ V}$
		—	—	1.0		$V_{in} = 0 \text{ V}$ $V_{in} = \text{VCC}$
Input pull-up resistor	$R_U$	10	20	100	$\text{k}\Omega$	$V_{in} = 0 \text{ V}$
Input capacitance	$C_{in}$	—	—	30	$\text{pF}$	$V_{in} = 0 \text{ V}$ $f = 1 \text{ MHz}$ $T_a = 25^\circ\text{C}$
		—	—	15		

Note 1. P400, P401 (total 2 pins)

## 2.2.5 Operating and Standby Current

**Table 2.10 Operating and standby current (1) (1 of 2)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter					Symbol	Typ <sup>*10</sup>	Max	Unit	Test Conditions
Supply current <sup>*1</sup>	High-speed mode <sup>*2</sup>	Normal mode	All peripheral clocks disabled, CoreMark code executing from flash <sup>*5</sup>	ICLK = 64 MHz	I <sub>CC</sub>	6.80	—	mA	*7 *11
				ICLK = 48 MHz		5.20	—		*7 *11
				ICLK = 32 MHz		3.60	—		*7
				ICLK = 16 MHz		2.15	—		
				ICLK = 8 MHz		1.40	—		
			All peripheral clocks enabled, code executing from flash <sup>*5</sup>	ICLK = 64 MHz		—	13.9		*9 *11
		Sleep mode	All peripheral clocks disabled <sup>*5</sup>	ICLK = 64 MHz		1.50	—		*7
				ICLK = 48 MHz		1.20	—		*7
				ICLK = 32 MHz		0.95	—		*7
				ICLK = 16 MHz		0.70	—		
				ICLK = 8 MHz		0.60	—		
		All peripheral clocks enabled <sup>*5</sup>		ICLK = 64 MHz		5.65	—		*9
				ICLK = 48 MHz		4.30	—		*9
				ICLK = 32 MHz		3.65	—		*8
				ICLK = 16 MHz		2.10	—		
				ICLK = 8 MHz		1.30	—		
	Increase during BGO operation <sup>*6</sup>					2.1	—		—

**Table 2.10 Operating and standby current (1) (2 of 2)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter				Symbol	Typ <sup>*10</sup>	Max	Unit	Test Conditions	
Supply current <sup>*1</sup>	Middle-speed mode <sup>*2</sup>	Normal mode	All peripheral clocks disabled, CoreMark code executing from flash <sup>*5</sup>	ICLK = 24 MHz	I <sub>CC</sub>	2.75	—	mA	*7
				ICLK = 4 MHz		0.90	—		
			All peripheral clocks enabled, code executing from flash <sup>*5</sup>	ICLK = 24 MHz	—	6.6	—		*8
		Sleep mode	All peripheral clocks disabled <sup>*5</sup>	ICLK = 24 MHz		0.75	—	mA	*7
				ICLK = 4 MHz		0.55	—		
			All peripheral clocks enabled <sup>*5</sup>	ICLK = 24 MHz		2.80	—		*8
	Low-speed mode <sup>*3</sup>	Normal mode	All peripheral clocks disabled, CoreMark code executing from flash <sup>*5</sup>	ICLK = 4 MHz	—	0.90	—	mA	*7
				Increase during BGO operation <sup>*6</sup>		1.80	—		
			All peripheral clocks enabled, code executing from flash <sup>*5</sup>	ICLK = 2 MHz		0.35	—		*7
		Sleep mode	All peripheral clocks enabled, code executing from flash <sup>*5</sup>	ICLK = 2 MHz		—	1.7	mA	*8
			All peripheral clocks disabled <sup>*5</sup>	ICLK = 2 MHz		0.13	—		*7
			All peripheral clocks enabled <sup>*5</sup>	ICLK = 2 MHz		0.30	—		*8
	Subosc-speed mode <sup>*4</sup>	Normal mode	All peripheral clocks enabled, code executing from flash <sup>*5</sup>	ICLK = 32.768 kHz	—	341	μA	mA	*8
			All peripheral clocks disabled <sup>*5</sup>	ICLK = 32.768 kHz		1.60	—		*8
		Sleep mode	All peripheral clocks enabled <sup>*5</sup>	ICLK = 32.768 kHz		4.15	—		*8

Note 1. Supply current is the total current flowing into VCC. Supply current values apply when internal pull-up MOSs are in the off state and these values do not include output charge/discharge current from any of the pins.

Note 2. The clock source is HOCO.

Note 3. The clock source is MOCO.

Note 4. The clock source is LOCO.

Note 5. This does not include BGO operation.

Note 6. This is the increase for programming or erasure of the flash memory for data storage during program execution.

Note 7. PCLKB and PCLKD are set to divided by 64.

Note 8. PCLKB and PCLKD are the same frequency as that of ICLK.

Note 9. PCLKB are set to be divided by 2 and PCLKD is the same frequency as that of ICLK.

Note 10. VCC = 3.3 V.

Note 11. The prefetch buffer is operating.

**Table 2.11 Operating and standby current (2)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter				Symbol	Typ <sup>*3</sup>	Max	Unit	Test conditions
Supply current <sup>*1</sup>	Software Standby mode <sup>*2</sup>	Peripheral modules stop	All SRAMs (0x2000_4000 to 0x2000_5FFF) are on	T <sub>a</sub> = 25°C	I <sub>CC</sub>	0.40	4.4	μA
				T <sub>a</sub> = 55°C		1.10	11	
				T <sub>a</sub> = 85°C		3.85	33	
				T <sub>a</sub> = 105°C		8.80	71	
				T <sub>a</sub> = 125°C		19.1	159	

Note 1. Supply current is the total current flowing into VCC. Supply current values apply when internal pull-up MOSs are in the off state and these values do not include output charge/discharge current from any of the pins.

Note 2. The IWDT and LVD are not operating.

Note 3. VCC = 3.3 V.

**Table 2.12 Operating and standby current (3)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Analog power supply current	During 12-bit A/D conversion (at high-speed A/D conversion mode)	$I_{AVCC0}$	—	—	1.44	mA	—
	During 12-bit A/D conversion (at high-speed A/D conversion mode) with S/H (2.7 V to 5.5V)		—	—	5.00	mA	—
	During 12-bit A/D conversion (at low-power A/D conversion mode)		—	—	0.78	mA	—
	Waiting for 12-bit A/D conversion (all units) <sup>*1</sup>		—	—	1.0	$\mu$ A	—
Reference power supply current	During 12-bit A/D conversion	$I_{REFH0}$	—	—	120	$\mu$ A	—
	Waiting for 12-bit A/D conversion		—	—	60	nA	—
Temperature Sensor (TSN) operating current		$I_{TNS}$	—	95	—	$\mu$ A	—
High-Speed Analog Comparator (ACMPHS) operating current per channel		$I_{CMPHS}$	—	100	—	$\mu$ A	—

Note 1. When the MCU is in Software Standby mode or the MSTPCRD.MSTPD16 (ADC120 module-stop bit) is in the module-stop state.

## 2.2.6 VCC Rise, Fall Gradient, and Ripple Frequency

**Table 2.13 Rise and fall gradient characteristics**

Conditions: VCC = AVCC0 = 0 to 5.5 V

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Power-on VCC rising gradient	Voltage monitor 0 reset disabled at startup	SrVCC	0.02	—	2	ms/V	—
	Voltage monitor 0 reset enabled at startup <sup>*1 *2</sup>				—		
	SCI boot mode <sup>*2</sup>				2		

Note 1. When OFS1.LVDAS = 0.

Note 2. At boot mode, the reset from voltage monitor 0 is disabled regardless of the value of OFS1.LVDAS bit.

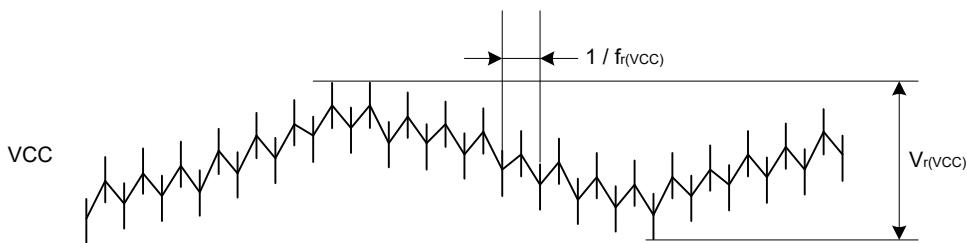
**Table 2.14 Rising and falling gradient and ripple frequency characteristics**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

The ripple voltage must meet the allowable ripple frequency  $f_r(VCC)$  within the range between the VCC upper limit (5.5 V) and lower limit (1.6 V).

When the VCC change exceeds  $VCC \pm 10\%$ , the allowable voltage change rising and falling gradient  $dt/dVCC$  must be met.

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Allowable ripple frequency	$f_r(VCC)$	—	—	10	kHz	<a href="#">Figure 2.2</a> $V_r(VCC) \leq VCC \times 0.2$
		—	—	1	MHz	<a href="#">Figure 2.2</a> $V_r(VCC) \leq VCC \times 0.08$
		—	—	10	MHz	<a href="#">Figure 2.2</a> $V_r(VCC) \leq VCC \times 0.06$
Allowable voltage change rising and falling gradient	$dt/dVCC$	1.0	—	—	ms/V	When VCC change exceeds $VCC \pm 10\%$

**Figure 2.2 Ripple waveform**

## 2.3 AC Characteristics

### 2.3.1 Frequency

**Table 2.15 Operation frequency in high-speed operating mode**Conditions:  $V_{CC} = AVCC0 = 1.8$  to  $5.5$  V

Parameter		Symbol	Min	Typ	Max <sup>*4</sup>	Unit
Operation frequency	System clock (ICLK) <sup>*1*2</sup>	f	0.032768	—	64	MHz
	Peripheral module clock (PCLKB)		—	—	32	
	Peripheral module clock (PCLKD) <sup>*3</sup>		—	—	64	

Note 1. The lower-limit frequency of ICLK is 1 MHz while programming or erasing the flash memory. When using ICLK for programming or erasing the flash memory at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note 2. The frequency accuracy of ICLK must be  $\pm 1.0\%$  during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 3. The lower-limit frequency of PCLKD is 1 MHz when the ADC12 is in use.

Note 4. The maximum value of operation frequency does not include internal oscillator errors. For details on the range for guaranteed operation, see [Table 2.19](#).

**Table 2.16 Operation frequency in middle-speed mode**Conditions:  $V_{CC} = AVCC0 = 1.6$  to  $5.5$  V

Parameter		Symbol	Min	Typ	Max <sup>*4</sup>	Unit	
Operation frequency	System clock (ICLK) <sup>*1*2</sup>	f	0.032768	—	24	MHz	
			0.032768	—	4		
	Peripheral module clock (PCLKB)		—	—	24		
			—	—	4		
	Peripheral module clock (PCLKD) <sup>*3</sup>		—	—	24		
			—	—	4		

Note 1. The lower-limit frequency of ICLK is 1 MHz while programming or erasing the flash memory. When using ICLK for programming or erasing the flash memory at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note 2. The frequency accuracy of ICLK must be  $\pm 1.0\%$  while programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 3. The lower-limit frequency of PCLKD is 1 MHz when the ADC12 is in use.

Note 4. The maximum value of operation frequency does not include internal oscillator errors. For details on the range for guaranteed operation, see [Table 2.19](#).

**Table 2.17 Operation frequency in low-speed mode**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter		Symbol	Min	Typ	Max <sup>*4</sup>	Unit
Operation frequency	System clock (ICLK) <sup>*1*2</sup>	f	0.032768	—	2	MHz
	Peripheral module clock (PCLKB)		—	—	2	
	Peripheral module clock (PCLKD) <sup>*3</sup>		—	—	2	

Note 1. The lower-limit frequency of ICLK is 1 MHz while programming or erasing the flash memory.

Note 2. The frequency accuracy of ICLK must be  $\pm 1.0\%$  while programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 3. The lower-limit frequency of PCLKD is 1 MHz when the ADC12 is in use.

Note 4. The maximum value of operation frequency does not include internal oscillator errors. For details on the range for guaranteed operation, see [Table 2.19](#).**Table 2.18 Operation frequency in Subosc-speed mode**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter		Symbol	Min	Typ	Max	Unit
Operation frequency	System clock (ICLK) <sup>*1</sup>	f	27.8528	32.768	37.6832	kHz
	Peripheral module clock (PCLKB)		—	—	37.6832	
	Peripheral module clock (PCLKD) <sup>*2</sup>		—	—	37.6832	

Note 1. Programming and erasing the flash memory is not possible.

Note 2. The ADC12 cannot be used.

### 2.3.2 Clock Timing

**Table 2.19 Clock timing (1 of 2)**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
EXTAL external clock input cycle time	t <sub>Xcyc</sub>	50	—	—	ns	<a href="#">Figure 2.3</a>
EXTAL external clock input high pulse width	t <sub>XH</sub>	20	—	—	ns	
EXTAL external clock input low pulse width	t <sub>XL</sub>	20	—	—	ns	
EXTAL external clock rising time	t <sub>Xr</sub>	—	—	5	ns	
EXTAL external clock falling time	t <sub>Xf</sub>	—	—	5	ns	
EXTAL external clock input wait time <sup>*1</sup>	t <sub>EXWT</sub>	0.3	—	—	μs	
EXTAL external clock input frequency	f <sub>EXTAL</sub>	—	—	20	MHz	1.8 ≤ VCC ≤ 5.5
		—	—	4		1.6 ≤ VCC < 1.8
Main clock oscillator oscillation frequency	f <sub>MAIN</sub>	1	—	20	MHz	1.8 ≤ VCC ≤ 5.5
		1	—	4		1.6 ≤ VCC < 1.8
LOCO clock oscillation frequency	f <sub>LOCO</sub>	27.8528	32.768	37.6832	kHz	—
LOCO clock oscillation stabilization time	t <sub>LOCO</sub>	—	—	100	μs	<a href="#">Figure 2.4</a>
IWDT-dedicated clock oscillation frequency	f <sub>ILOCO</sub>	12.75	15	17.25	kHz	—
MOCO clock oscillation frequency	f <sub>MOCO</sub>	6.8	8	9.2	MHz	—
MOCO clock oscillation stabilization time	t <sub>MOCO</sub>	—	—	1	μs	—
HOCO clock oscillation frequency <sup>*4</sup>	f <sub>HOCO24</sub>	23.76	24	24.24	MHz	Ta = -40 to 105°C 1.6 ≤ VCC ≤ 5.5
	f <sub>HOCO32</sub>	31.68	32	32.32		Ta = -40 to 105°C 1.6 ≤ VCC ≤ 5.5
	f <sub>HOCO48</sub>	47.52	48	48.48		Ta = -40 to 105°C 1.6 ≤ VCC ≤ 5.5
	f <sub>HOCO64</sub>	63.36	64	64.64		Ta = -40 to 105°C 1.6 ≤ VCC ≤ 5.5

**Table 2.19 Clock timing (2 of 2)**

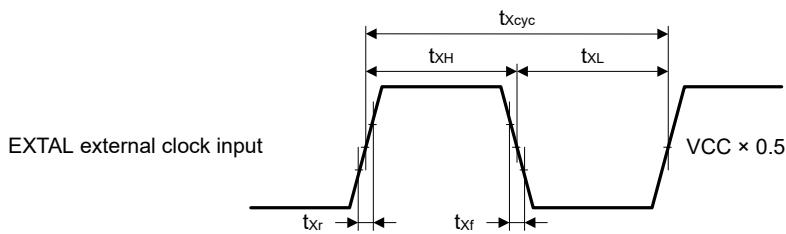
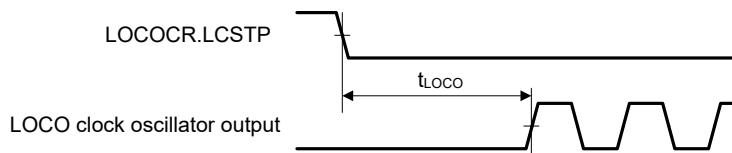
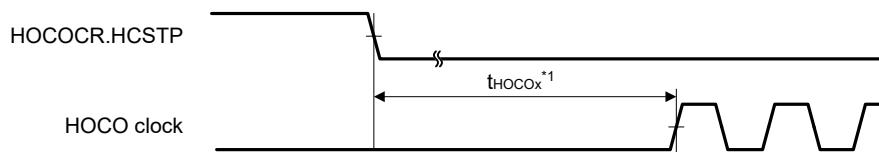
Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
HOCO clock oscillation stabilization time <sup>*2 *3</sup> t <sub>HOCO24</sub> t <sub>HOCO32</sub> t <sub>HOCO48</sub> t <sub>HOCO64</sub>	—	—	6.7	7.7	μs	<a href="#">Figure 2.5</a>

Note 1. Time until the clock can be used after the Main Clock Oscillator stop bit (MOSCCR.MOSTP) is set to 0 (operating) when the external clock is stable.

Note 2. This is a characteristic when the HOCOCR.HCSTP bit is set to 0 (oscillation) in the MOCO stop state. When the HOCOCR.HCSTP bit is set to 0 (oscillation) during MOCO oscillation, this specification is shortened by 1 μs.

Note 3. Check OSCSF.HOCOSF to confirm whether stabilization time has elapsed.

Note 4. Accuracy at production test.

**Figure 2.3 EXTAL external clock input timing****Figure 2.4 LOCO clock oscillation start timing**

Note:  $x = 24, 32, 48, 64$

**Figure 2.5 HOCO clock oscillation start timing (started by setting the HOCOCR.HCSTP bit)**

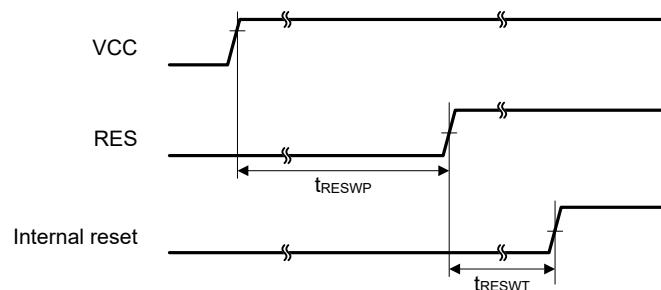
### 2.3.3 Reset Timing

**Table 2.20 Reset timing**

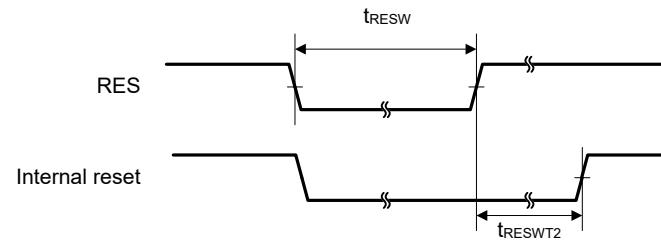
Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
RES pulse width	At power-on	$t_{RESWP}$	10	—	—	ms	<a href="#">Figure 2.6</a>
	Not at power-on	$t_{RESW}$	30	—	—	μs	<a href="#">Figure 2.7</a>
Wait time after RES cancellation (at power-on)	LVD0 enabled*1	$t_{RESWT}$	—	0.9	—	ms	<a href="#">Figure 2.6</a>
	LVD0 disabled*2		—	0.2	—		
Wait time after RES cancellation (during powered-on state)	LVD0 enabled*1	$t_{RESWT2}$	—	0.9	—	ms	<a href="#">Figure 2.7</a>
	LVD0 disabled*2		—	0.2	—		
Wait time after internal reset cancellation (Watchdog timer reset, SRAM parity error reset, bus master MPU error reset, bus slave MPU error reset, stack pointer error reset, software reset)	LVD0 enabled*1	$t_{RESWT3}$	—	0.9	—	ms	<a href="#">Figure 2.8</a>
	LVD0 disabled*2		—	0.15	—		

Note 1. When OFS1.LVDAS = 0.

Note 2. When OFS1.LVDAS = 1.



**Figure 2.6 Reset input timing at power-on**



**Figure 2.7 Reset input timing (1)**

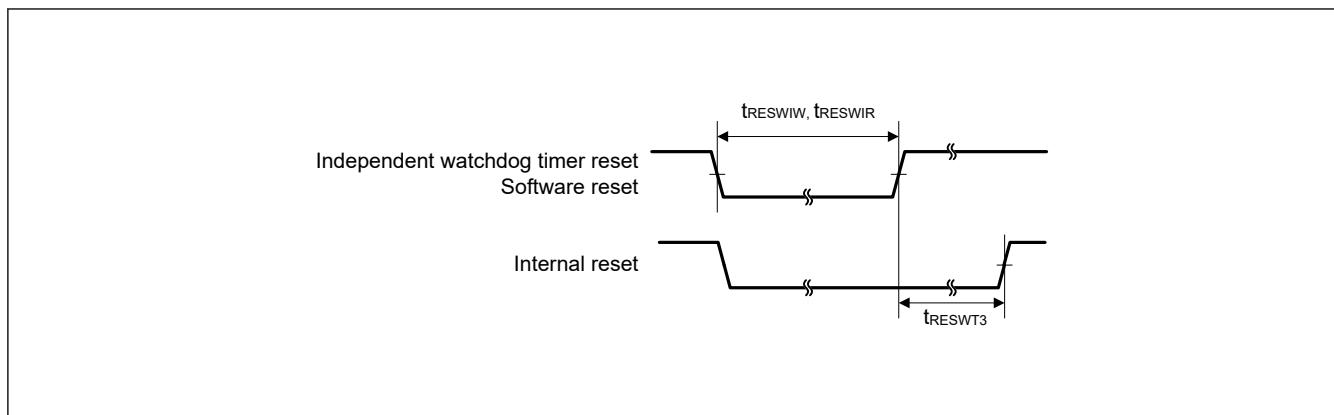


Figure 2.8 Reset input timing (2)

## 2.3.4 Wakeup Time

Table 2.21 Timing of recovery from low power modes (1)

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode <sup>*1</sup>	High-speed mode	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator (20 MHz) <sup>*2</sup>	t <sub>SBYMC</sub>	—	2	3	ms	Figure 2.9
		External clock input to main clock oscillator	System clock source is main clock oscillator (20 MHz) <sup>*3</sup>	t <sub>SBYEX</sub>	—	2.4	3.1	μs	
		System clock source is HO <sub>CO</sub> (HO <sub>CO</sub> clock is 32 MHz) <sup>*4</sup>		t <sub>SBYHO</sub>	—	7.4	9.1	μs	
		System clock source is HO <sub>CO</sub> (HO <sub>CO</sub> clock is 48 MHz) <sup>*5</sup>		t <sub>SBYHO</sub>	—	7.3	8.9	μs	
		System clock source is HO <sub>CO</sub> (HO <sub>CO</sub> clock is 64 MHz) <sup>*6</sup>		t <sub>SBYHO</sub>	—	7.3	8.8	μs	
		System clock source is MO <sub>CO</sub> (8 MHz)		t <sub>SBYMO</sub>	—	4	5	μs	

Note 1. The division ratio of ICLK and PCLKx is the minimum division ratio within the allowable frequency range. The recovery time is determined by the system clock source.

Note 2. The Main Clock Oscillator Wait Control Register (MOSCWT<sub>CR</sub>) is set to 0x05.

Note 3. The Main Clock Oscillator Wait Control Register (MOSCWT<sub>CR</sub>) is set to 0x00.

Note 4. The system clock is 32 MHz.

Note 5. The system clock is 48 MHz.

Note 6. The system clock is 64 MHz.

**Table 2.22 Timing of recovery from low power modes (2)**

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode <sup>*1</sup>	Middle-speed mode	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator (20 MHz) <sup>*2</sup>	t <sub>SBYMC</sub>	—	2	3	ms	Figure 2.9
				t <sub>SBYEX</sub>	—	2.4	3.1	μs	
		External clock input to main clock oscillator	System clock source is main clock oscillator (20 MHz) <sup>*3</sup> VCC = 1.8 V to 5.5 V		—	8.5	9.1	μs	
			t <sub>SBYHO</sub>	—	7.7	9.4	μs		
		System clock source is HOCO <sup>*4</sup>		VCC = 1.8 V to 5.5 V <sup>*4</sup>	—	15.7	17.9	μs	
				VCC = 1.6 V to 1.8 V	—	4	5	μs	
		System clock source is MOCO (8 MHz)	VCC = 1.8 V to 5.5 V	t <sub>SBYMO</sub>	—	7.2	9	μs	
			VCC = 1.6 V to 1.8 V		—	—	—	—	

Note 1. The division ratio of ICLK and PCLKx is the minimum division ratio within the allowable frequency range. The recovery time is determined by the system clock source.

Note 2. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x05.

Note 3. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x00.

Note 4. The system clock is 24 MHz.

**Table 2.23 Timing of recovery from low power modes (3)**

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode <sup>*1</sup>	Low-speed mode	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator (2 MHz) <sup>*2</sup>	t <sub>SBYMC</sub>	—	2	3	ms	Figure 2.9
				t <sub>SBYEX</sub>	—	14.5	16	μs	
		System clock source is MOCO (8 MHz)	t <sub>SBYMO</sub>	—	12	15	μs	—	

Note 1. The division ratio of ICLK and PCLKx is the minimum division ratio within the allowable frequency range. The recovery time is determined by the system clock source.

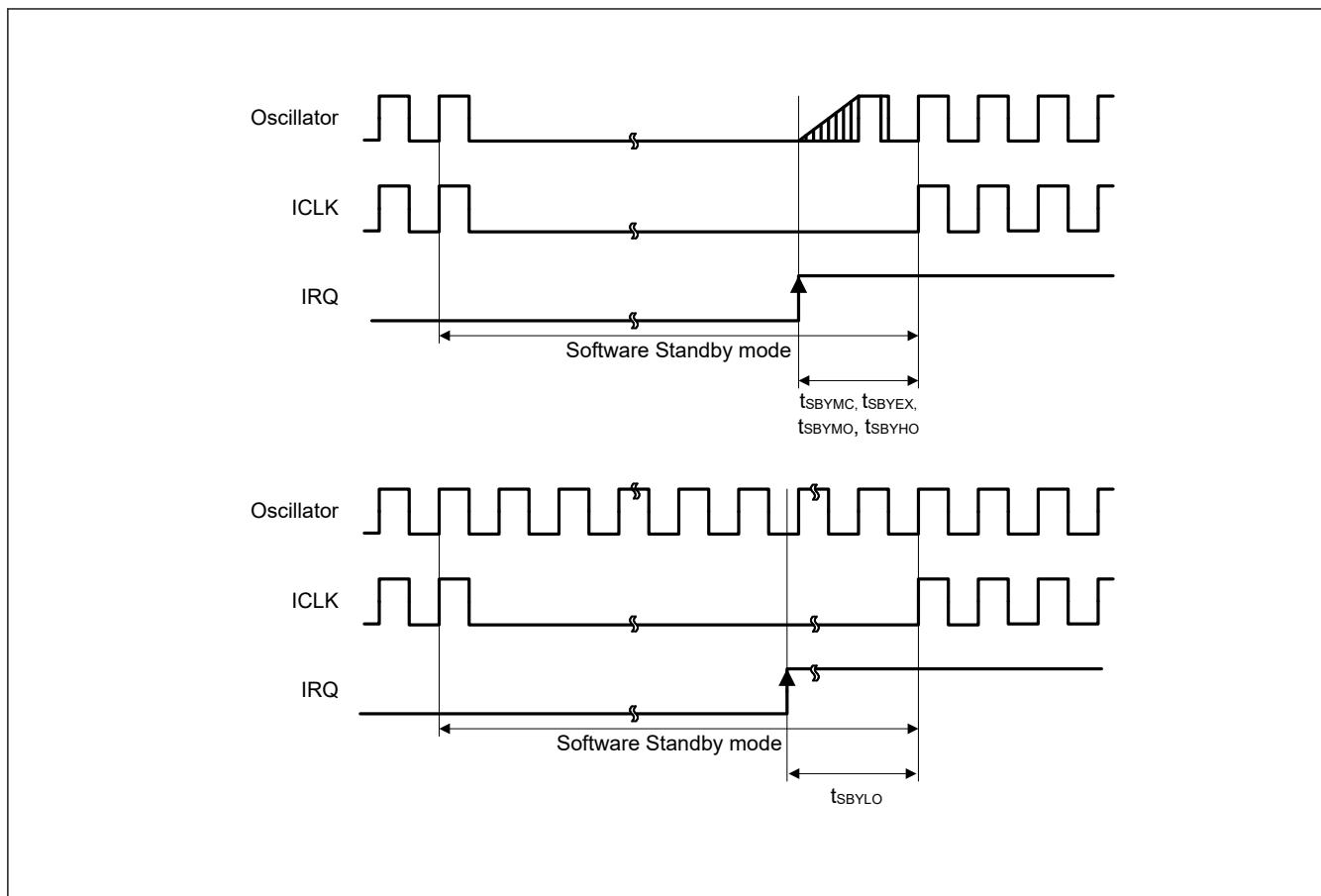
Note 2. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x05.

Note 3. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x00.

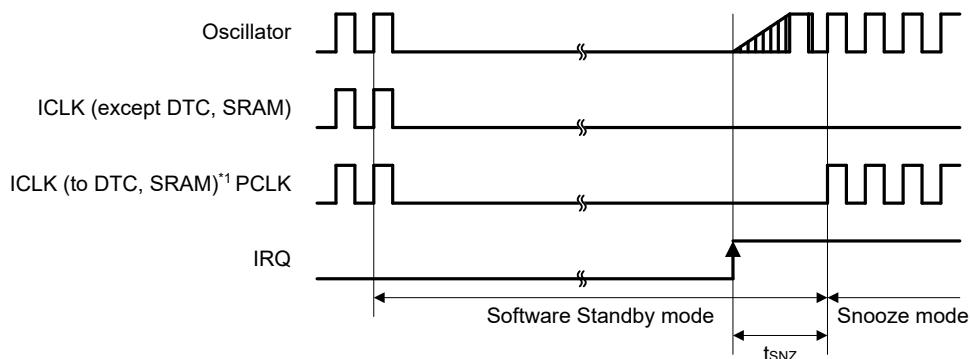
**Table 2.24 Timing of recovery from low power modes (4)**

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode <sup>*1</sup>	Subosc-speed mode	System clock source is LOCO (32.768 kHz)	t <sub>SBYLO</sub>	—	0.85	1.2	ms	—	Figure 2.9

Note 1. LOCO itself continues oscillating in Software Standby mode during Subosc-speed mode.

**Figure 2.9** Software Standby mode cancellation timing**Table 2.25** Timing of recovery from low power modes (5)

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode to Snooze mode	High-speed mode System clock source is HOCO	$t_{SNZ}$	—	6.6	8.1	$\mu s$	<a href="#">Figure 2.10</a>
	Middle-speed mode System clock source is HOCO (24 MHz) $VCC = 1.8 V$ to $5.5 V$	$t_{SNZ}$	—	6.7	8.2	$\mu s$	
	Middle-speed mode System clock source is HOCO (24 MHz) $VCC = 1.6 V$ to $1.8 V$	$t_{SNZ}$	—	10.8	12.9	$\mu s$	
	Low-speed mode System clock source is MOCO (2 MHz)	$t_{SNZ}$	—	6.7	8.0	$\mu s$	



Note 1. When SNZCR.SNZDTCEN bit is set to 1, ICLK is supplied to DTC and SRAM.

**Figure 2.10 Recovery timing from Software Standby mode to Snooze mode**

### 2.3.5 NMI and IRQ Noise Filter

**Table 2.26 NMI and IRQ noise filter**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
NMI pulse width	$t_{NMIW}$	200	—	—	ns	NMI digital filter disabled
		$t_{Pcyc} \times 2^{*1}$	—	—		$t_{Pcyc} \times 2 > 200$ ns
		200	—	—		$t_{NMICK} \times 3 \leq 200$ ns
		$t_{NMICK} \times 3.5^{*2}$	—	—		$t_{NMICK} \times 3 > 200$ ns
IRQ pulse width	$t_{IRQW}$	200	—	—	ns	IRQ digital filter disabled
		$t_{Pcyc} \times 2^{*1}$	—	—		$t_{Pcyc} \times 2 > 200$ ns
		200	—	—		$t_{IRQCK} \times 3 \leq 200$ ns
		$t_{IRQCK} \times 3.5^{*3}$	—	—		$t_{IRQCK} \times 3 > 200$ ns

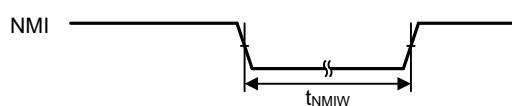
Note: 200 ns minimum in Software Standby mode.

Note: If the clock source is being switched it is needed to add 4 clock cycle of switched source.

Note 1.  $t_{Pcyc}$  indicates the PCLKB cycle.

Note 2.  $t_{NMICK}$  indicates the cycle of the NMI digital filter sampling clock.

Note 3.  $t_{IRQCK}$  indicates the cycle of the IRQi digital filter sampling clock ( $i = 0$  to 7).



**Figure 2.11 NMI interrupt input timing**

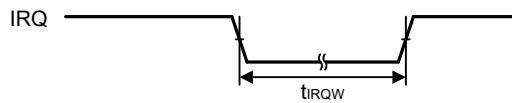


Figure 2.12 IRQ interrupt input timing

## 2.3.6 I/O Ports, POEG, GPT, AGTW, KINT, and ADC12 Trigger Timing

Table 2.27 I/O Ports, POEG, GPT, AGTW, KINT, and ADC12 trigger timing (1 of 3)

Parameter			Symbol	Min	Typ	Max	Unit	Test conditions
I/O Ports	Input data pulse width	2.7 V ≤ VCC ≤ 5.5 V	$t_{PRW}$	3	—	—	$t_{Pcyc}$	Figure 2.13
		2.4 V ≤ VCC < 2.7 V		4	—	—		
		1.6 V ≤ VCC < 2.4 V		5	—	—		

**Table 2.27 I/O Ports, POEG, GPT, AGTW, KINT, and ADC12 trigger timing (2 of 3)**

Parameter			Symbol	Min	Typ	Max	Unit	Test conditions
POEG	GTETRGn input pulse width		t <sub>POEW</sub>	1.5	—	—	t <sub>Pcyc</sub>	<a href="#">Figure 2.14</a>
	Output disable time	Input level detection of the GTETRGn pin (via flag)	t <sub>POEGDI</sub>	—	—	3PCLK B + 0.34	μs	<a href="#">Figure 2.15</a> When the digital noise filter is not in use (POEGGn.NF EN = 0 (n = A to D))
		Detection of the output stopping signal from GPT (deadtime error, simultaneous high output, or simultaneous low output)	t <sub>POEGDE</sub>	—	—	0.5	μs	<a href="#">Figure 2.16</a>
		Edge detection signal from a comparator	t <sub>POEGDC</sub>	—	—	3PCLK B + 0.5	μs	<a href="#">Figure 2.17</a> The time is that when the noise filter for ACMPHS is not in use (COMPFIR0.CIFCK[1:0] = 00) and excludes the time for detection by ACMPHS.
		Resister setting	t <sub>POEGDS</sub>	—	—	1PCLK B + 0.3	μs	<a href="#">Figure 2.18</a> Time for access to the register is not included.
		Oscillation stop detection *2	t <sub>POEGDOS</sub>	—	≤ 1	—	μs	<a href="#">Figure 2.19</a>
		Input level detection of the GTETRGn pin (direct path)	t <sub>POEGDDI</sub>	—	—	2PCLK B + 1 PCLKD + 0.34	μs	<a href="#">Figure 2.20</a>
		Level detection signal from a comparator	t <sub>POEGDDC</sub>	—	—	1PCLK D + 0.3	μs	<a href="#">Figure 2.21</a> The time is that when the noise filter for ACMPHS is not in use (COMPFIR0.CIFCK[1:0] = 00) and excludes the time for detection by ACMPHS.

Table 2.27 I/O Ports, POEG, GPT, AGTW, KINT, and ADC12 trigger timing (3 of 3)

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions	
GPT	Input capture pulse width	Single edge		$t_{GTICW}$	1.5	—	—	$t_{PDcyc}$	<a href="#">Figure 2.22</a>	
		Dual edge			2.5	—	—			
	GTIOCxY output skew ( $x = 0$ to 3, $Y = A$ or $B$ )			$t_{GTISK}$	—	—	4	ns	<a href="#">Figure 2.23</a>	
	GTIOCxY output skew ( $x = 0$ to 3, $Y = A$ or $B$ )				—	—	6			
	OPS output skew GTOUUP, GTOULO, GTOVUP, GTOVLO, GTOWUP, GTOWLO			$t_{GTOSK}$	—	—	5	ns	<a href="#">Figure 2.24</a>	
	External trigger input pulse width	Synchronous clock	Single-edge setting	$t_{GTEW}$	1.5	—	—	$t_{Pcyc}$	<a href="#">Figure 2.25</a>	
			Both-edge setting		2.5	—	—			
	Timer clock pulse width	Synchronous clock	Single-edge setting	$t_{GTCKWH}, t_{GTCKWL}$	1.5	—	—	$t_{Pcyc}$	<a href="#">Figure 2.26</a>	
			Both-edge setting		2.5	—	—			
GPT (PWM Delay Generation Circuit)	GTIOCxY_Z skew ( $x = 0$ to 3, $Y = A$ or $B$ , $Z = A$ to $D$ )			$t_{HRSK}^{*1}$	—	—	4.0	ns	<a href="#">Figure 2.27</a>	
AGTW	AGTIO, AGTEE input cycle	1.8 V ≤ VCC ≤ 5.5 V		$t_{ACYC}^{*1}$	250	—	—	ns	<a href="#">Figure 2.28</a>	
		1.6 V ≤ VCC < 1.8 V			2000	—	—	ns		
	AGTIO, AGTEE input high-level width, low-level width	1.8 V ≤ VCC ≤ 5.5 V		$t_{ACKWH}, t_{ACKWL}$	100	—	—	ns	<a href="#">Figure 2.28</a>	
		1.6 V ≤ VCC < 1.8 V			800	—	—	ns		
	AGTIO, AGTO, AGTOA, AGTOB output cycle	2.7 V ≤ VCC ≤ 5.5 V		$t_{ACYC2}$	62.5	—	—	ns	<a href="#">Figure 2.28</a>	
		2.4 V ≤ VCC < 2.7 V			125	—	—	ns		
		1.8 V ≤ VCC < 2.4 V			250	—	—	ns		
		1.6 V ≤ VCC < 1.8 V			500	—	—	ns		
ADC12	12-bit A/D converter trigger input pulse width			$t_{TRGW}$	1.5	—	—	$t_{Pcyc}$	<a href="#">Figure 2.29</a>	
KINT	KRn ( $n = 00$ to 04) pulse width			$t_{KR}$	250	—	—	ns	<a href="#">Figure 2.30</a>	

Note 1. Constraints on input cycle:  $t_{Pcyc} \times 2$  ( $t_{Pcyc}$ : PCLKB cycle) <  $t_{ACYC}$

Note 2. Reference value

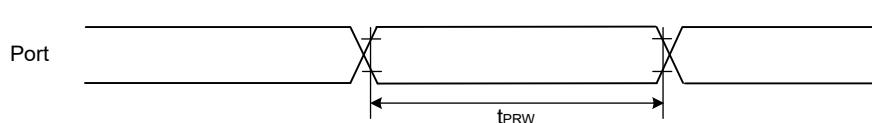


Figure 2.13 I/O ports input timing

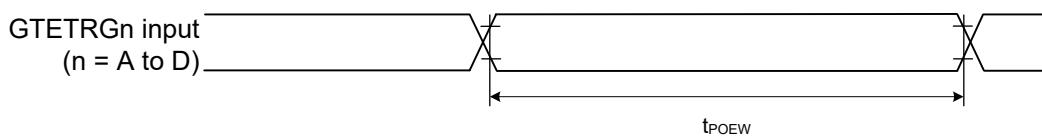


Figure 2.14 POEG input trigger timing

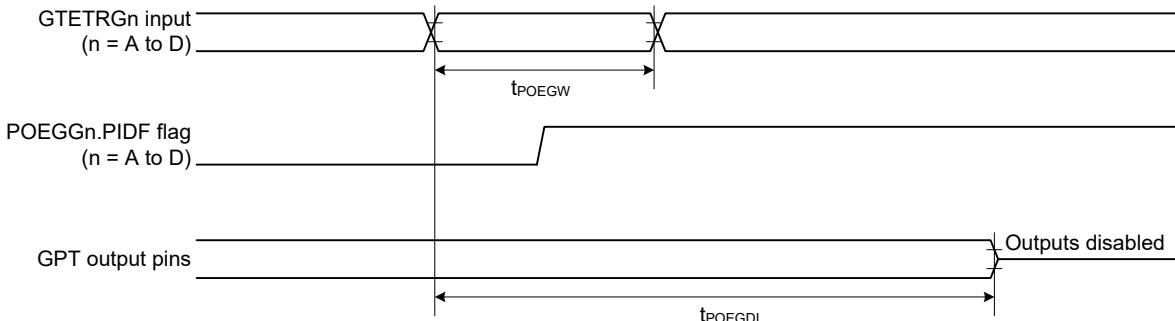
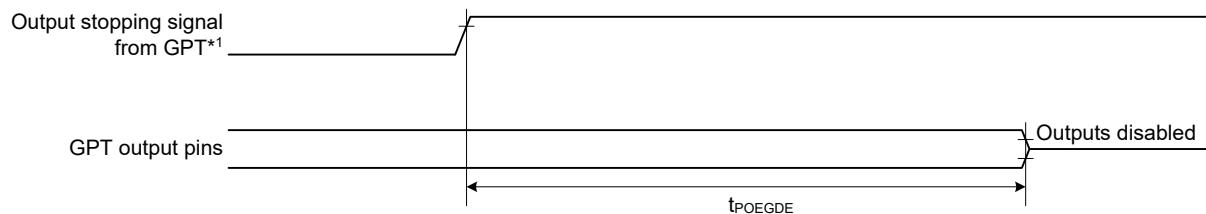


Figure 2.15 Output disable time for POEG via detection flag in response to the input level detection of the GTETRGn pin



Note 1. GPT16n.GTST.DTEF (dead time error flag), GPT32n.GTST.OABL<sub>F</sub> (simultaneous low output flag), or GPT16n.GTST.OABHF (simultaneous high output flag)

Figure 2.16 Output disable time for POEG in response to detection of the output stopping signal from GPT

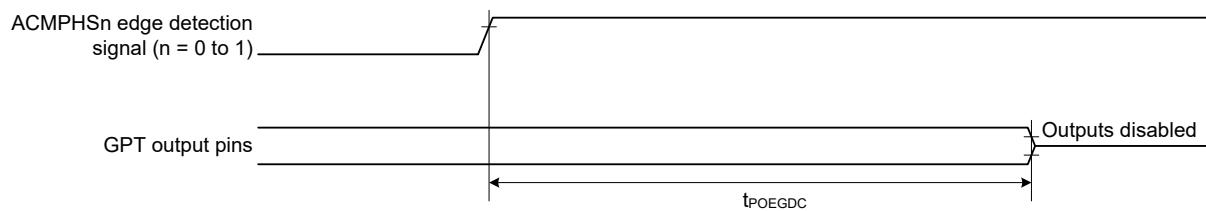
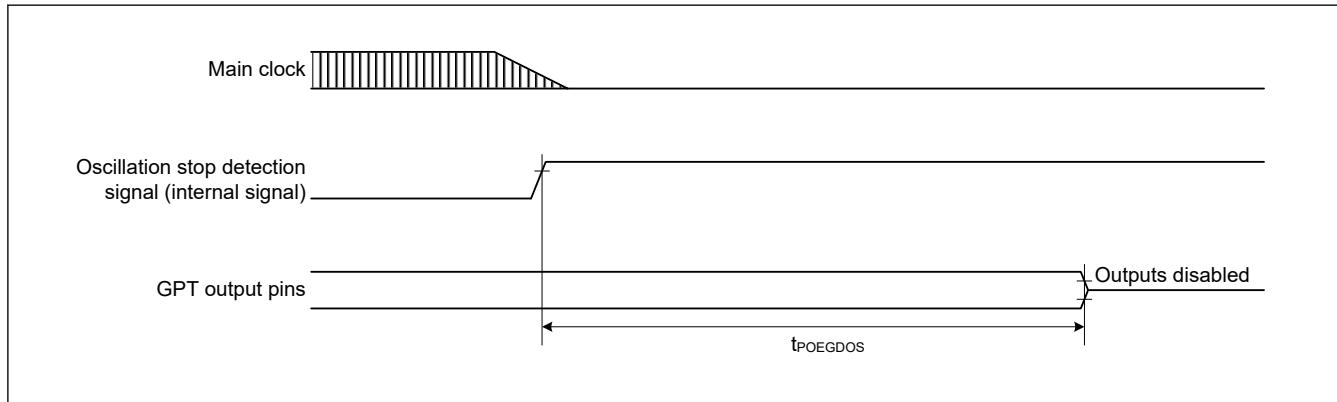


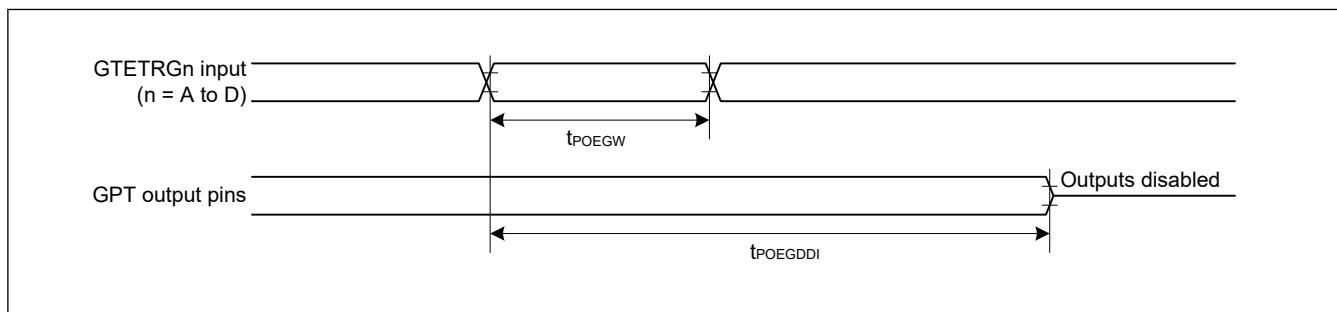
Figure 2.17 Output disable time for POEG in response to edge detection signal from ACMPHS



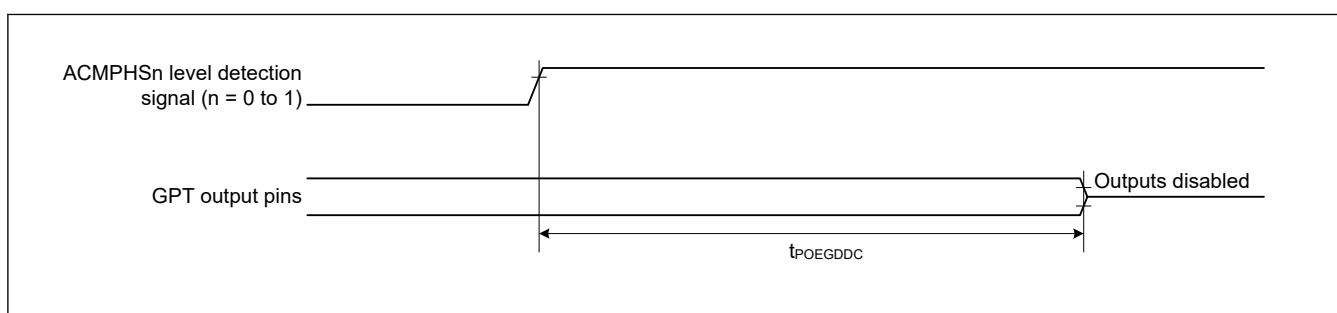
**Figure 2.18** Output disable time for POEG in response to the register setting



**Figure 2.19** Output disable time of POEG in response to the oscillation stop detection



**Figure 2.20** Output disable time for POEG in direct response to the input level detection of the GTETRGn pin



**Figure 2.21** Output disable time for POEG in response to level detection signal from ACMPHS

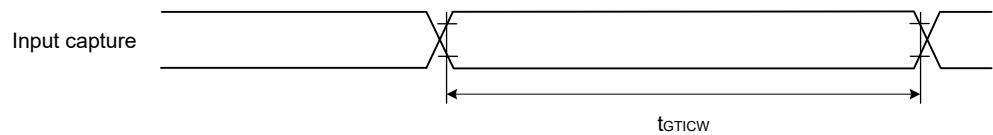


Figure 2.22 GPT input capture timing

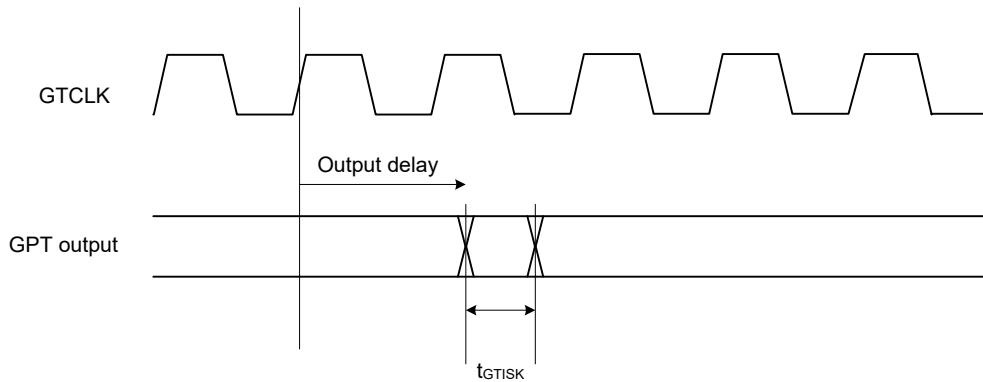


Figure 2.23 GPT output delay skew

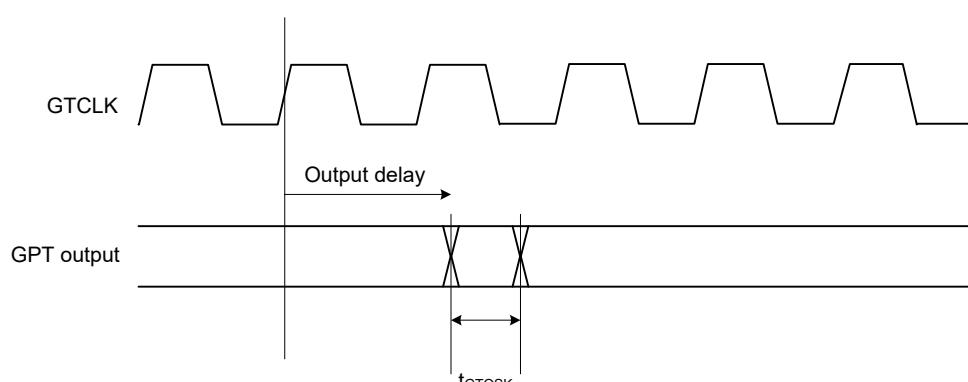


Figure 2.24 GPT output delay skew for OPS

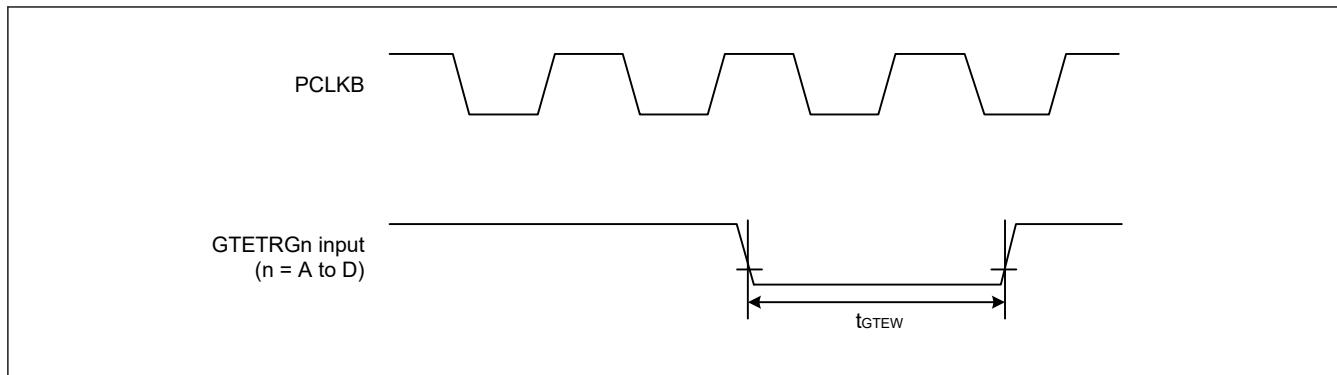


Figure 2.25 GPT external trigger input timing

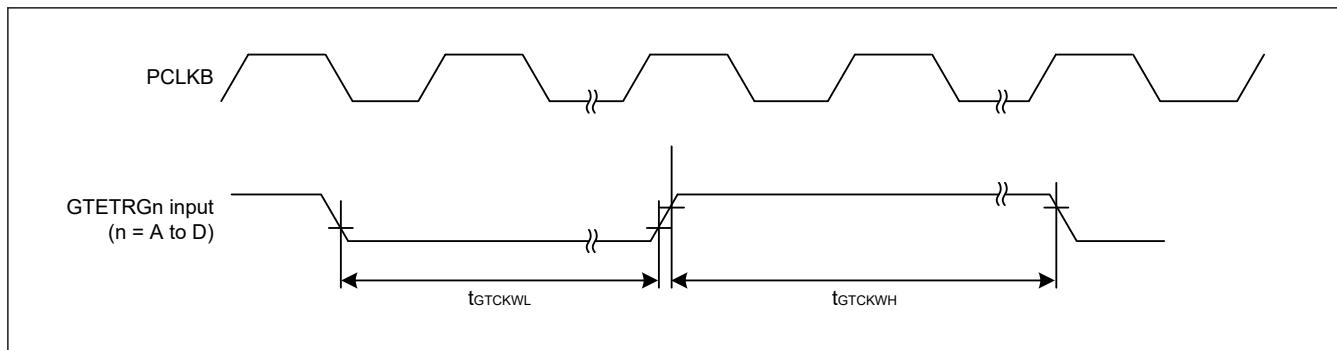


Figure 2.26 GPT clock input timing

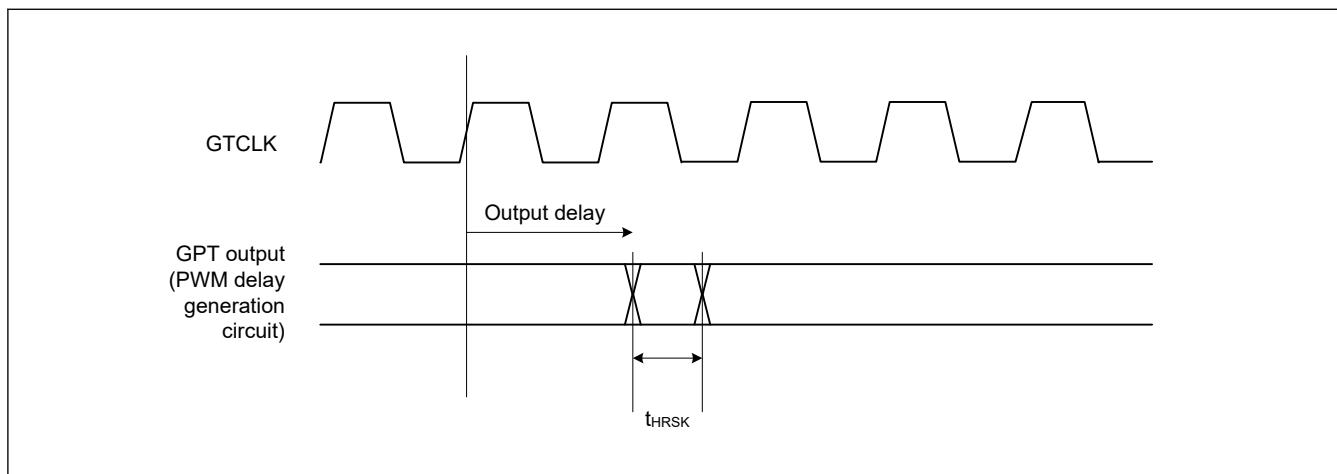


Figure 2.27 GPT (PDG) output delay skew

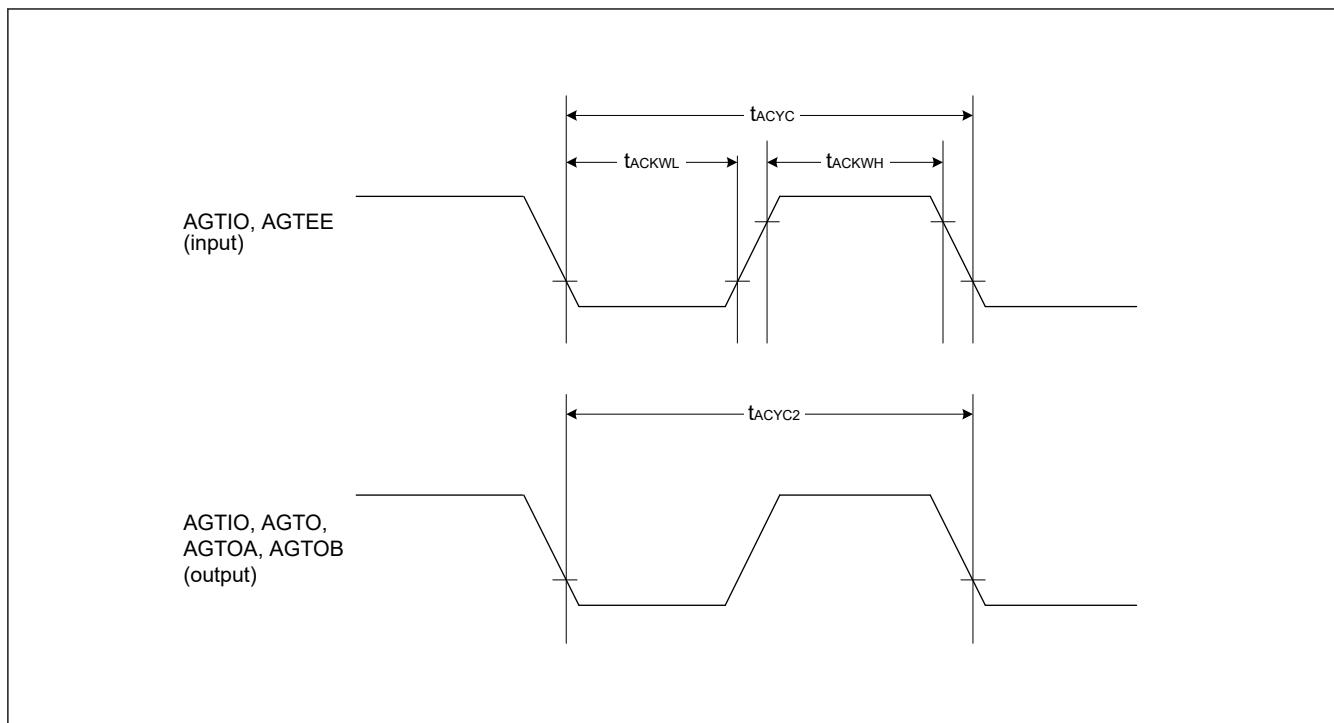


Figure 2.28 AGTW I/O timing

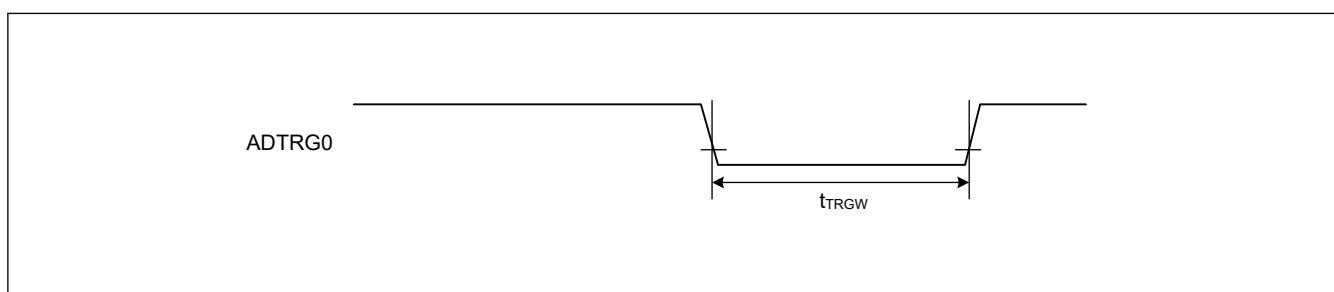


Figure 2.29 ADC12 trigger input timing

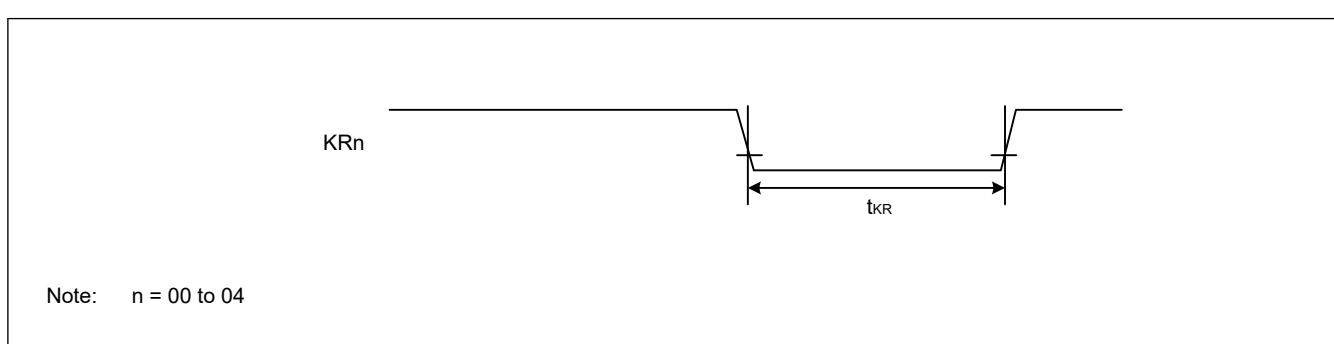


Figure 2.30 Key interrupt input timing

### 2.3.7 CAC Timing

**Table 2.28 CAC timing**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
CAC	CACREF input pulse width	$t_{Pcyc}^{*1} \leq t_{CAC}^{*2}$	$t_{CACREF}$	$4.5 \times t_{CAC} + 3 \times t_{Pcyc}$	—	—	ns
				$5 \times t_{CAC} + 6.5 \times t_{Pcyc}$	—	—	ns

Note 1.  $t_{Pcyc}$ : PCLKB cycle.

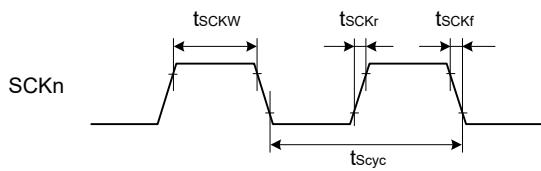
Note 2.  $t_{CAC}$ : CAC count clock source cycle.

### 2.3.8 SCI Timing

**Table 2.29 SCI timing (1)**

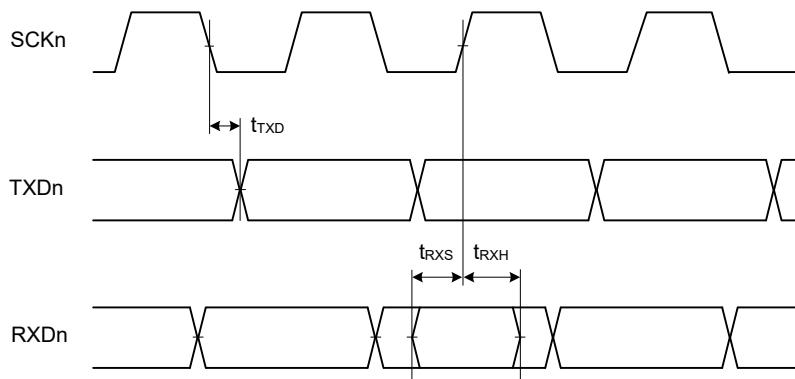
Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter				Symbol	Min	Max	Unit	Test conditions		
SCI	Input clock cycle	Asynchronous	2.7 V ≤ VCC ≤ 5.5 V	t <sub>Scyc</sub>	125	—	ns	Figure 2.31		
			2.4 V ≤ VCC < 2.7 V		250	—				
			1.8 V ≤ VCC < 2.4 V		500	—				
			1.6 V ≤ VCC < 1.8 V		1000	—				
		Clock synchronous	2.7 V ≤ VCC ≤ 5.5 V		187.5	—				
			2.4 V ≤ VCC < 2.7 V		375	—				
			1.8 V ≤ VCC < 2.4 V		750	—				
			1.6 V ≤ VCC < 1.8 V		1500	—				
	Input clock pulse width			t <sub>SCKW</sub>	0.4	0.6	t <sub>Scyc</sub>			
	Input clock rise time			t <sub>SCKr</sub>	—	20	ns			
	Input clock fall time			t <sub>SCKf</sub>	—	20	ns			
	Output clock cycle	Asynchronous	2.7 V ≤ VCC ≤ 5.5 V	t <sub>Scyc</sub>	187.5	—	ns			
			2.4 V ≤ VCC < 2.7 V		375	—				
			1.8 V ≤ VCC < 2.4 V		750	—				
			1.6 V ≤ VCC < 1.8 V		1500	—				
		Clock synchronous	2.7 V ≤ VCC ≤ 5.5 V		125	—				
			2.4 V ≤ VCC < 2.7 V		250	—				
			1.8 V ≤ VCC < 2.4 V		500	—				
			1.6 V ≤ VCC < 1.8 V		1000	—				
	Output clock pulse width			t <sub>SCKW</sub>	0.4	0.6	t <sub>Scyc</sub>			
	Output clock rise time		1.8 V ≤ VCC ≤ 5.5 V	t <sub>SCKr</sub>	—	20	ns			
			1.6 V ≤ VCC < 1.8 V		—	30				
	Output clock fall time		1.8 V ≤ VCC ≤ 5.5 V	t <sub>SCKf</sub>	—	20	ns			
			1.6 V ≤ VCC < 1.8 V		—	30				
	Transmit data delay time (master)	Clock synchronous	1.8 V ≤ VCC ≤ 5.5 V	t <sub>TXD</sub>	—	40	ns	Figure 2.32		
			1.6 V ≤ VCC < 1.8 V		—	45				
	Transmit data delay time (slave)	Clock synchronous	2.7 V ≤ VCC ≤ 5.5 V		—	55	ns			
			2.4 V ≤ VCC < 2.7 V		—	60				
			1.8 V ≤ VCC < 2.4 V		—	100				
			1.6 V ≤ VCC < 1.8 V		—	125				
	Receive data setup time (master)	Clock synchronous	2.7 V ≤ VCC ≤ 5.5 V	t <sub>RXS</sub>	45	—	ns			
			2.4 V ≤ VCC < 2.7 V		55	—				
			1.8 V ≤ VCC < 2.4 V		90	—				
			1.6 V ≤ VCC < 1.8 V		110	—				
	Receive data setup time (slave)	Clock synchronous	2.7 V ≤ VCC ≤ 5.5 V		40	—	ns			
			1.6 V ≤ VCC < 2.7 V		45	—				
	Receive data hold time (master)	Clock synchronous			t <sub>RXH</sub>	5	—	ns		
	Receive data hold time (slave)	Clock synchronous			t <sub>RXH</sub>	40	—	ns		



Note: n = 0 to 2, 9

Figure 2.31 SCK clock input timing



Note: n = 0 to 2, 9

Figure 2.32 SCI input/output timing in clock synchronous mode

**Table 2.30 SCI timing (2) (1 of 2)**

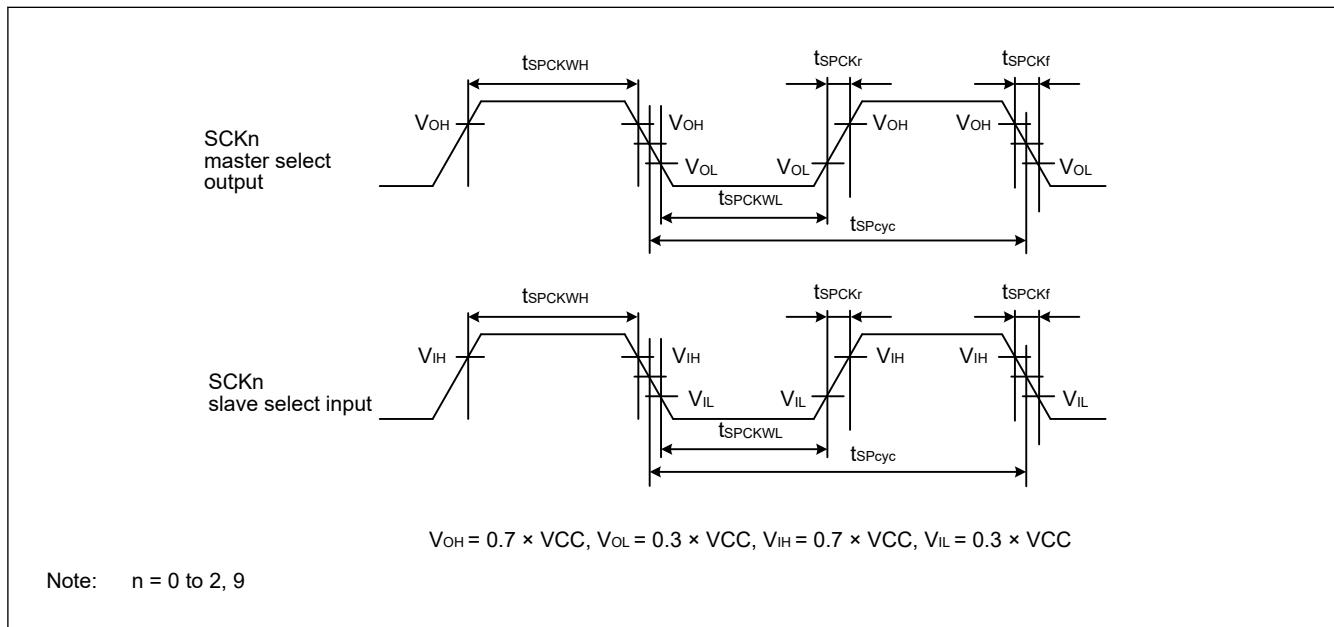
Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter			Symbol	Min	Max	Unit <sup>*1</sup>	Test conditions	
Simple SPI	SCK clock cycle output (master)	2.7 V ≤ VCC ≤ 5.5 V	$t_{SPcyc}$	125	—	ns	<a href="#">Figure 2.33</a>	
		2.4 V ≤ VCC < 2.7 V		250	—			
		1.8 V ≤ VCC < 2.4 V		500	—			
		1.6 V ≤ VCC < 1.8 V		1000	—			
	SCK clock cycle input (slave)	2.7 V ≤ VCC ≤ 5.5 V		187.5	—			
		2.4 V ≤ VCC < 2.7 V		375	—			
		1.8 V ≤ VCC < 2.4 V		750	—			
		1.6 V ≤ VCC < 1.8 V		1500	—			
	SCK clock high pulse width			$t_{SPCKWH}$	0.4	0.6	$t_{SPcyc}$	
	SCK clock low pulse width			$t_{SPCKWL}$	0.4	0.6	$t_{SPcyc}$	
	SCK clock rise and fall time	1.8 V ≤ VCC ≤ 5.5 V	$t_{SPCKr}, t_{SPCKf}$	—	20	ns	<a href="#">Figure 2.34 to Figure 2.37</a>	
		1.6 V ≤ VCC < 1.8 V		—	30			
	Data input setup time	Master	$t_{SU}$	2.7 V ≤ VCC ≤ 5.5 V	45	—		
				2.4 V ≤ VCC < 2.7 V	55	—		
				1.8 V ≤ VCC < 2.4 V	80	—		
				1.6 V ≤ VCC < 1.8 V	110	—		
		Slave		2.7 V ≤ VCC ≤ 5.5 V	40	—		
				1.6 V ≤ VCC < 2.7 V	45	—		
	Data input hold time	Master	$t_H$	—	33.3	—	<a href="#">Figure 2.34 to Figure 2.37</a>	
		Slave		—	40	—		
	SS input setup time			$t_{LEAD}$	1	—	$t_{SPcyc}$	
	SS input hold time			$t_{LAG}$	1	—	$t_{SPcyc}$	
	Data output delay time	Master	$t_{OD}$	1.8 V ≤ VCC ≤ 5.5 V	—	40	<a href="#">Figure 2.34 to Figure 2.37</a>	
				1.6 V ≤ VCC < 1.8 V	—	50		
		Slave		2.4 V ≤ VCC ≤ 5.5 V	—	65		
				1.8 V ≤ VCC < 2.4 V	—	100		
				1.6 V ≤ VCC < 1.8 V	—	125		
				—	—	—		
	Data output hold time	Master	$t_{OH}$	2.7 V ≤ VCC ≤ 5.5 V	-10	—	<a href="#">Figure 2.34 to Figure 2.37</a>	
				2.4 V ≤ VCC < 2.7 V	-20	—		
				1.8 V ≤ VCC < 2.4 V	-30	—		
				1.6 V ≤ VCC < 1.8 V	-40	—		
		Slave		—	-10	—		
		—		—	—	—		
	Data rise and fall time	Master	$t_{DR}, t_{DF}$	1.8 V ≤ VCC ≤ 5.5 V	—	20	<a href="#">Figure 2.34 to Figure 2.37</a>	
				1.6 V ≤ VCC < 1.8 V	—	30		
		Slave		1.8 V ≤ VCC ≤ 5.5 V	—	20		
				1.6 V ≤ VCC < 1.8 V	—	30		
				—	—	—		

**Table 2.30 SCI timing (2) (2 of 2)**

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter			Symbol	Min	Max	Unit <sup>*1</sup>	Test conditions	
Simple SPI	Slave access time	2.4 V ≤ VCC ≤ 5.5 V	t <sub>SA</sub>	—	6	t <sub>Pcyc</sub>	Figure 2.37	
		1.8 V ≤ VCC < 2.4 V		—	7			
		24 MHz ≤ PCLKB ≤ 32 MHz		—	6			
		PCLKB < 24 MHz		—	6			
	Slave output release time	1.6 V ≤ VCC < 1.8 V		—	6			
		2.4 V ≤ VCC ≤ 5.5 V	t <sub>REL</sub>	—	6	t <sub>Pcyc</sub>		
		1.8 V ≤ VCC < 2.4 V		—	7			
		24 MHz ≤ PCLKB ≤ 32 MHz		—	6			
		PCLKB < 24 MHz		—	6			
		1.6 V ≤ VCC < 1.8 V		—	6			

Note 1. t<sub>Pcyc</sub>: PCLKB cycle.**Figure 2.33 SCI simple SPI mode clock timing**

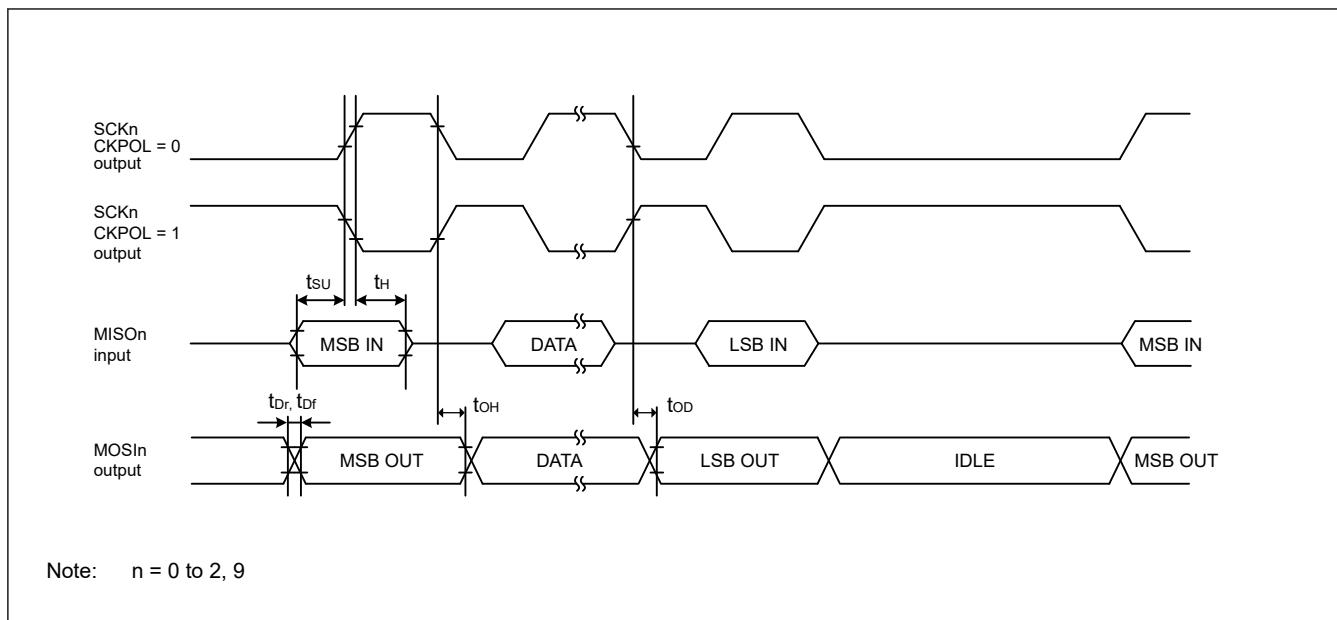


Figure 2.34 SCI simple SPI mode timing (master, CKPH = 1)

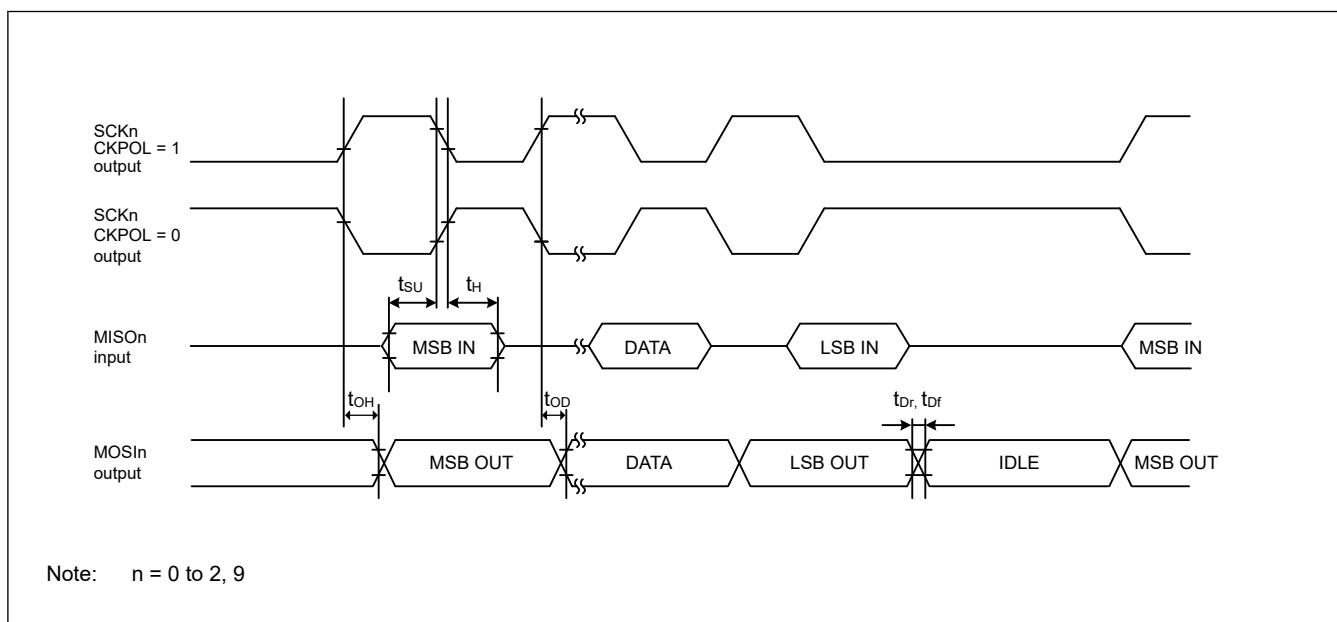
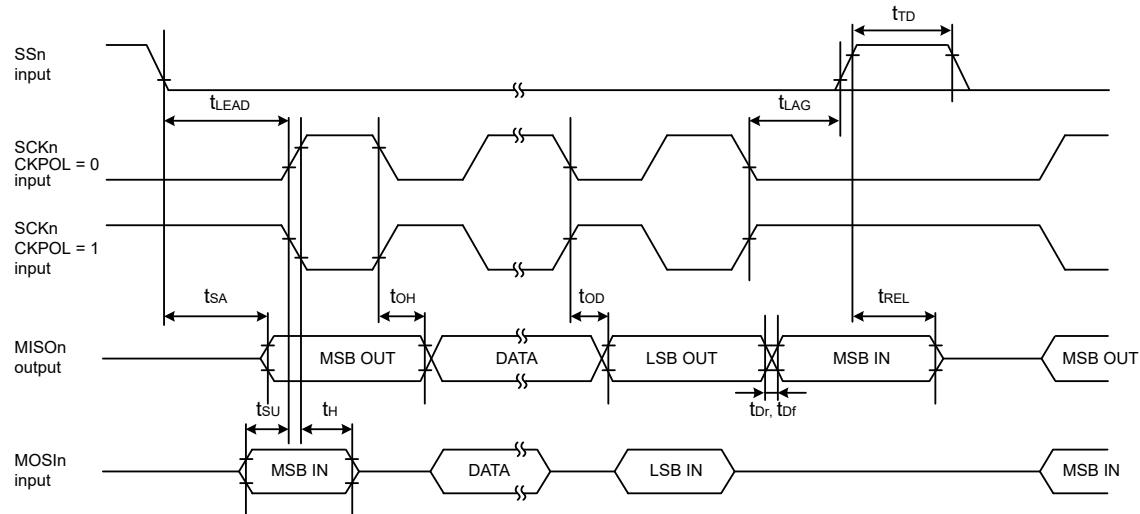
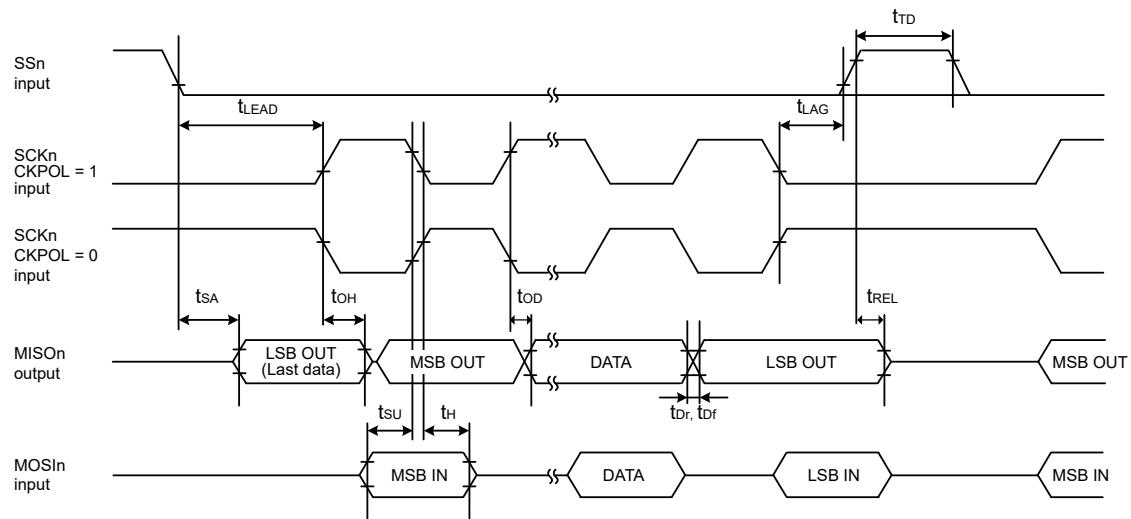


Figure 2.35 SCI simple SPI mode timing (master, CKPH = 0)



Note:  $n = 0$  to 2, 9

Figure 2.36 SCI simple SPI mode timing (slave, CKPH = 1)



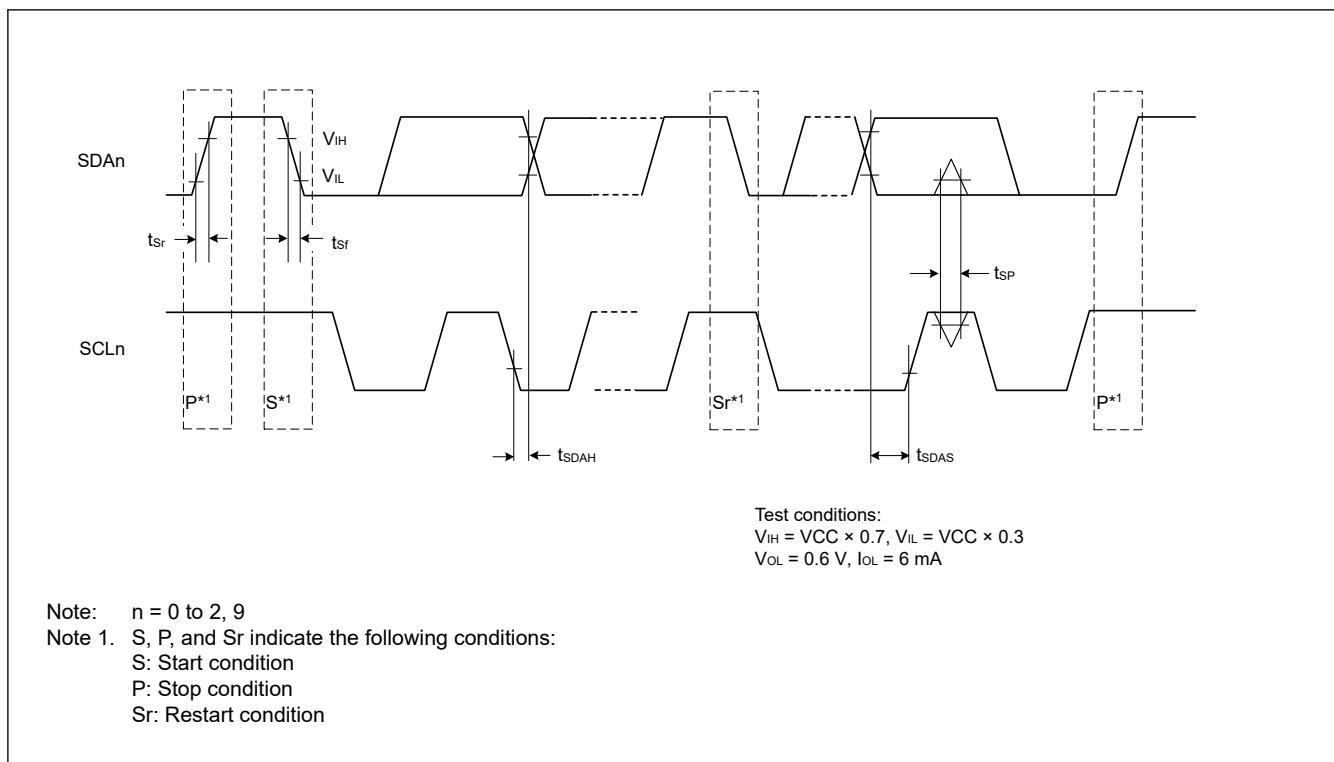
Note:  $n = 0$  to 2, 9

Figure 2.37 SCI simple SPI mode timing (slave, CKPH = 0)

**Table 2.31 SCI timing (3)**

Conditions: VCC = AVCC0 = 2.7 to 5.5 V

Parameter	Symbol	Min	Max	Unit	Test conditions
Simple IIC (Standard mode)	SDA input rise time	$t_{Sr}$	—	1000	ns
	SDA input fall time	$t_{Sf}$	—	300	ns
	SDA input spike pulse removal time	$t_{SP}$	0	$4 \times t_{IICcyc}^{*1}$	ns
	Data input setup time	$t_{SDAS}$	250	—	ns
	Data input hold time	$t_{SDAH}$	0	—	ns
	SCL, SDA capacitive load	$C_b^{*2}$	—	400	pF
Simple IIC (Fast mode)	SDA input rise time	$t_{Sr}$	—	300	ns
	SDA input fall time	$t_{Sf}$	—	300	ns
	SDA input spike pulse removal time	$t_{SP}$	0	$4 \times t_{IICcyc}^{*1}$	ns
	Data input setup time	$t_{SDAS}$	100	—	ns
	Data input hold time	$t_{SDAH}$	0	—	ns
	SCL, SDA capacitive load	$C_b^{*2}$	—	400	pF

Note 1.  $t_{IICcyc}$ : Clock cycle selected by the SMR.CKS[1:0] bits.Note 2.  $C_b$  indicates the total capacity of the bus line.**Figure 2.38 SCI simple IIC mode timing**

## 2.3.9 SPI Timing

Table 2.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit <sup>*1</sup>	Test conditions
SPI RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t <sub>SPcyc</sub>	62.5	—	—	ns	Figure 2.39 C = 30 pF
		2.4 V ≤ VCC < 2.7 V		125	—	—		
		1.8 V ≤ VCC < 2.4 V		250	—	—		
		1.6 V ≤ VCC < 1.8 V		500	—	—		
	Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—	—		
		2.4 V ≤ VCC < 2.7 V		375	—	—		
		1.8 V ≤ VCC < 2.4 V		750	—	—		
		1.6 V ≤ VCC < 1.8 V		1500	—	—		
	RSPCK clock high pulse width	Master		(t <sub>SPcyc</sub> - t <sub>SPCKr</sub> - t <sub>SPCKf</sub> ) / 2 - 3	—	—	ns	
		Slave		3 × t <sub>SPcyc</sub>	—	—		
	RSPCK clock low pulse width	Master	t <sub>SPCKWL</sub>	(t <sub>SPcyc</sub> - t <sub>SPCKr</sub> - t <sub>SPCKf</sub> ) / 2 - 3	—	—	ns	
		Slave		3 × t <sub>SPcyc</sub>	—	—		
	RSPCK clock rise and fall time	Output	t <sub>SPCKr</sub> , t <sub>SPCKf</sub>	2.7 V ≤ VCC ≤ 5.5 V	—	10	ns	
				2.4 V ≤ VCC < 2.7 V	—	15		
				1.8 V ≤ VCC ≤ 2.4 V	—	20		
				1.6 V ≤ VCC < 1.8 V	—	30		
		Input		—	0.1	—	μs/V	

Table 2.32 SPI timing (2 of 3)

Parameter				Symbol	Min	Max	Unit <sup>*1</sup>	Test conditions
SPI	Data input setup time	Master	2.7 V ≤ VCC ≤ 5.5 V	t <sub>SU</sub>	10	—	ns	Figure 2.40 to Figure 2.45 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		30	—		
			16 MHz < PCLKB ≤ 32 MHz		10	—		
			PCLKB ≤ 16 MHz		55	—		
			1.8 V ≤ VCC < 2.4 V		30	—		
			16 MHz < PCLKB ≤ 32 MHz		10	—		
			8 MHz < PCLKB ≤ 16 MHz		10	—		
			PCLKB ≤ 8 MHz		10	—		
			1.6 V ≤ VCC < 1.8 V		10	—		
		Slave	2.4 V ≤ VCC ≤ 5.5 V	t <sub>H</sub>	10	—	ns	Figure 2.40 to Figure 2.45 C = 30 pF
			1.8 V ≤ VCC < 2.4 V		15	—		
			1.6 V ≤ VCC < 1.8 V		20	—		
	Data input hold time	Master (RSPCK is PCLKB/2)		t <sub>HF</sub>	0	—	ns	Figure 2.40 to Figure 2.45 C = 30 pF
		Master (RSPCK is not PCLKB/2)		t <sub>H</sub>	t <sub>Pcyc</sub>	—		
		Slave		t <sub>H</sub>	20	—		
SPI	SSL setup time	Master	1.8 V ≤ VCC ≤ 5.5 V	t <sub>LEAD</sub>	-30 + N × t <sub>SPcyc</sub> <sup>*2</sup>	—	ns	Figure 2.40 to Figure 2.45 C = 30 pF
			1.6 V ≤ VCC < 1.8 V		-50 + N × t <sub>SPcyc</sub> <sup>*2</sup>	—		
		Slave			6 × t <sub>Pcyc</sub>	—		
	SSL hold time	Master		t <sub>LAG</sub>	-30 + N × t <sub>SPcyc</sub> <sup>*3</sup>	—	ns	Figure 2.40 to Figure 2.45 C = 30 pF
		Slave			6 × t <sub>Pcyc</sub>	—		
	Data output delay time	Master	2.7 V ≤ VCC ≤ 5.5 V	t <sub>OD</sub>	—	14	ns	Figure 2.40 to Figure 2.45 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		—	20		
			1.8 V ≤ VCC < 2.4 V		—	25		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		—	50		
			2.4 V ≤ VCC < 2.7 V		—	60		
			1.8 V ≤ VCC < 2.4 V		—	85		
			1.6 V ≤ VCC < 1.8 V		—	110		
	Data output hold time	Master		t <sub>OH</sub>	0	—	ns	Figure 2.40 to Figure 2.45 C = 30 pF
		Slave			0	—		
	Successive transmission delay time	Master		t <sub>TD</sub>	t <sub>SPcyc</sub> + 2 × t <sub>Pcyc</sub>	8 × t <sub>SPcyc</sub> + 2 × t <sub>Pcyc</sub>	ns	Figure 2.40 to Figure 2.45 C = 30 pF
		Slave			6 × t <sub>Pcyc</sub>	—		

Table 2.32 SPI timing (3 of 3)

Parameter				Symbol	Min	Max	Unit <sup>*1</sup>	Test conditions	
SPI MOSI and MISO rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	$t_{Df}$	$t_{Df}$	—	10	ns	Figure 2.40 to Figure 2.45 $C = 30 \text{ pF}$	
		2.4 V ≤ VCC < 2.7 V			—	15			
		1.8 V ≤ VCC < 2.4 V			—	20			
		1.6 V ≤ VCC < 1.8 V			—	30			
	Input				—	1	μs		
	SSL rise and fall time	2.7 V ≤ VCC ≤ 5.5 V	$t_{SSLr}$ , $t_{SSLf}$	$t_{SSLr}$ , $t_{SSLf}$	—	10	ns		
		2.4 V ≤ VCC < 2.7 V			—	15			
		1.8 V ≤ VCC < 2.4 V			—	20			
		1.6 V ≤ VCC < 1.8 V			—	30			
	Input				—	1	μs		
Slave access time		2.4 V ≤ VCC ≤ 5.5 V	$t_{SA}$	$t_{SA}$	—	$2 \times t_{Pcyc} + 100$	ns	Figure 2.44 and Figure 2.45 $C = 30 \text{ pF}$	
		1.8 V ≤ VCC < 2.4 V			—	$2 \times t_{Pcyc} + 140$			
		1.6 V ≤ VCC < 1.8 V			—	$2 \times t_{Pcyc} + 180$			
Slave output release time		2.4 V ≤ VCC ≤ 5.5 V	$t_{REL}$	$t_{REL}$	—	$2 \times t_{Pcyc} + 100$	ns		
		1.8 V ≤ VCC < 2.4 V			—	$2 \times t_{Pcyc} + 140$			
		1.6 V ≤ VCC < 1.8 V			—	$2 \times t_{Pcyc} + 180$			

Note 1.  $t_{Pcyc}$ : PCLKB cycle.

Note 2. N is set as an integer from 1 to 8 by the SPCKD register.

Note 3. N is set as an integer from 1 to 8 by the SSLND register.

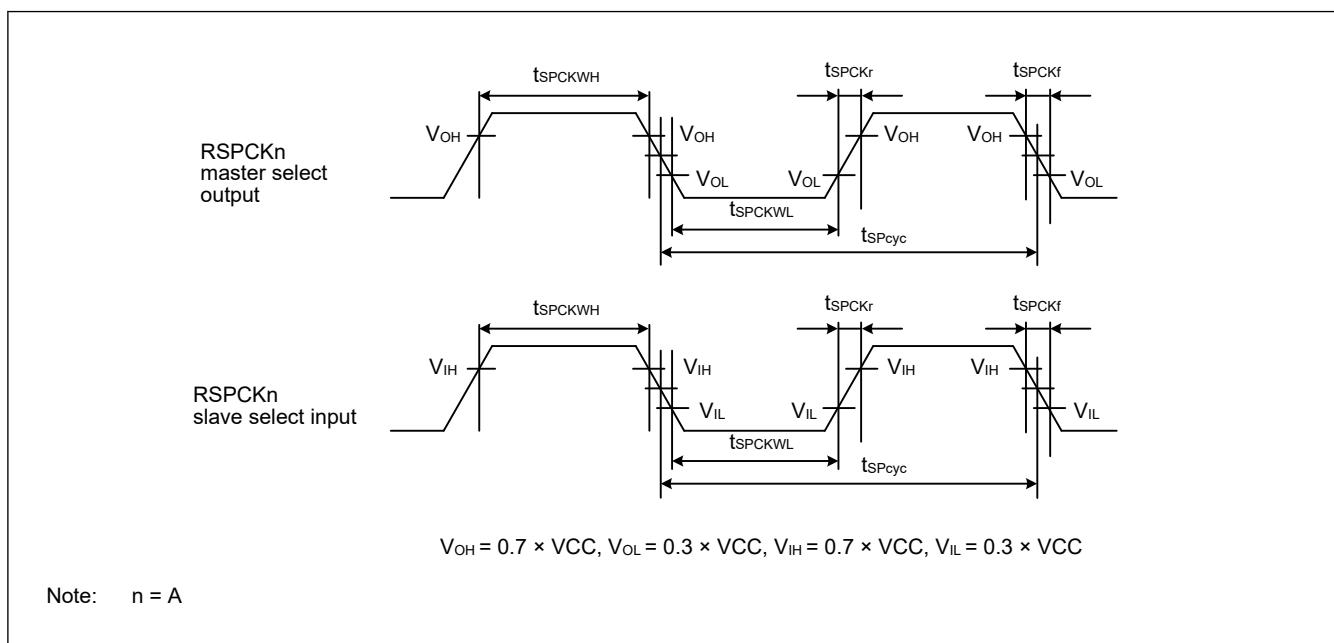


Figure 2.39 SPI clock timing

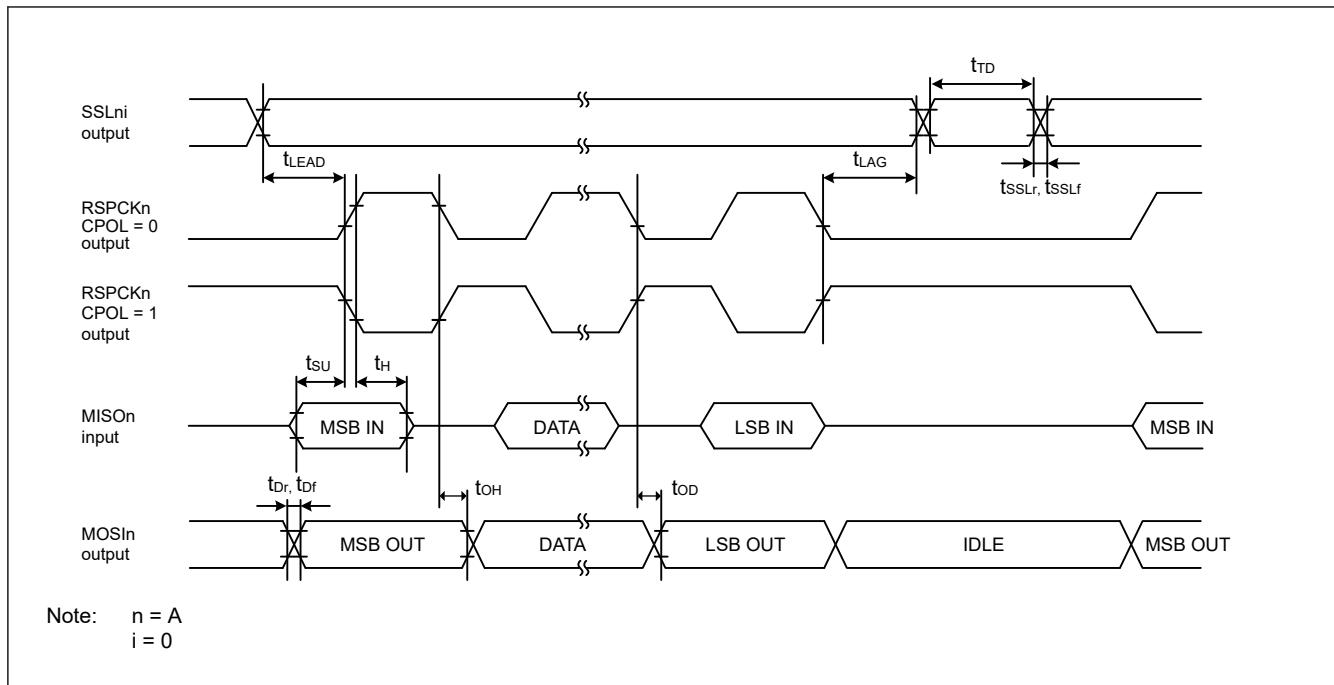


Figure 2.40 SPI timing (master, CPHA = 0) (bit rate: PCLKB division ratio is set to any value other than 1/2)

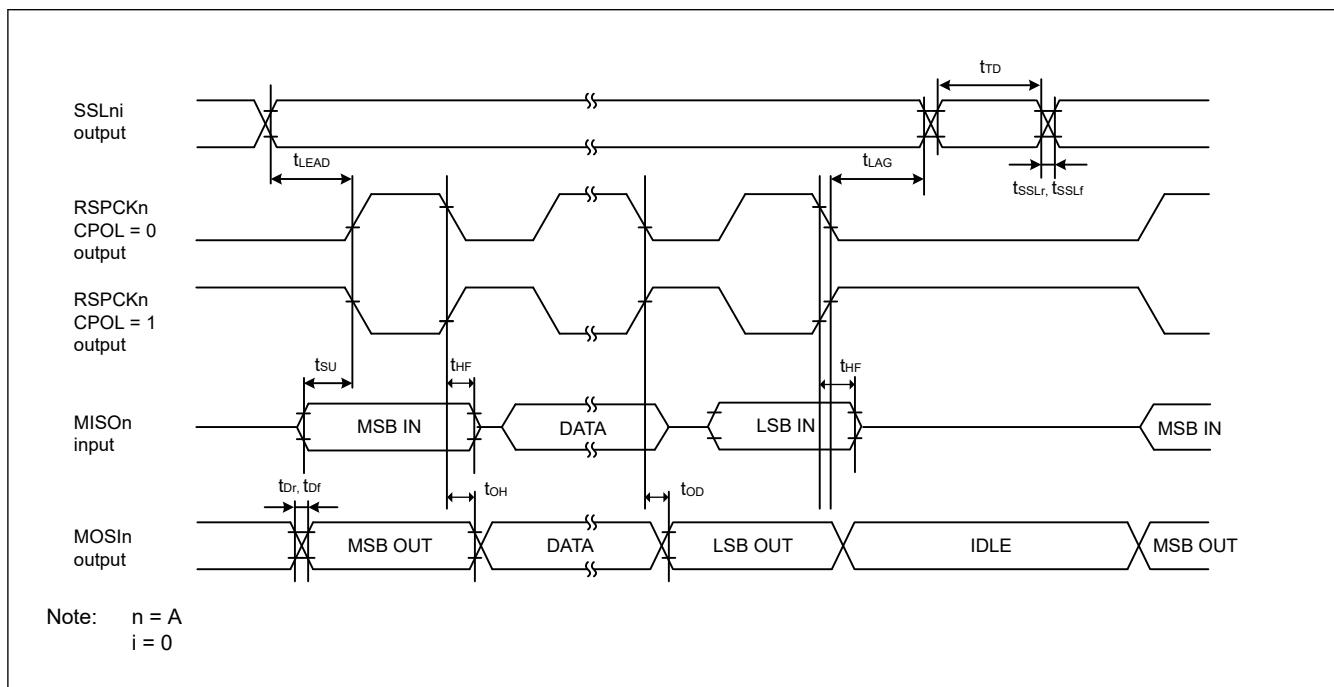


Figure 2.41 SPI timing (master, CPHA = 0) (bit rate: PCLKB division ratio is set to 1/2)

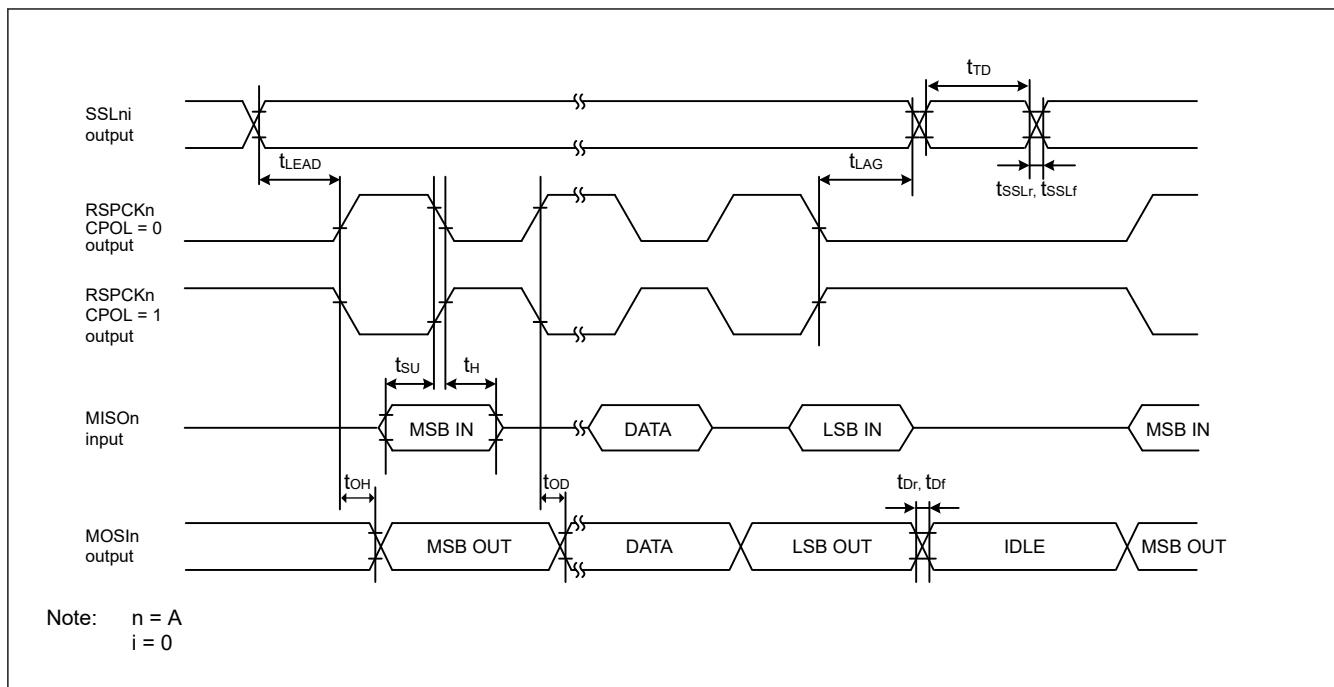


Figure 2.42 SPI timing (master, CPHA = 1) (bit rate: PCLKB division ratio is set to any value other than 1/2)

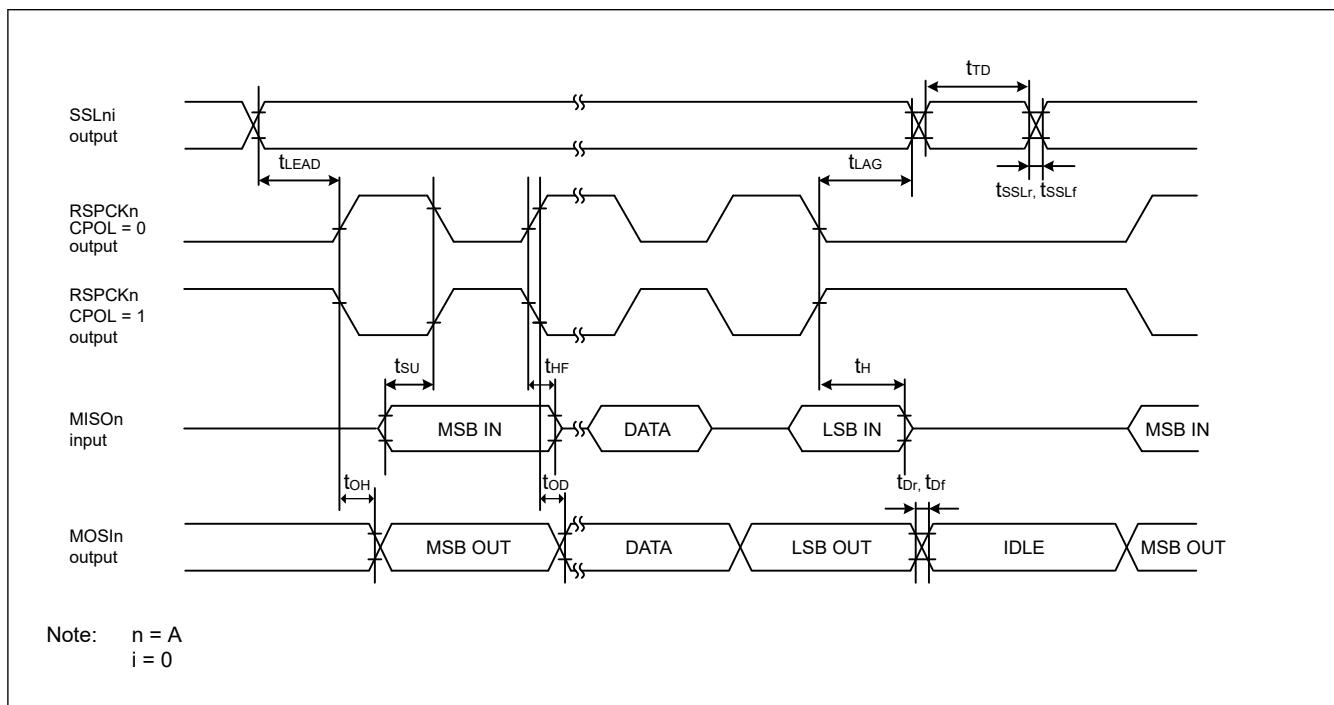


Figure 2.43 SPI timing (master, CPHA = 1) (bit rate: PCLKB division ratio is set to 1/2)

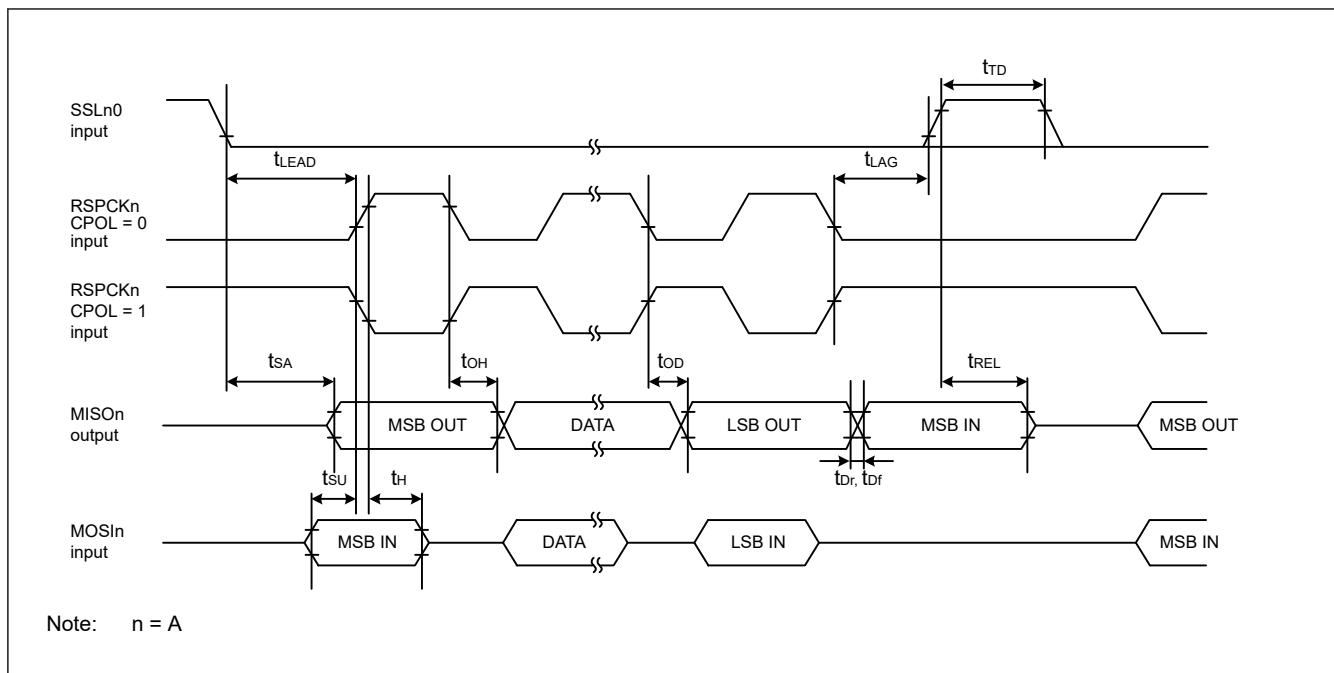


Figure 2.44 SPI timing (slave, CPHA = 0)

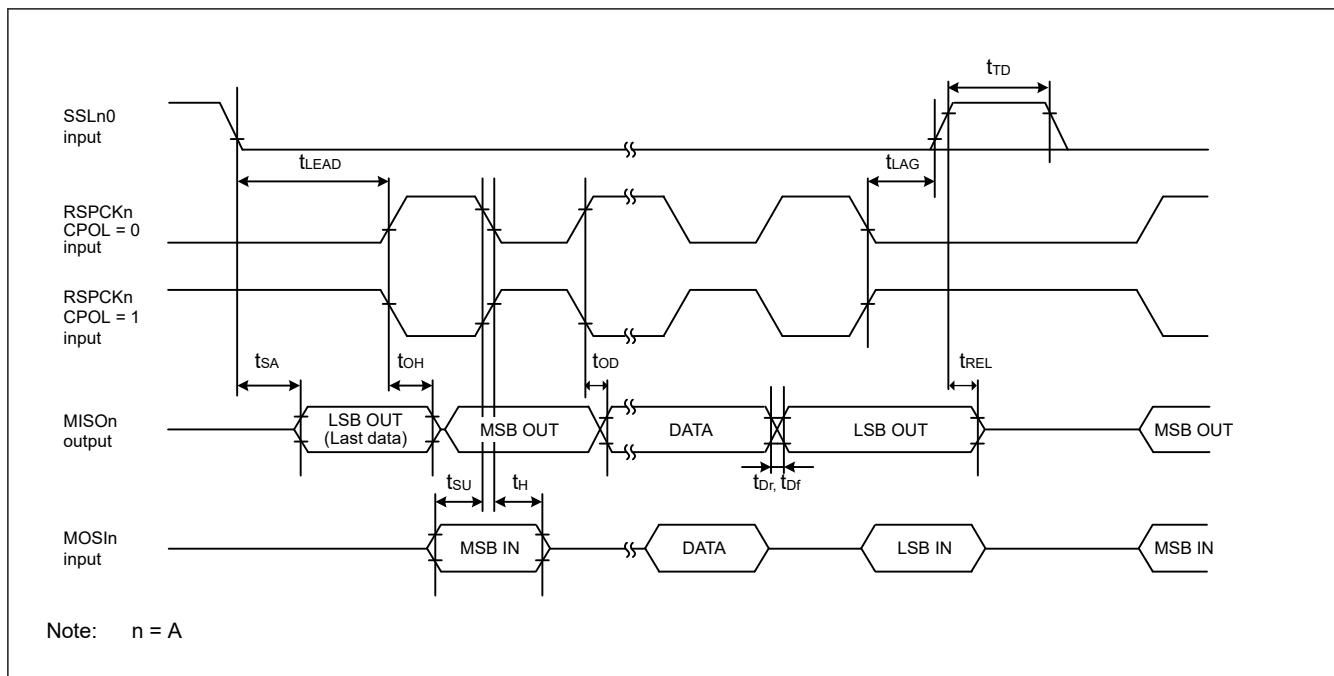


Figure 2.45 SPI timing (slave, CPHA = 1)

### 2.3.10 IIC Timing

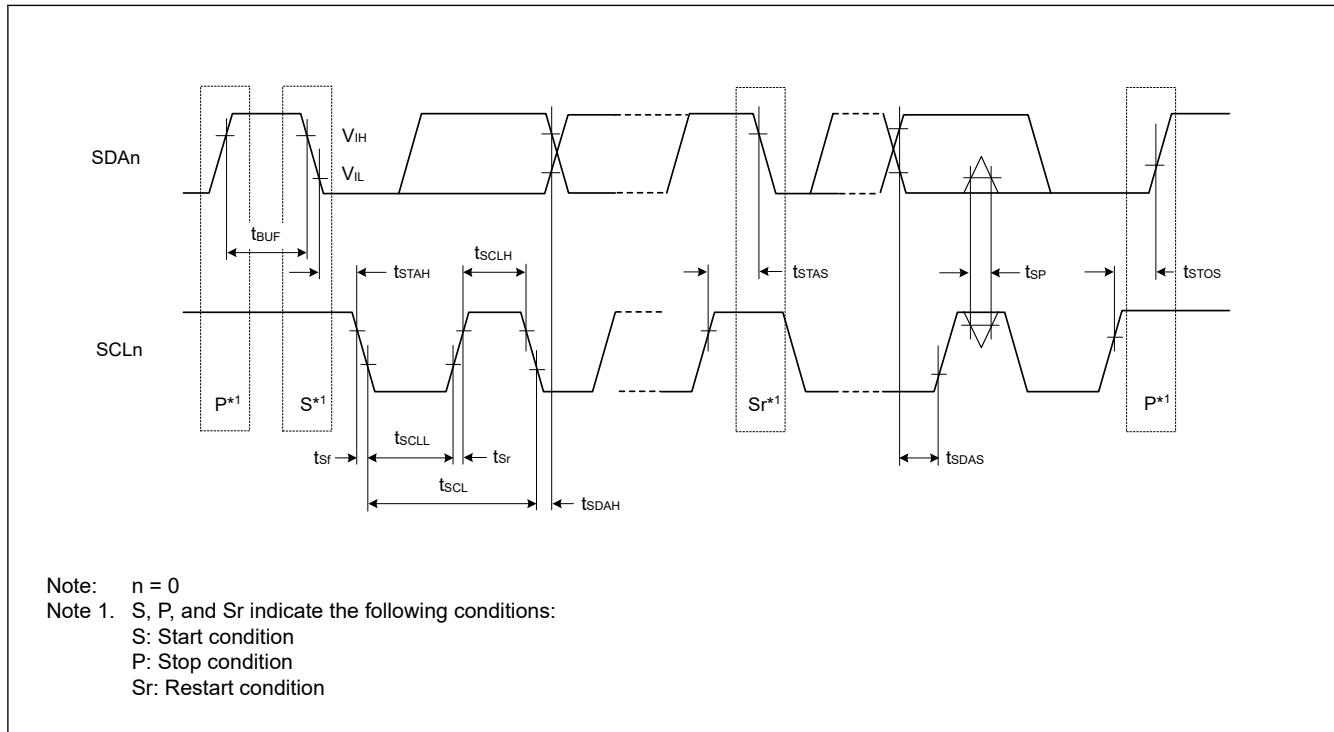
**Table 2.33 IIC timing**

Conditions: VCC = AVCC0 = 2.7 to 5.5 V

Parameter	Symbol	Min <sup>*1</sup>	Max	Unit	Test conditions
IIC (standard mode, SMBus)	SCL input cycle time	$t_{SCL}$	$6(12) \times t_{IICcyc} + 1300$	—	ns
	SCL input high pulse width	$t_{SCLH}$	$3(6) \times t_{IICcyc} + 300$	—	ns
	SCL input low pulse width	$t_{SCLL}$	$3(6) \times t_{IICcyc} + 300$	—	ns
	SCL, SDA input rise time	$t_{Sr}$	—	1000	ns
	SCL, SDA input fall time	$t_{Sf}$	—	300	ns
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$1(4) \times t_{IICcyc}$	ns
	SDA input bus free time (when wakeup function is disabled)	$t_{BUF}$	$3(6) \times t_{IICcyc} + 300$	—	ns
	SDA input bus free time (when wakeup function is enabled)	$t_{BUF}$	$3(6) \times t_{IICcyc} + 4 \times t_{Pcyc} + 300$	—	ns
	START condition input hold time (when wakeup function is disabled)	$t_{STAH}$	$t_{IICcyc} + 300$	—	ns
	START condition input hold time (when wakeup function is enabled)	$t_{STAH}$	$1(5) \times t_{IICcyc} + t_{Pcyc} + 300$	—	ns
	Repeated START condition input setup time	$t_{STAS}$	1000	—	ns
	STOP condition input setup time	$t_{STOS}$	1000	—	ns
	Data input setup time	$t_{SDAS}$	$t_{IICcyc} + 50$	—	ns
	Data input hold time	$t_{SDAH}$	0	—	ns
	SCL, SDA capacitive load	$C_b$	—	400	pF
IIC (Fast mode)	SCL input cycle time	$t_{SCL}$	$6(12) \times t_{IICcyc} + 600$	—	ns
	SCL input high pulse width	$t_{SCLH}$	$3(6) \times t_{IICcyc} + 300$	—	ns
	SCL input low pulse width	$t_{SCLL}$	$3(6) \times t_{IICcyc} + 300$	—	ns
	SCL, SDA input rise time	$t_{Sr}$	—	300	ns
	SCL, SDA input fall time	$t_{Sf}$	—	300	ns
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$1(4) \times t_{IICcyc}$	ns
	SDA input bus free time (When wakeup function is disabled)	$t_{BUF}$	$3(6) \times t_{IICcyc} + 300$	—	ns
	SDA input bus free time (When wakeup function is enabled)	$t_{BUF}$	$3(6) \times t_{IICcyc} + 4 \times t_{Pcyc} + 300$	—	ns
	START condition input hold time (When wakeup function is disabled)	$t_{STAH}$	$t_{IICcyc} + 300$	—	ns
	START condition input hold time (When wakeup function is enabled)	$t_{STAH}$	$1(5) \times t_{IICcyc} + t_{Pcyc} + 300$	—	ns
	Repeated START condition input setup time	$t_{STAS}$	300	—	ns
	STOP condition input setup time	$t_{STOS}$	300	—	ns
	Data input setup time	$t_{SDAS}$	$t_{IICcyc} + 50$	—	ns
	Data input hold time	$t_{SDAH}$	0	—	ns
	SCL, SDA capacitive load	$C_b$	—	400	pF

Note:  $t_{IICcyc}$ : IIC internal reference clock (IIC $\phi$ ) cycle,  $t_{Pcyc}$ : PCLKB cycle

Note 1. Values in parentheses apply when ICMR3.NF[1:0] is set to 11b while the digital filter is enabled with ICFER.NFE set to 1.



**Figure 2.46** I<sup>2</sup>C bus interface input/output timing

### 2.3.11 CLKOUT Timing

**Table 2.34** CLKOUT timing

Parameter		Symbol	Min	Max	Unit	Test conditions
CLKOUT	CLKOUT pin output cycle <sup>*1</sup>	2.7 V ≤ VCC ≤ 5.5 V	t <sub>Cyc</sub>	62.5	—	ns
		1.8 V ≤ VCC < 2.7 V		125	—	
		1.6 V ≤ VCC < 1.8 V		250	—	
	CLKOUT pin high pulse width <sup>*2</sup>	2.7 V ≤ VCC ≤ 5.5 V	t <sub>CH</sub>	15	—	ns
		1.8 V ≤ VCC < 2.7 V		30	—	
		1.6 V ≤ VCC < 1.8 V		150	—	
	CLKOUT pin low pulse width <sup>*2</sup>	2.7 V ≤ VCC ≤ 5.5 V	t <sub>CL</sub>	15	—	ns
		1.8 V ≤ VCC < 2.7 V		30	—	
		1.6 V ≤ VCC < 1.8 V		150	—	
	CLKOUT pin output rise time	2.7 V ≤ VCC ≤ 5.5 V	t <sub>Cr</sub>	—	12	ns
		1.8 V ≤ VCC < 2.7 V		—	25	
		1.6 V ≤ VCC < 1.8 V		—	50	
	CLKOUT pin output fall time	2.7 V ≤ VCC ≤ 5.5 V	t <sub>Cf</sub>	—	12	ns
		1.8 V ≤ VCC < 2.7 V		—	25	
		1.6 V ≤ VCC < 1.8 V		—	50	

Note 1. When the EXTAL external clock input or an oscillator is used with division by 1 (the CKOCR.CKOSEL[2:0] bits are 011b and the CKOCR.CKODIV[2:0] bits are 000b) to output from CLKOUT, specifications in Table 2.34 should be satisfied with 45% to 55% of input duty cycle.

Note 2. When MOCO is selected as the clock output source (the CKOCR.CKOSEL[2:0] bits are 001b), set the clock output division ratio to be divided by 2 (the CKOCR.CKODIV[2:0] bits are 001b).

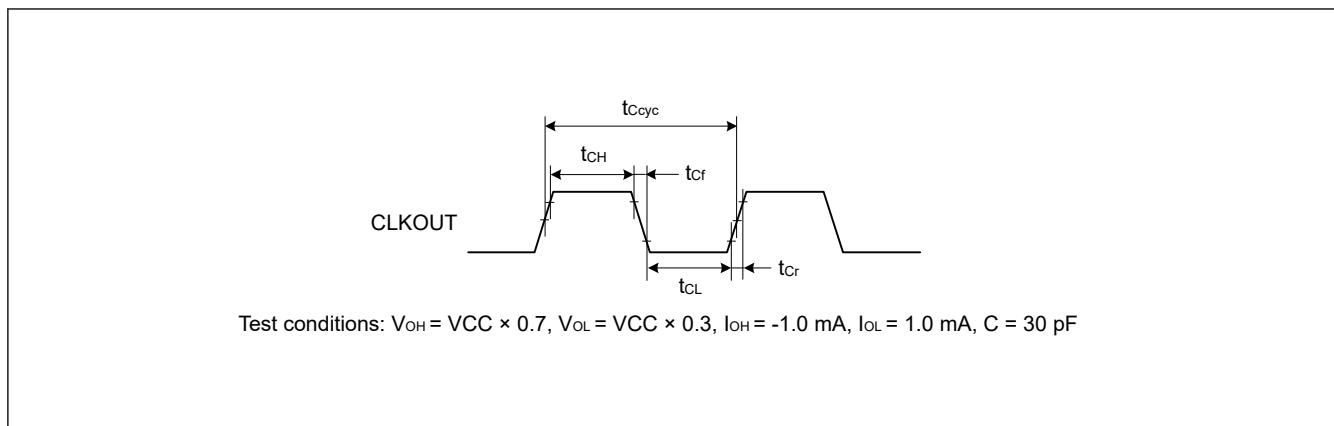


Figure 2.47 CLKOUT output timing

## 2.4 ADC12 Characteristics

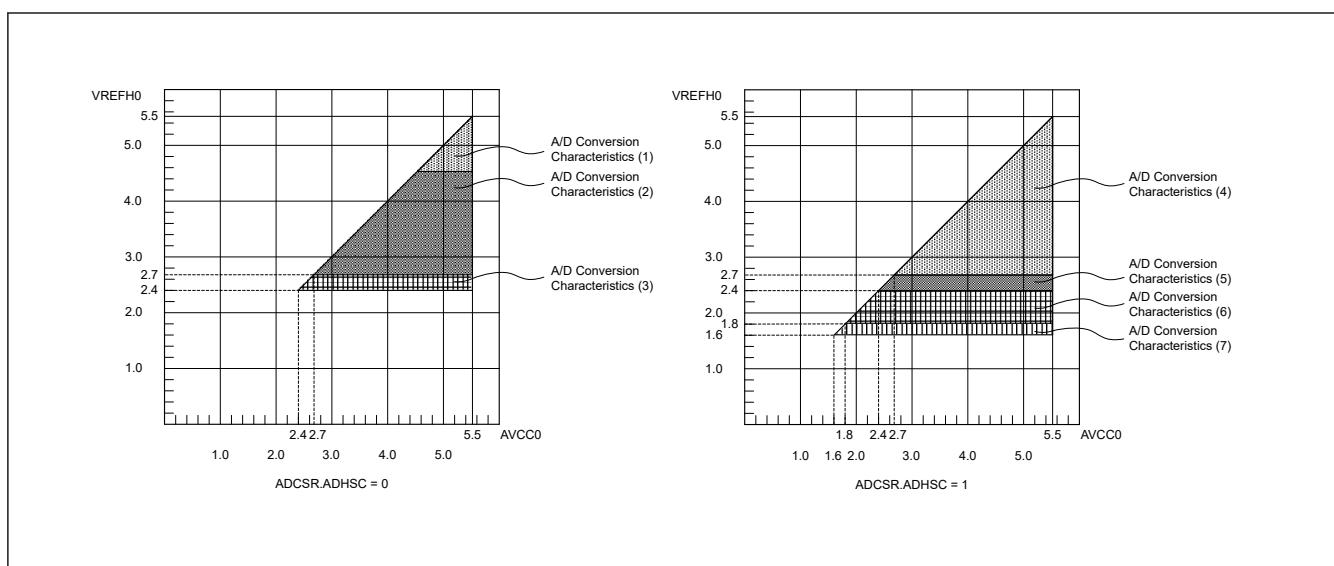


Figure 2.48 AVCC0 to VREFH0 voltage range

Table 2.35 A/D conversion characteristics (1) in high-speed A/D conversion mode (1 of 2)

Conditions:  $V_{CC} = AVCC_0 = V_{REFH0} = 4.5 \text{ to } 5.5 \text{ V}^5$ ,  $V_{SS} = AVSS_0 = V_{REFL0} = 0 \text{ V}$ 

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
PCLKD (ADCLK) frequency	1	—	64	MHz	ADACSR.ADSAC = 0
		—	48	MHz	ADACSR.ADSAC = 1
Analog input capacitance <sup>*2</sup>	Cs	—	$9^{*3}$	pF	High-precision channel
		—	$10^{*3}$	pF	Normal-precision channel
Analog input resistance	Rs	—	$1.3^{*3}$	kΩ	High-precision channel
		—	$5.0^{*3}$	kΩ	Normal-precision channel
Analog input voltage range	Ain	0	$V_{REFH0}$	V	—
Resolution	—	—	12	Bit	—

**Table 2.35 A/D conversion characteristics (1) in high-speed A/D conversion mode (2 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 4.5 to 5.5 V<sup>5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter		Min	Typ	Max	Unit	Test conditions	
Conversion time <sup>1</sup> (Operation at PCLKD = 64 MHz)	Permissible signal source impedance Max. = 0.3 kΩ	0.70 (0.211) <sup>4</sup>	—	—	μs	High-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0D ADACSR.ADSAC = 0	
		1.30 (0.406+0.211) <sup>4</sup>	—	—	μs	High-precision channel dedicated sample-and-hold circuits in use (AN000 to AN002) ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0D ADACSR.ADSAC = 0 ADSHCR.SSTSH[7:0] = 0x1A	
		1.34 (0.852) <sup>4</sup>	—	—	μs	Normal-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x36 ADACSR.ADSAC = 0	
Conversion time <sup>1</sup> (Operation at PCLKD = 48 MHz)	Permissible signal source impedance Max. = 0.3 kΩ	0.67 (0.219) <sup>4</sup>	—	—	μs	High-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1	
		1.33 (0.417+0.219) <sup>4</sup>	—	—	μs	High-precision channel dedicated sample-and-hold circuits in use (AN000 to AN002) ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1 ADSHCR.SSTSH[7:0] = 0x14	
		1.29 (0.844) <sup>4</sup>	—	—	μs	Normal-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x28 ADACSR.ADSAC = 1	
Offset error		—	±1.0	±4.5 ±6.0	LSB	High-precision channel Other than specified	
Full-scale error		—	±1.0	±4.5 ±6.0	LSB	High-precision channel Other than specified	
Quantization error		—	±0.5	—	LSB	—	
Absolute accuracy		—	±2.5	±5.0 ±7 ±8.0	LSB	High-precision channel High-precision channel when the sample-and-hold circuit is in use (0.25 V ≤ VAIN ≤ AVCC0 – 0.25 V) Other than specified	
DNL differential nonlinearity error		—	±1.0	—	LSB	—	
INL integral nonlinearity error		—	±1.5	±3.0	LSB	—	
Holding characteristics of sample-and-hold circuits		—	—	10 <sup>-6</sup>	μs	—	

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance (Cin), see [section 2.2.4. I/O V<sub>OH</sub>, V<sub>OL</sub>, and Other Characteristics](#).

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When VREFH0 < AVCC0, the MAX. values are as follows.

Absolute accuracy/Offset error/Full-scale error:

For voltage difference between AVCC0 and VREFH0, it should be added  $\pm 0.75$  LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between AVCC0 and VREFH0, it should be added  $\pm 0.2$  LSB/V to the Max spec.

Note 6. For 3 channel simultaneous sampling: When using a 3 channel S/H circuit, there is a restriction that one AD conversion should be  $3.3 \mu\text{s}$  or less ( $3.3 \mu\text{s} \times 3 < \text{Max } 10 \mu\text{s}$ ).

**Table 2.36 A/D conversion characteristics (2) in high-speed A/D conversion mode**

Conditions: VCC = AVCC0 = VREFH0 = 2.7 to 5.5 V<sup>5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter		Min	Typ	Max	Unit	Test conditions
PCLKD (ADCLK) frequency		1	—	48	MHz	—
Analog input capacitance <sup>2</sup>	Cs	—	—	$9^{*3}$	pF	High-precision channel
		—	—	$10^{*3}$	pF	Normal-precision channel
Analog input resistance	Rs	—	—	$1.9^{*3}$	kΩ	High-precision channel
		—	—	$6.0^{*3}$	kΩ	Normal-precision channel
Analog input voltage range	Ain	0	—	VREFH0	V	—
Resolution		—	—	12	Bit	—
Conversion time <sup>1</sup> (Operation at PCLKD = 48 MHz)	Permissible signal source impedance Max. = 0.3 kΩ	0.67 (0.219) <sup>*4</sup>	—	—	μs	High-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1
		1.33 (0.417+0.219) <sup>*4</sup>	—	—	μs	High-precision channel dedicated sample-and-hold circuits in use (AN000 to AN002) ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1 ADSHCR.SSTSH[7:0] = 0x14
		1.29 (0.844) <sup>*4</sup>	—	—	μs	Normal-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x28 ADACSR.ADSAC = 1
Offset error		—	$\pm 1.0$	$\pm 5.5$	LSB	High-precision channel
				$\pm 7.0$	LSB	Other than specified
Full-scale error		—	$\pm 1.0$	$\pm 5.5$	LSB	High-precision channel
				$\pm 7.0$	LSB	Other than specified
Quantization error		—	$\pm 0.5$	—	LSB	—
Absolute accuracy		—	$\pm 2.5$	$\pm 6.0$	LSB	High-precision channel
				$\pm 8.5$	LSB	High-precision channel when the sample-and-hold circuit is in use (0.25 V ≤ VAIN ≤ AVCC0 – 0.25 V)
				$\pm 9.0$	LSB	Other than specified
DNL differential nonlinearity error		—	$\pm 1.0$	—	LSB	—
INL integral nonlinearity error		—	$\pm 1.5$	$\pm 3.0$	LSB	—
Holding characteristics of sample-and-hold circuits		—	—	$10^{*6}$	μs	—

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance (Cin), see section 2.2.4. I/O VoH, VoL, and Other Characteristics.

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When VREFH0 < AVCC0, the MAX. values are as follows.

Absolute accuracy/Offset error/Full-scale error:

For voltage difference between AVCC0 and VREFH0, it should be added  $\pm 0.75$  LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between AVCC0 and VREFH0, it should be added  $\pm 0.2$  LSB/V to the Max spec.

Note 6. For 3 channel simultaneous sampling: When using a 3 channel S/H circuit, there is a restriction that one AD conversion should be  $3.3 \mu s$  or less ( $3.3 \mu s \times 3 < \text{Max } 10 \mu s$ ).

**Table 2.37 A/D conversion characteristics (3) in high-speed A/D conversion mode**

Conditions: VCC = AVCC0 = VREFH0 = 2.4 to 5.5 V<sup>5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter		Min		Max	Unit	Test conditions
PCLKD (ADCLK) frequency		1	—	32	MHz	—
Analog input capacitance <sup>*2</sup>	Cs	—	—	9 <sup>*3</sup>	pF	High-precision channel
		—	—	10 <sup>*3</sup>	pF	Normal-precision channel
Analog input resistance	Rs	—	—	2.2 <sup>*3</sup>	kΩ	High-precision channel
		—	—	7.0 <sup>*3</sup>	kΩ	Normal-precision channel
Analog input voltage range	Ain	0	—	VREFH0	V	—
Resolution		—	—	12	Bit	—
Conversion time <sup>*1</sup> (Operation at PCLKD = 32 MHz)	Permissible signal source impedance Max. = 1.3 kΩ	1.00 (0.328) <sup>*4</sup>	—	—	μs	High-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1
		1.94 (1.266) <sup>*4</sup>	—	—	μs	Normal-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0x28 ADACSR.ADSAC = 1
Offset error		—	±1.0	±5.5	LSB	High-precision channel
		—	—	±7.0	LSB	Other than specified
Full-scale error		—	±1.0	±5.5	LSB	High-precision channel
		—	—	±7.0	LSB	Other than specified
Quantization error		—	±0.5	—	LSB	—
Absolute accuracy		—	±2.50	±6.0	LSB	High-precision channel
		—	—	±9.0	LSB	Other than specified
DNL differential nonlinearity error		—	±1.0	—	LSB	—
INL integral nonlinearity error		—	±1.5	±3.0	LSB	—

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance (Cin), see [section 2.2.4. I/O V<sub>OH</sub>, V<sub>OL</sub>, and Other Characteristics](#).

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When VREFH0 < AVCC0, the MAX. values are as follows.

Absolute accuracy/Offset error/Full-scale error:

For voltage difference between AVCC0 and VREFH0, it should be added  $\pm 0.75$  LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between AVCC0 and VREFH0, it should be added  $\pm 0.2$  LSB/V to the Max spec.

**Table 2.38 A/D conversion characteristics (4) in low-power A/D conversion mode (1 of 2)**

Conditions: VCC = AVCC0 = VREFH0 = 2.7 to 5.5 V<sup>5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
PCLKD (ADCLK) frequency	1	—	24	MHz	—

**Table 2.38 A/D conversion characteristics (4) in low-power A/D conversion mode (2 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 2.7 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter		Min	Typ	Max	Unit	Test conditions	
Analog input capacitance <sup>*2</sup>	Cs	—	—	9 <sup>*3</sup>	pF	High-precision channel	
		—	—	10 <sup>*3</sup>	pF	Normal-precision channel	
Analog input resistance	Rs	—	—	1.9 <sup>*3</sup>	kΩ	High-precision channel	
		—	—	6 <sup>*3</sup>	kΩ	Normal-precision channel	
Analog input voltage range	Ain	0	—	VREFH0	V	—	
Resolution		—	—	12	Bit	—	
Conversion time <sup>*1</sup> (Operation at PCLKD = 24 MHz)	Permissible signal source impedance Max. = 1.1 kΩ	1.58 (0.438) <sup>*4</sup>	—	—	μs	High-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1	
		2.0 (0.854) <sup>*4</sup>	—	—	μs	Normal-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x14 ADACSR.ADSAC = 1	
Offset error		—	±1.25	±6.0	LSB	High-precision channel	
		—		±7.5	LSB	Other than specified	
Full-scale error		—	±1.25	±6.0	LSB	High-precision channel	
		—		±7.5	LSB	Other than specified	
Quantization error		—	±0.5	—	LSB	—	
Absolute accuracy		—	±3.25	±7.0	LSB	High-precision channel	
		—		±10.0	LSB	Other than specified	
DNL differential nonlinearity error		—	±1.5	—	LSB	—	
INL integral nonlinearity error		—	±1.75	±4.0	LSB	—	

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance (Cin), see [section 2.2.4. I/O V<sub>OH</sub>, V<sub>OL</sub>, and Other Characteristics](#).

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When VREFH0 < AVCC0, the MAX. values are as follows.

Absolute accuracy/Offset error/Full-scale error:

For voltage difference between AVCC0 and VREFH0, it should be added ±0.75 LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between AVCC0 and VREFH0, it should be added ±0.2 LSB/V to the Max spec.

**Table 2.39 A/D conversion characteristics (5) in low-power A/D conversion mode (1 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 2.4 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter		Min	Typ	Max	Unit	Test conditions
PCLKD (ADCLK) frequency		1	—	16	MHz	—
Analog input capacitance <sup>*2</sup>	Cs	—	—	9 <sup>*3</sup>	pF	High-precision channel
		—	—	10 <sup>*3</sup>	pF	Normal-precision channel
Analog input resistance	Rs	—	—	2.2 <sup>*3</sup>	kΩ	High-precision channel
		—	—	7 <sup>*3</sup>	kΩ	Normal-precision channel
Analog input voltage range	Ain	0	—	VREFH0	V	—
Resolution		—	—	12	Bit	—

**Table 2.39 A/D conversion characteristics (5) in low-power A/D conversion mode (2 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 2.4 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
Conversion time <sup>*1</sup> (Operation at PCLKD = 16 MHz)	2.38 (0.656) <sup>*4</sup>	—	—	μs	High-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1
	3.0 (1.281) <sup>*4</sup>	—	—	μs	Normal-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x14 ADACSR.ADSAC = 1
Offset error	—	±1.25	±6.0	LSB	High-precision channel
			±7.5	LSB	Other than specified
Full-scale error	—	±1.25	±6.0	LSB	High-precision channel
			±7.5	LSB	Other than specified
Quantization error	—	±0.5	—	LSB	—
Absolute accuracy	—	±3.25	±7.0	LSB	High-precision channel
			±10.0	LSB	Other than specified
DNL differential nonlinearity error	—	±1.5	—	LSB	—
INL integral nonlinearity error	—	±1.75	±4.0	LSB	—

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance (Cin), see [section 2.2.4. I/O V<sub>OH</sub>, V<sub>OL</sub>, and Other Characteristics](#).

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When VREFH0 < AVCC0, the MAX. values are as follows.

Absolute accuracy/Offset error/Full-scale error:

For voltage difference between AVCC0 and VREFH0, it should be added ±0.75 LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between AVCC0 and VREFH0, it should be added ±0.2 LSB/V to the Max spec.

**Table 2.40 A/D conversion characteristics (6) in low-power A/D conversion mode (1 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 1.8 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
PCLKD (ADCLK) frequency	1	—	8	MHz	—
Analog input capacitance <sup>*2</sup>	Cs	—	9 <sup>*3</sup>	pF	High-precision channel
		—	10 <sup>*3</sup>	pF	Normal-precision channel
Analog input resistance	Rs	—	6 <sup>*3</sup>	kΩ	High-precision channel
		—	14 <sup>*3</sup>	kΩ	Normal-precision channel
Analog input voltage range	Ain	0	VREFH0	V	—
Resolution	—	—	12	Bit	—
Conversion time <sup>*1</sup> (Operation at PCLKD = 8 MHz)	Permissible signal source impedance Max. = 5 kΩ	4.75 (1.313) <sup>*4</sup>	—	μs	High-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1
		6.0 (2.563) <sup>*4</sup>	—	μs	Normal-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x14 ADACSR.ADSAC = 1

**Table 2.40 A/D conversion characteristics (6) in low-power A/D conversion mode (2 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 1.8 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
Offset error	—	±1.25	±7.5	LSB	High-precision channel
			±10.0	LSB	Other than specified
Full-scale error	—	±1.5	±7.5	LSB	High-precision channel
			±10.0	LSB	Other than specified
Quantization error	—	±0.5	—	LSB	—
Absolute accuracy	—	±3.75	±9.5	LSB	High-precision channel
			±13.5	LSB	Other than specified
DNL differential nonlinearity error	—	±2.0	—	LSB	—
INL integral nonlinearity error	—	±2.25	±4.5	LSB	—

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance (Cin), see [section 2.2.4. I/O V<sub>OH</sub>, V<sub>OL</sub>, and Other Characteristics](#).

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When VREFH0 < AVCC0, the MAX. values are as follows.

Absolute accuracy/Offset error/Full-scale error:

For voltage difference between AVCC0 and VREFH0, it should be added ±0.75 LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between AVCC0 and VREFH0, it should be added ±0.2 LSB/V to the Max spec.

**Table 2.41 A/D conversion characteristics (7) in low-power A/D conversion mode (1 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 1.6 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
PCLKD (ADCLK) frequency	1	—	4	MHz	—
Analog input capacitance <sup>*2</sup>	Cs	—	9 <sup>*3</sup>	pF	High-precision channel
		—	10 <sup>*3</sup>	pF	Normal-precision channel
Analog input resistance	Rs	—	12 <sup>*3</sup>	kΩ	High-precision channel
		—	28 <sup>*3</sup>	kΩ	Normal-precision channel
Analog input voltage range	Ain	0	VREFH0	V	—
Resolution	—	—	12	Bit	—
Conversion time <sup>*1</sup> (Operation at PCLKD = 4 MHz) Max. = 9.9 kΩ	Permissible signal source impedance Max. = 9.9 kΩ	9.5 (2.625) <sup>*4</sup>	—	μs	High-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x0A ADACSR.ADSAC = 1
		12.0 (5.125) <sup>*4</sup>	—	μs	Normal-precision channel ADCSR.ADHSC = 1 ADSSTRn.SST[7:0] = 0x14 ADACSR.ADSAC = 1
Offset error	—	±1.25	±7.5	LSB	High-precision channel
			±10.0	LSB	Other than specified
Full-scale error	—	±1.5	±7.5	LSB	High-precision channel
			±10.0	LSB	Other than specified
Quantization error	—	±0.5	—	LSB	—

**Table 2.41 A/D conversion characteristics (7) in low-power A/D conversion mode (2 of 2)**Conditions: VCC = AVCC0 = VREFH0 = 1.6 to 5.5 V<sup>\*5</sup>, VSS = AVSS0 = VREFL0 = 0 V

Reference voltage range applied to the VREFH0 and VREFL0.

Parameter	Min	Typ	Max	Unit	Test conditions
Absolute accuracy	—	$\pm 3.75$	$\pm 9.5$	LSB	High-precision channel
			$\pm 13.5$	LSB	Other than specified
DNL differential nonlinearity error	—	$\pm 2.0$	—	LSB	—
INL integral nonlinearity error	—	$\pm 2.25$	$\pm 4.5$	LSB	—

Note: The characteristics apply when no pin functions other than 12-bit A/D converter input are used. Absolute accuracy does not include quantization errors. Offset error, full-scale error, DNL differential nonlinearity error, and INL integral nonlinearity error do not include quantization errors.

Note 1. The conversion time is the sum of the sampling time and the comparison time. The number of sampling states is indicated for the test conditions.

Note 2. Except for I/O input capacitance ( $C_{in}$ ), see [section 2.2.4. I/O  \$V\_{OH}\$ ,  \$V\_{OL}\$ , and Other Characteristics](#).

Note 3. Reference data.

Note 4. ( ) lists sampling time.

Note 5. When  $VREFH0 < AVCC0$ , the MAX. values are as follows.

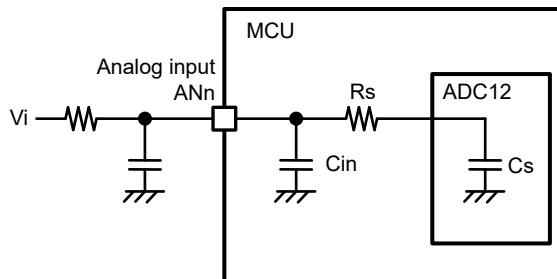
Absolute accuracy/Offset error/Full-scale error:

For voltage difference between  $AVCC0$  and  $VREFH0$ , it should be added  $\pm 0.75$  LSB/V to the Max spec.

INL integral non-linearity error:

For voltage difference between  $AVCC0$  and  $VREFH0$ , it should be added  $\pm 0.2$  LSB/V to the Max spec.

[Figure 2.49](#) shows the equivalent circuit for analog input.



Note: Terminal leakage current is not shown in this figure.

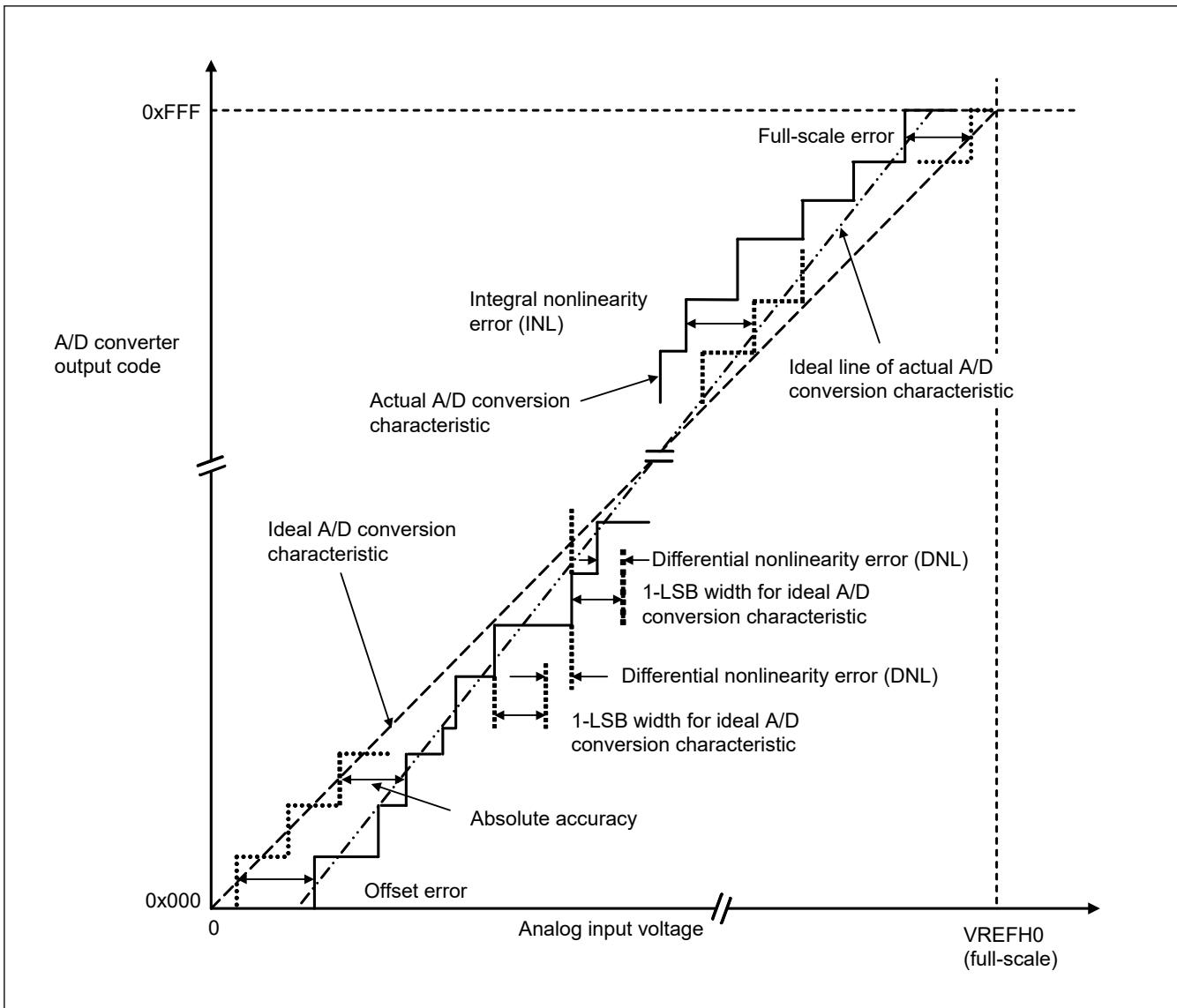
**Figure 2.49 Equivalent circuit for analog input****Table 2.42 12-bit A/D converter channel classification**

Classification	Channel	Conditions	Remarks
High-precision channel	AN000 to AN002, AN005 to AN010	$AVCC0 = 1.6$ to 5.5 V	Pins AN000 to AN002, AN005 to AN010 cannot be used as general I/O when the A/D converter is in use.
Normal-precision channel	AN019 to AN022		
Internal reference voltage input channel	Internal reference voltage	$AVCC0 = 1.8$ to 5.5 V	—
Temperature sensor input channel	Temperature sensor output	$AVCC0 = 1.8$ to 5.5 V	—

**Table 2.43 A/D internal reference voltage characteristics**Conditions: VCC = AVCC0 = VREFH0 = 1.8 to 5.5 V<sup>\*1</sup>

Parameter	Min	Typ	Max	Unit	Test conditions
Internal reference voltage input channel <sup>*2</sup>	1.42	1.48	1.54	V	—
PCLKD (ADCLK) frequency <sup>*3</sup>	1	—	2	MHz	—
Sampling time <sup>*4</sup>	5.0	—	—	μs	—

- Note 1. The internal reference voltage cannot be selected for input channels when AVCC0 < 1.8 V.  
 Note 2. The 12-bit A/D internal reference voltage indicates the voltage when the internal reference voltage is input to the 12-bit A/D converter.  
 Note 3. When the internal reference voltage is selected as the high-potential reference voltage.  
 Note 4. When the internal reference voltage is converted.



**Figure 2.50** Illustration of 12-bit A/D converter characteristic terms

### Absolute accuracy

Absolute accuracy is the difference between output code based on the theoretical A/D conversion characteristics, and the actual A/D conversion result. When measuring absolute accuracy, the voltage at the midpoint of the width of the analog input voltage (1-LSB width), which can meet the expectation of outputting an equal code based on the theoretical A/D conversion characteristics, is used as the analog input voltage. For example, if 12-bit resolution is used and the reference voltage  $VREFH0 = 3.072$  V, then 1-LSB width becomes 0.75 mV, and 0 mV, 0.75 mV, and 1.5 mV are used as the analog input voltages. If analog input voltage is 6 mV, an absolute accuracy of  $\pm 5$  LSB means that the actual A/D conversion result is in the range of 0x003 to 0x00D, though an output code of 0x008 can be expected from the theoretical A/D conversion characteristics.

### Integral nonlinearity error (INL)

Integral nonlinearity error is the maximum deviation between the ideal line when the measured offset and full-scale errors are zeroed, and the actual output code.

### Differential nonlinearity error (DNL)

Differential nonlinearity error is the difference between 1 LSB width based on the ideal A/D conversion characteristics and the width of the actual output code.

### Offset error

Offset error is the difference between the transition point of the ideal first output code and the actual first output code.

### Full-scale error

Full-scale error is the difference between the transition point of the ideal last output code and the actual last output code.

## 2.5 TSN Characteristics

**Table 2.44 TSN characteristics**

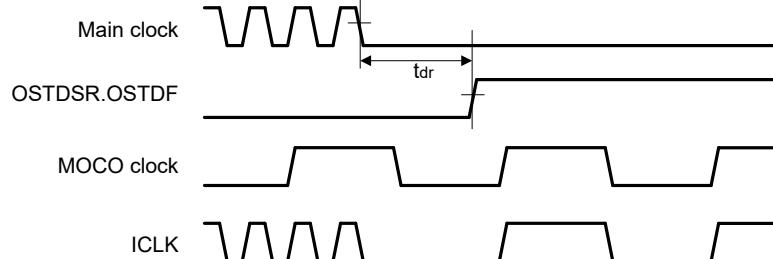
Conditions: VCC = AVCC0 = 1.8 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Relative accuracy	—	—	± 1.5	—	°C	2.4 V or above
		—	± 2.0	—	°C	Below 2.4 V
Temperature slope	—	—	-3.3	—	mV/°C	—
Output voltage (at 25°C)	—	—	1.05	—	V	VCC = 3.3 V
Temperature sensor start time	t <sub>START</sub>	—	—	5	μs	—
Sampling time	—	5	—	—	μs	—

## 2.6 OSC Stop Detect Characteristics

**Table 2.45 Oscillation stop detection circuit characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Detection time	t <sub>dr</sub>	—	—	1	ms	<a href="#">Figure 2.51</a>



**Figure 2.51 Oscillation stop detection timing**

## 2.7 POR and LVD Characteristics

**Table 2.46 Power-on reset circuit and voltage detection circuit characteristics (1) (1 of 2)**

Parameter			Symbol	Min	Typ	Max	Unit	Test Conditions
Voltage detection level <sup>*1</sup>	Power-on reset (POR)	When power supply rise	V <sub>POR</sub>	1.47	1.51	1.55	V	<a href="#">Figure 2.52</a>
		When power supply fall	V <sub>PDR</sub>	1.46	1.50	1.54		
	Voltage detection circuit (LVD0) <sup>*2</sup>	When power supply rise	V <sub>det0_0</sub>	3.74	3.91	4.06		<a href="#">Figure 2.54</a> At falling edge VCC
		When power supply fall		3.68	3.85	4.00		
		When power supply rise	V <sub>det0_1</sub>	2.73	2.9	3.01		
		When power supply fall		2.68	2.85	2.96		
		When power supply rise	V <sub>det0_2</sub>	2.44	2.59	2.70		
		When power supply fall		2.38	2.53	2.64		
		When power supply rise	V <sub>det0_3</sub>	1.83	1.95	2.07		
		When power supply fall		1.78	1.90	2.02		
		When power supply rise	V <sub>det0_4</sub>	1.66	1.75	1.88		
		When power supply fall		1.60	1.69	1.82		
Voltage detection level <sup>*1</sup>	Voltage detection circuit (LVD1) <sup>*3</sup>	When power supply rise	V <sub>det1_0</sub>	4.23	4.39	4.55	V	<a href="#">Figure 2.55</a> At falling edge VCC
		When power supply fall		4.13	4.29	4.45		
		When power supply rise	V <sub>det1_1</sub>	4.07	4.25	4.39		
		When power supply fall		3.98	4.16	4.30		
		When power supply rise	V <sub>det1_2</sub>	3.97	4.14	4.29		
		When power supply fall		3.86	4.03	4.18		
		When power supply rise	V <sub>det1_3</sub>	3.74	3.92	4.06		
		When power supply fall		3.68	3.86	4.00		
		When power supply rise	V <sub>det1_4</sub>	3.05	3.17	3.29		
		When power supply fall		2.98	3.10	3.22		
		When power supply rise	V <sub>det1_5</sub>	2.95	3.06	3.17		
		When power supply fall		2.89	3.00	3.11		
		When power supply rise	V <sub>det1_6</sub>	2.86	2.97	3.08		
		When power supply fall		2.79	2.90	3.01		
		When power supply rise	V <sub>det1_7</sub>	2.74	2.85	2.96		
		When power supply fall		2.68	2.79	2.90		

**Table 2.46 Power-on reset circuit and voltage detection circuit characteristics (1) (2 of 2)**

Parameter		Symbol	Min	Typ	Max	Unit	Test Conditions
Voltage detection level <sup>*1</sup>	Voltage detection circuit (LVD1) <sup>*3</sup>	When power supply rise	V <sub>det1_8</sub>	2.63	2.75	2.85	V <a href="#">Figure 2.55</a> At falling edge VCC
		When power supply fall		2.58	2.68	2.78	
		When power supply rise	V <sub>det1_9</sub>	2.54	2.64	2.75	
		When power supply fall		2.48	2.58	2.68	
		When power supply rise	V <sub>det1_A</sub>	2.43	2.53	2.63	
		When power supply fall		2.38	2.48	2.58	
		When power supply rise	V <sub>det1_B</sub>	2.16	2.26	2.36	
		When power supply fall		2.10	2.20	2.30	
		When power supply rise	V <sub>det1_C</sub>	1.88	2	2.09	
		When power supply fall		1.84	1.96	2.05	
		When power supply rise	V <sub>det1_D</sub>	1.78	1.9	1.99	
		When power supply fall		1.74	1.86	1.95	
		When power supply rise	V <sub>det1_E</sub>	1.67	1.79	1.88	
		When power supply fall		1.63	1.75	1.84	
		When power supply rise	V <sub>det1_F</sub>	1.65	1.7	1.78	
		When power supply fall		1.60	1.65	1.73	
Voltage detection level <sup>*1</sup>	Voltage detection circuit (LVD2) <sup>*4</sup>	When power supply rise	V <sub>det2_0</sub>	4.20	4.40	4.57	V <a href="#">Figure 2.56</a> At falling edge VCC
		When power supply fall		4.11	4.31	4.48	
		When power supply rise	V <sub>det2_1</sub>	4.05	4.25	4.42	
		When power supply fall		3.97	4.17	4.34	
		When power supply rise	V <sub>det2_2</sub>	3.91	4.11	4.28	
		When power supply fall		3.83	4.03	4.20	
		When power supply rise	V <sub>det2_3</sub>	3.71	3.91	4.08	
		When power supply fall		3.64	3.84	4.01	

Note 1. These characteristics apply when noise is not superimposed on the power supply. When a setting causes this voltage detection level to overlap with that of the voltage detection circuit, it cannot be specified whether LVD1 or LVD2 is used for voltage detection.

Note 2. # in the symbol V<sub>det0\_#</sub> denotes the value of the OFS1.VDSEL0[2:0] bits.

Note 3. # in the symbol V<sub>det1\_#</sub> denotes the value of the LVDLVL.R.LVD1LVL[4:0] bits.

Note 4. # in the symbol V<sub>det2\_#</sub> denotes the value of the LVDLVL.R.LVD2LVL[2:0] bits.

**Table 2.47 Power-on reset circuit and voltage detection circuit characteristics (2) (1 of 2)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Wait time after power-on reset cancellation	LVD0: enable	t <sub>POR</sub>	—	4.3	—	ms
	LVD0: disable	t <sub>POR</sub>	—	3.7	—	ms
Wait time after voltage monitor 0, 1, 2 reset cancellation	LVD0: enable <sup>*1</sup>	t <sub>LVD0,1,2</sub>	—	1.4	—	ms
	LVD0: disable <sup>*2</sup>	t <sub>LVD1,2</sub>	—	0.7	—	ms
Power-on reset response delay time <sup>*3</sup>	t <sub>det</sub>	—	—	500	μs	<a href="#">Figure 2.52</a> , <a href="#">Figure 2.53</a>
LVD0 response delay time <sup>*3</sup>	t <sub>det</sub>	—	—	500	μs	<a href="#">Figure 2.54</a>
LVD1 response delay time <sup>*3</sup>	t <sub>det</sub>	—	—	350	μs	<a href="#">Figure 2.55</a>
LVD2 response delay time <sup>*3</sup>	t <sub>det</sub>	—	—	600	μs	<a href="#">Figure 2.56</a>
Minimum VCC down time	t <sub>VOFF</sub>	500	—	—	μs	<a href="#">Figure 2.52</a> , VCC = 1.0 V or above
Power-on reset enable time	t <sub>W (POR)</sub>	1	—	—	ms	<a href="#">Figure 2.53</a> , VCC = below 1.0 V

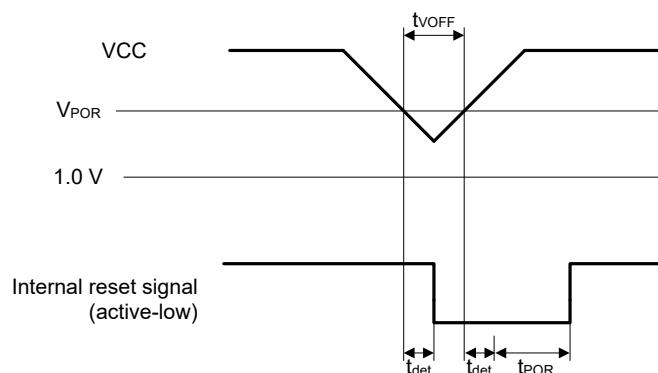
**Table 2.47 Power-on reset circuit and voltage detection circuit characteristics (2) (2 of 2)**

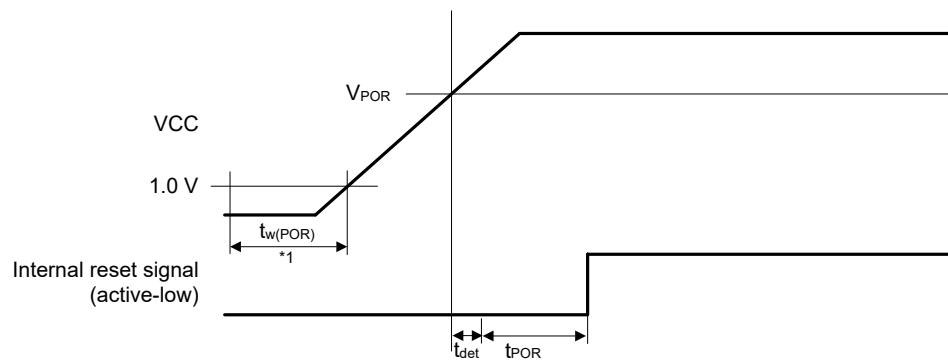
Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
LVD1 operation stabilization time (after LVD1 is enabled)	$T_d$ (E-A)	—	—	300	μs	<a href="#">Figure 2.55</a>
LVD2 operation stabilization time (after LVD2 is enabled)	$T_d$ (E-A)	—	—	1200	μs	<a href="#">Figure 2.56</a>
Hysteresis width (POR)	$V_{PORH}$	—	10	—	mV	—
Hysteresis width (LVD0, LVD1 and LVD2)	$V_{LVH}$	—	60	—	mV	LVD0 selected
		—	110	—		$V_{det1\_0}$ to $V_{det1\_2}$ selected
		—	70	—		$V_{det1\_3}$ to $V_{det1\_9}$ selected
		—	60	—		$V_{det1\_A}$ to $V_{det1\_B}$ selected
		—	50	—		$V_{det1\_C}$ to $V_{det1\_F}$ selected
		—	90	—		LVD2 selected

Note 1. When OFS1.LVDAS = 0.

Note 2. When OFS1.LVDAS = 1.

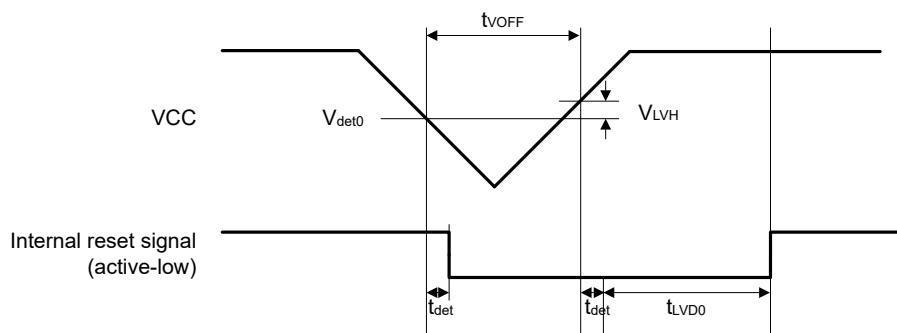
Note 3. The minimum VCC down time indicates the time when VCC is below the minimum value of voltage detection levels  $V_{POR}$ ,  $V_{det0}$ ,  $V_{det1}$ , and  $V_{det2}$  for the POR/LVD.

**Figure 2.52 Voltage detection reset timing**

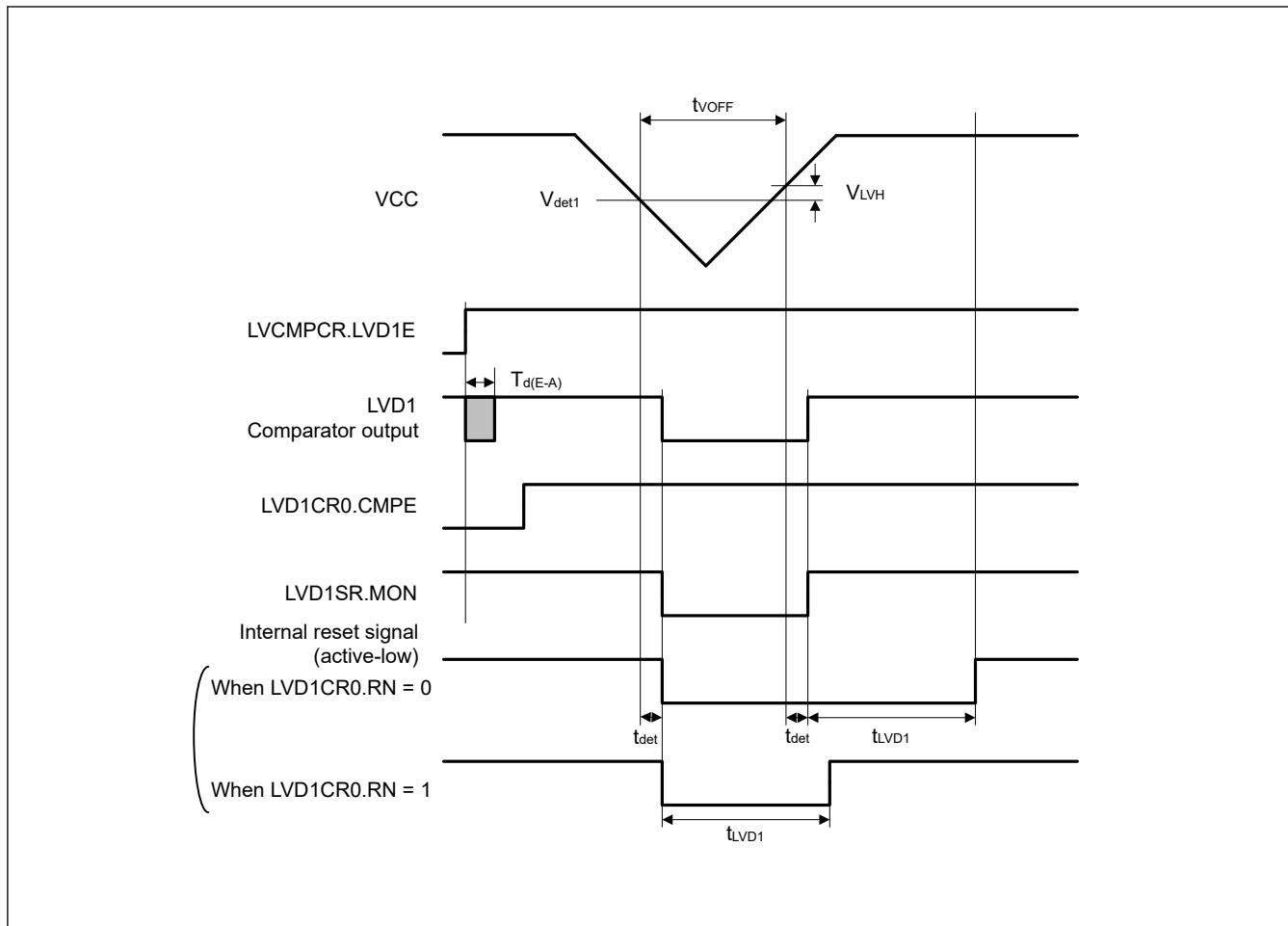


Note 1.  $t_{w(POR)}$  is the time required for a power-on reset to be enabled while the external power  $V_{CC}$  is being held below the valid voltage (1.0 V).  
When  $V_{CC}$  turns on, maintain  $t_{w(POR)}$  for 1.0 ms or more.

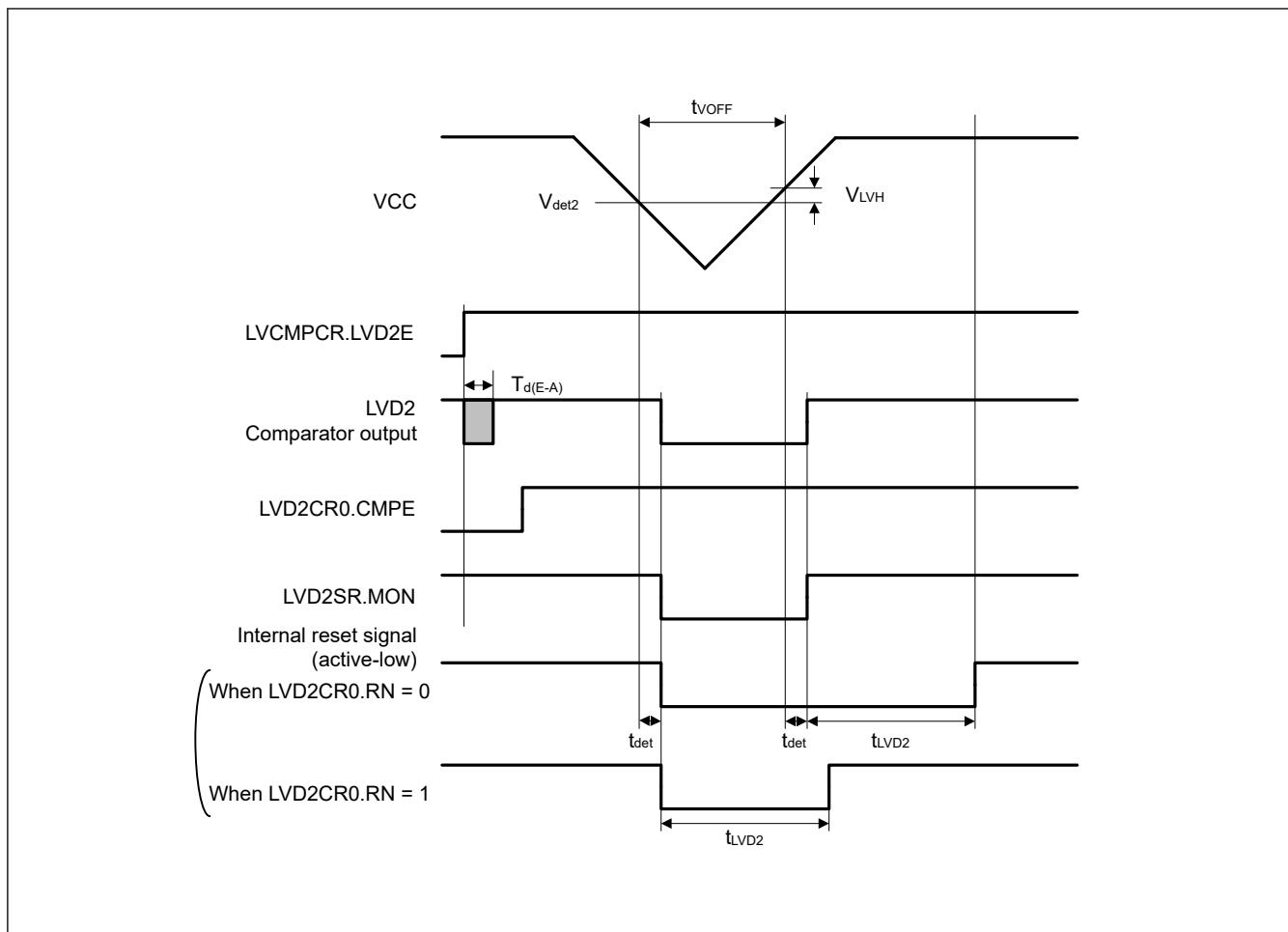
**Figure 2.53 Power-on reset timing**



**Figure 2.54 Voltage detection circuit timing ( $V_{det0}$ )**



**Figure 2.55** Voltage detection circuit timing ( $V_{det1}$ )

Figure 2.56 Voltage detection circuit timing ( $V_{det2}$ )

## 2.8 Comparator Characteristics

Table 2.48 ACMPHS characteristics

Conditions: VCC = AVCC0 = 2.7 to 5.5 V, VSS = AVSS0 = 0 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Reference voltage range	VREF	0		VCC	V	—
Input voltage range	VI	0		VCC	V	—
Internal reference voltage	—	1.34	1.44	1.54	V	—
Output delay time <sup>*1</sup>	Td		50	100	ns	VI = VREF ± 100 mV
Offset voltage	—		±5	±40	mV	—
Operation stabilization wait time	Tcmp	1			μs	—
Input channel switch stabilization wait time <sup>*2</sup>	—	0.3	—	—	μs	—

Note 1. This value is the internal propagation delay.

Note 2. The time from the operation permission signal switching of the comparator (CMPnEN = 0 to 1) until the comparator is satisfied with the DC / AC characteristics.

## 2.9 Flash Memory Characteristics

### 2.9.1 Code Flash Memory Characteristics

**Table 2.49 Code flash characteristics (1)**

Parameter		Symbol	Min	Typ	Max	Unit	Conditions
Reprogramming/erasure cycle <sup>*1</sup>		NPEC	10000	—	—	Times	—
Data hold time	After 1000 times NPEC	t <sub>DRP</sub>	20 <sup>*2</sup>	—	—	Year	T <sub>a</sub> = +105°C
	After 10000 times NPEC		10 <sup>*2</sup>	—	—	Year	T <sub>a</sub> = +125°C

Note 1. The reprogram/erase cycle is the number of erasures for each block. When the reprogram/erase cycle is n times (n = 10,000), erasing can be performed n times for each block. For instance, when 4-byte programming is performed 512 times for different addresses in 2-KB blocks, and then the entire block is erased, the reprogram/erase cycle is counted as one. However, programming the same address for several times as one erasure is not enabled (overwriting is prohibited).

Note 2. This result is obtained from reliability testing.

**Table 2.50 Code flash characteristics (2)**

High-speed operating mode

Conditions: VCC = AVCC0 = 1.8 to 5.5 V

Parameter		Symbol	ICLK = 1 MHz			ICLK = 64 MHz			Unit
			Min	Typ	Max	Min	Typ	Max	
Programming time	4-byte	t <sub>P4</sub>	—	86	732	—	34	321	μs
Erasure time	2-KB	t <sub>E2K</sub>	—	12.5	355	—	5.6	215	ms
Blank check time	4-byte	t <sub>BC4</sub>	—	—	46.5	—	—	8.3	μs
	2-KB	t <sub>BC2K</sub>	—	—	3681	—	—	231	μs
Erase suspended time		t <sub>SED</sub>	—	—	22.3	—	—	10.5	μs
Access window information program Start-up area selection and security setting time		t <sub>AWSSAS</sub>	—	21.2	570	—	11.4	423	ms
OCD/serial programmer ID setting time <sup>*1</sup>		t <sub>OSIS</sub>	—	84.7	2280	—	45.3	1690	ms
Flash memory mode transition wait time 1		t <sub>DIS</sub>	2	—	—	2	—	—	μs
Flash memory mode transition wait time 2		t <sub>MS</sub>	15	—	—	15	—	—	μs

Note: Does not include the time until each operation of the flash memory is started after instructions are executed by software.

Note: The lower-limit frequency of ICLK is 1 MHz during programming or erasing the flash memory. When using ICLK at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note: The frequency accuracy of ICLK must be ± 1.0% during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 1. Total time of four commands.

**Table 2.51 Code flash characteristics (3) (1 of 2)**

Middle-speed operating mode

Conditions: VCC = AVCC0 = 1.8 to 5.5 V

Parameter		Symbol	ICLK = 1 MHz			ICLK = 24 MHz <sup>*2</sup>			Unit
			Min	Typ	Max	Min	Typ	Max	
Programming time	4-byte	t <sub>P4</sub>	—	86	732	—	39	356	μs
Erasure time	2-KB	t <sub>E2K</sub>	—	12.5	355	—	6.2	227	ms
Blank check time	4-byte	t <sub>BC4</sub>	—	—	46.5	—	—	11.3	μs
	2-KB	t <sub>BC2K</sub>	—	—	3681	—	—	534	μs
Erase suspended time		t <sub>SED</sub>	—	—	22.3	—	—	11.7	μs
Access window information program Start-up area selection and security setting time		t <sub>AWSSAS</sub>	—	21.2	570	—	12.2	435	ms

**Table 2.51 Code flash characteristics (3) (2 of 2)**

Middle-speed operating mode

Conditions: VCC = AVCC0 = 1.8 to 5.5 V

Parameter	Symbol	ICLK = 1 MHz			ICLK = 24 MHz <sup>*2</sup>			Unit
		Min	Typ	Max	Min	Typ	Max	
OCD/serial programmer ID setting time <sup>*1</sup>	t <sub>OSIS</sub>	—	84.7	2280	—	48.7	1740	ms
Flash memory mode transition wait time 1	t <sub>DIS</sub>	2	—	—	2	—	—	μs
Flash memory mode transition wait time 2	t <sub>MS</sub>	15	—	—	15	—	—	μs

Note: Does not include the time until each operation of the flash memory is started after instructions are executed by software.

Note: The lower-limit frequency of ICLK is 1 MHz during programming or erasing the flash memory. When using ICLK at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note: The frequency accuracy of ICLK must be ± 1.0% during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 1. Total time of four commands.

Note 2. When 1.8 V ≤ VCC = AVCC0 ≤ 5.5 V

**Table 2.52 Code flash characteristics (4)**

Low-speed operating mode

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	ICLK = 1 MHz			ICLK = 2 MHz			Unit
		Min	Typ	Max	Min	Typ	Max	
Programming time	t <sub>P4</sub>	—	86	732	—	57	502	μs
Erasure time	t <sub>E2K</sub>	—	12.5	355	—	8.8	280	ms
Blank check time	4-byte	t <sub>BC4</sub>	—	—	46.5	—	23.3	μs
	2-KB	t <sub>BC2K</sub>	—	—	3681	—	1841	μs
Erase suspended time	t <sub>SED</sub>	—	—	22.3	—	—	16.2	μs
Access window information program Start-up area selection and security setting time	t <sub>AWSSAS</sub>	—	21.2	570	—	15.9	491	ms
OCD/serial programmer ID setting time <sup>*1</sup>	t <sub>OSIS</sub>	—	84.7	2280	—	63.5	1964	ms
Flash memory mode transition wait time 1	t <sub>DIS</sub>	2	—	—	2	—	—	μs
Flash memory mode transition wait time 2	t <sub>MS</sub>	15	—	—	15	—	—	μs

Note: Does not include the time until each operation of the flash memory is started after instructions are executed by software.

Note: The lower-limit frequency of ICLK is 1 MHz during programming or erasing the flash memory. When using ICLK at below 4 MHz, the frequency can be set to 1 MHz or 2 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note: The frequency accuracy of ICLK must be ± 1.0% during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 1. Total time of four commands.

## 2.9.2 Data Flash Memory Characteristics

**Table 2.53 Data flash characteristics (1) (1 of 2)**

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Reprogramming/erasure cycle <sup>*1</sup>	N <sub>DPEC</sub>	100000	1000000	—	Times	—

**Table 2.53 Data flash characteristics (1) (2 of 2)**

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Data hold time	$t_{DDRP}$	20 *2	—	—	Year	T <sub>a</sub> = +105°C
		10	—	—	Year	T <sub>a</sub> = +125°C
		5 *2	—	—	Year	T <sub>a</sub> = +105°C
		—	1 *2	—	Year	T <sub>a</sub> = +25°C

Note 1. The reprogram/erase cycle is the number of erasure for each block. When the reprogram/erase cycle is n times (n = 100,000), erasing can be performed n times for each block. For instance, when 1-byte programming is performed 1,024 times for different addresses in 1-KB blocks, and then the entire block is erased, the reprogram/erase cycle is counted as one. However, programming the same address for several times as one erasure is not enabled. (overwriting is prohibited.)

Note 2. This result is obtained from reliability testing.

**Table 2.54 Data flash characteristics (2)**

High-speed operating mode

Conditions: V<sub>CC</sub> = AV<sub>CC0</sub> = 1.8 to 5.5 V

Parameter	Symbol	ICLK = 1 MHz			ICLK = 64 MHz			Unit
		Min	Typ	Max	Min	Typ	Max	
Programming time	$t_{DP1}$	—	45	404	—	34	321	μs
Erasure time	1-KB	$t_{DE1K}$	—	8.8	280	—	6.1	224
Blank check time	1-byte	$t_{DBC1}$	—	—	15.2	—	—	8.3
	1-KB	$t_{DBC1K}$	—	—	1832	—	—	444
Suspended time during erasing	$t_{DSED}$	—	—	13.2	—	—	10.5	μs
Data flash STOP recovery time	$t_{DSTOP}$	250	—	—	250	—	—	ns

Note: Does not include the time until each operation of the flash memory is started after instructions are executed by software.

Note: The lower-limit frequency of ICLK is 1 MHz during programming or erasing the flash memory. When using ICLK at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note: The frequency accuracy of ICLK must be ± 1.0% during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

**Table 2.55 Data flash characteristics (3)**

Middle-speed operating mode

Conditions: V<sub>CC</sub> = AV<sub>CC0</sub> = 1.8 to 5.5 V

Parameter	Symbol	ICLK = 1 MHz			ICLK = 24 MHz*1			Unit
		Min	Typ	Max	Min	Typ	Max	
Programming time	1-byte	$t_{DP1}$	—	45	404	—	39	356
Erasure time	1-KB	$t_{DE1K}$	—	8.8	280	—	7.3	248
Blank check time	1-byte	$t_{DBC1}$	—	—	15.2	—	—	11.3
	1-KB	$t_{DBC1K}$	—	—	1.84	—	—	1.06
Suspended time during erasing	$t_{DSED}$	—	—	13.2	—	—	11.7	μs
Data flash STOP recovery time	$t_{DSTOP}$	250	—	—	250	—	—	ns

Note: Does not include the time until each operation of the flash memory is started after instructions are executed by software.

Note: The lower-limit frequency of ICLK is 1 MHz during programming or erasing the flash memory. When using ICLK at below 4 MHz, the frequency can be set to 1 MHz, 2 MHz, or 3 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note: The frequency accuracy of ICLK must be ± 1.0% during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

Note 1. When 1.8 V ≤ V<sub>CC</sub> = AV<sub>CC0</sub> ≤ 5.5 V

**Table 2.56 Data flash characteristics (4)**

Low-speed operating mode

Conditions: VCC = AVCC0 = 1.6 to 5.5 V

Parameter	Symbol	ICLK = 1 MHz			ICLK = 2 MHz			Unit
		Min	Typ	Max	Min	Typ	Max	
Programming time	t <sub>DP1</sub>	—	86	732	—	57	502	μs
Erasure time	t <sub>DE1K</sub>	—	19.7	504	—	12.4	354	ms
Blank check time	1-byte	t <sub>DBC1</sub>	—	—	46.5	—	23.3	μs
	1-KB	t <sub>DBC1K</sub>	—	—	7.3	—	3.66	ms
Suspended time during erasing	t <sub>DSED</sub>	—	—	22.3	—	—	16.2	μs
Data flash STOP recovery time	t <sub>DSTOP</sub>	250	—	—	250	—	—	ns

Note: Does not include the time until each operation of the flash memory is started after instructions are executed by software.

Note: The lower-limit frequency of ICLK is 1 MHz during programming or erasing the flash memory. When using ICLK at below 2 MHz, the frequency can be set to 1 MHz or 2 MHz. A non-integer frequency such as 1.5 MHz cannot be set.

Note: The frequency accuracy of ICLK must be ± 1.0% during programming or erasing the flash memory. Confirm the frequency accuracy of the clock source.

## 2.10 Serial Wire Debug (SWD)

**Table 2.57 SWD characteristics (1)**

Conditions: VCC = AVCC0 = 2.4 to 5.5 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
SWCLK clock cycle time	t <sub>SWCKcyc</sub>	80	—	—	ns	Figure 2.57
SWCLK clock high pulse width	t <sub>SWCKH</sub>	35	—	—	ns	
SWCLK clock low pulse width	t <sub>SWCKL</sub>	35	—	—	ns	
SWCLK clock rise time	t <sub>SWCKr</sub>	—	—	5	ns	
SWCLK clock fall time	t <sub>SWCKf</sub>	—	—	5	ns	
SWDIO setup time	t <sub>SWDS</sub>	16	—	—	ns	Figure 2.58
SWDIO hold time	t <sub>SWDH</sub>	16	—	—	ns	
SWDIO data delay time	t <sub>SWDD</sub>	2	—	70	ns	

**Table 2.58 SWD characteristics (2)**

Conditions: VCC = AVCC0 = 1.6 to 2.4 V

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
SWCLK clock cycle time	t <sub>SWCKcyc</sub>	250	—	—	ns	Figure 2.57
SWCLK clock high pulse width	t <sub>SWCKH</sub>	120	—	—	ns	
SWCLK clock low pulse width	t <sub>SWCKL</sub>	120	—	—	ns	
SWCLK clock rise time	t <sub>SWCKr</sub>	—	—	5	ns	
SWCLK clock fall time	t <sub>SWCKf</sub>	—	—	5	ns	
SWDIO setup time	t <sub>SWDS</sub>	50	—	—	ns	Figure 2.58
SWDIO hold time	t <sub>SWDH</sub>	50	—	—	ns	
SWDIO data delay time	t <sub>SWDD</sub>	2	—	170	ns	

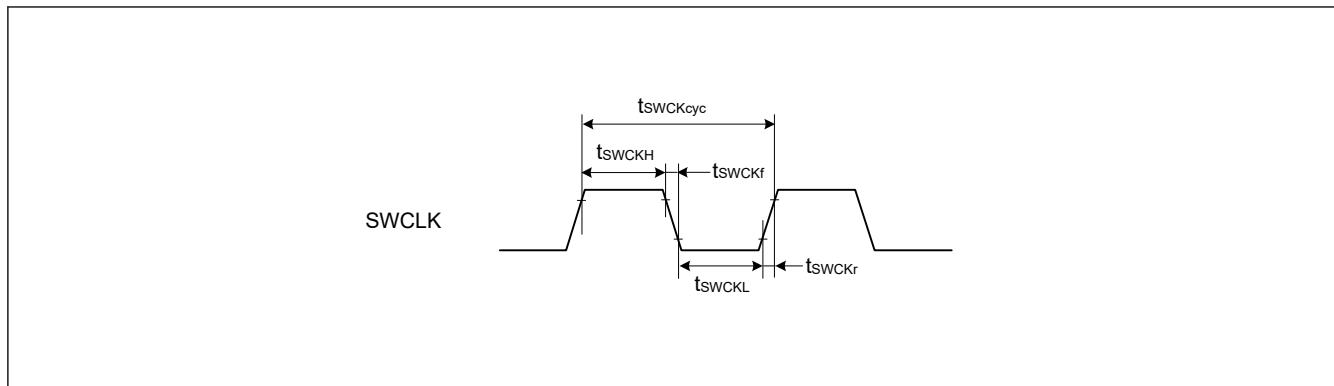


Figure 2.57 SWD SWCLK timing

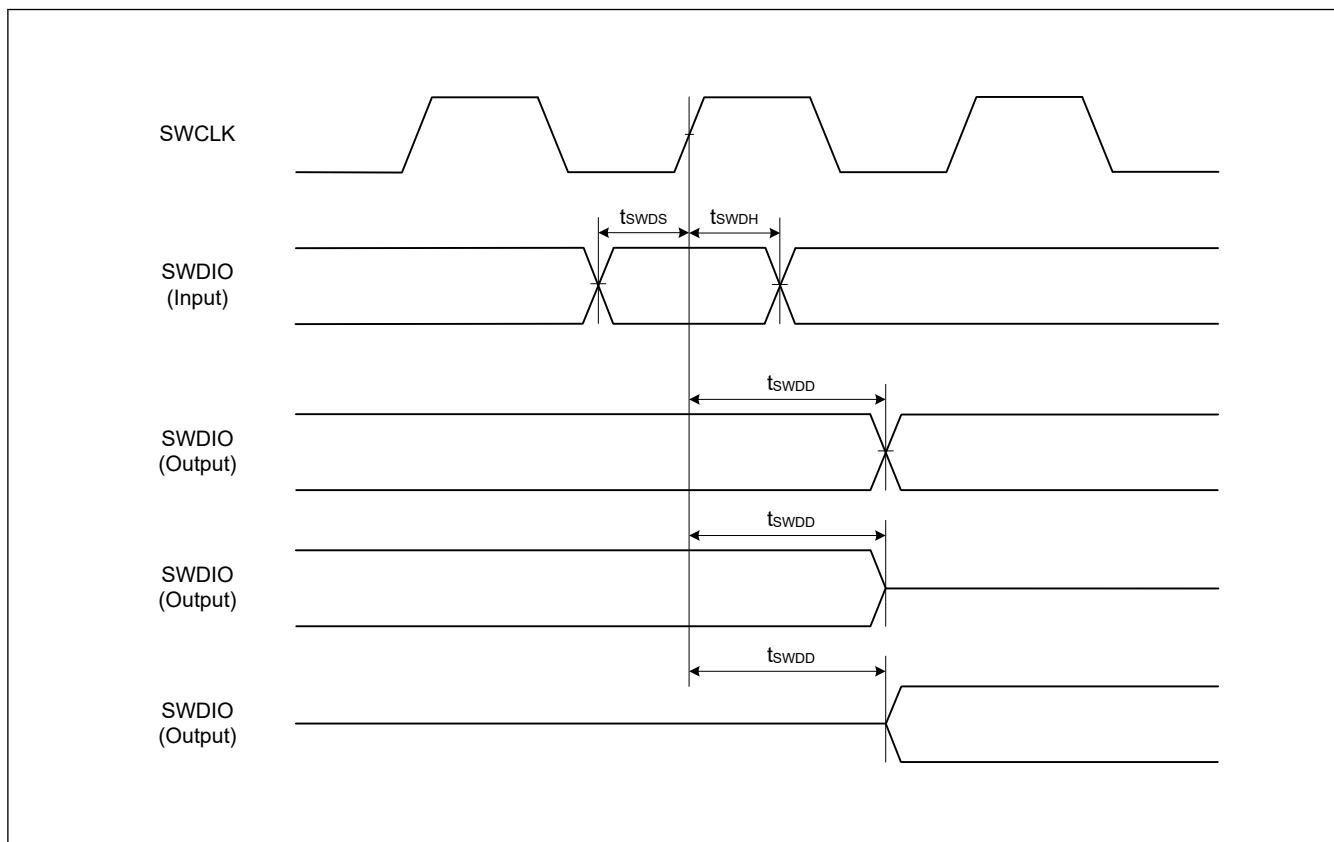


Figure 2.58 SWD input/output timing

## Appendix 1. Port States in each Processing Mode

**Table A1.1 Port states in each processing mode (1 of 2)**

Port name	Reset	Software Standby Mode
P000/AN008	Hi-Z	Keep-O
P001/AN009/IRQ7_A	Hi-Z	Keep-O <sup>*1</sup>
P002/AN010	Hi-Z	Keep-O
P010/AN005	Hi-Z	Keep-O
P011/AN006	Hi-Z	Keep-O
P012/AN007	Hi-Z	Keep-O
P013/AN000/CMPIN03/GTIW_A/IRQ1_C	Hi-Z	Keep-O <sup>*1</sup>
P014/AN001/CMPIN02/GTIV_A/IRQ3_B	Hi-Z	Keep-O <sup>*1</sup>
P015/AN002/CMPIN01/GTIU_A/IRQ2_C	Hi-Z	Keep-O <sup>*1</sup>
P100/AGTIO0_A/GTOVLO_B/GTIOC1B_B/ RXD0_A/MISO0_A/SCL0_A/SCL0_D/ SCK1_A/MISOA_A/KRM00/AN022/IRQ0_C	Hi-Z	[AGTIO0_A output selected] AGTIO0_A output <sup>*2</sup> [Other than the above] Keep-O <sup>*1</sup>
P101/AGTEE0/GTOVUP_B/GTIOC1A_B/ TXD0_A/MOSI0_A/SDA0_A/MOSIA_A/ SDA0_C/CTS1_RTS1_A/KRM01/AN021/ IRQ2_A	Hi-Z	Keep-O <sup>*1</sup>
P102/ADTRG0_A/AGTO0/GTOWLO_B/ GTIOC2B_A/AN020/CMPREF0/IRQ1_A/ SCK0_ATXD2_D/MOSI2_D/SDA2_D/ RSPCKA_A/KRM02	Hi-Z	[AGTO0 selected] AGTO0 output <sup>*2</sup> [Other than the above] Keep-O <sup>*1</sup>
P103/GTOWUP_B/GTIOC2A_A/RXD2_D/ MISO2_D/SCL2_DAN019/CMPIN1/IRQ4_B/ GTCPP03/CTS0_RTS0_A/SSLA0_A/ KRM03	Hi-Z	Keep-O <sup>*1</sup>
P104/GTETRGB_B/RXD0_C/MISO0_C/ SCL0_C/SSLA1_A/KRM04/IRQ1_B	Hi-Z	Keep-O <sup>*1</sup>
P108/SWDIO/AGTEE1_B/GTETRGB_C/ GTIOC3B_A/RXD1/MISO1/SCL1/IRQ6_C/ GTCPP02/CTS9_RTS9_B	Pull-up	Keep-O <sup>*1</sup>
P109/AGTOA1_B/GTOWUP_A/ GTIOC2A_B/SCK1_E/TXD9_B/MOSI9_B/ SDA9_B/CLKOUT_B	Hi-Z	[AGTOA1_B selected] AGTOA1_B output <sup>*2</sup> [CLKOUT selected] CLKOUT output [Other than the above] Keep-O
P110/AGTIO1_A/GTOWLO_A/GTIOC2B_B/ VCOUT/CTS2_RTS2_B/RXD9_B/SCL9_B/ MISO9_B/IRQ3_A	Hi-Z	[AGTIO1 selected] AGTIO1 output <sup>*2</sup> [ACMPHS selected] VCOUT output [Other than the above] Keep-O <sup>*1</sup>
P111/AGTOA0/GTIOC1A_C/SCK2_B/ SCK9_B/IRQ4_A	Hi-Z	[AGTOA0 selected] AGTOA0 output <sup>*2</sup> [Other than the above] Keep-O <sup>*1</sup>
P112/AGTOB0/GTIOC1B_C/SCK1_D	Hi-Z	[AGTOB0 selected] AGTOB0 output <sup>*2</sup> [Other than the above] Keep-O
P200/NMI	Hi-Z	Hi-Z

**Table A1.1 Port states in each processing mode (2 of 2)**

Port name	Reset	Software Standby Mode
P201/M0	Pull-up	Keep-O
P206/GTIU_B/TXD0_C/MOSI0_C/SDA0_C/IRQ0_B	Hi-Z	Keep-O <sup>*1</sup>
P207	Hi-Z	Keep-O
P208/AGTOB0_A/GTOUUP_B/GTIOC0A_B	Hi-Z	[AGTOB0_A selected] AGTOB0_A output <sup>*2</sup> [Other than the above] Keep-O
P212/EXTAL/AGTEE1_A/GTOULO_A/GTIOC0B_A/IRQ7_C	Hi-Z	Keep-O <sup>*1</sup>
P213/XTAL/GTOUUP_A/GTIOC0A_A/IRQ2_B	Hi-Z	Keep-O <sup>*1</sup>
P300/SWCLK/GTETRGA_C/GTIOC3A_A/TXD1/MOSI1/SDA1/IRQ5_B/GTCPP01	Pull-up	Keep-O <sup>*1</sup>
P301/AGTIO0_D/GTETRGB_A/RXD2_A/MISO2_A/SCL2_A/CTS9_RTSA_D/IRQ6_A	Hi-Z	[AGTIO0_D output selected] AGTIO0_D output <sup>*2</sup> [Other than the above] Keep-O <sup>*1</sup>
P302/GTETRGA_D/TXD2_A/MOSI2_A/SDA2_A/IRQ5_A	Hi-Z	Keep-O <sup>*1</sup>
P400/CACREF_C/AGTIO1_C/GTIOC3A_B/SCK0_B/SCK1_B/SCL0_A/IRQ0_A	Hi-Z	[AGTIO1_C output selected] AGTIO1_C output <sup>*2</sup> [Other than the above] Keep-O <sup>*1</sup>
P401/GTETRGA_B/GTIOC3B_B/CTS0_RTSA_B/SDA0_A/IRQ5_C	Hi-Z	Keep-O <sup>*1</sup>
P402/GTADSM0	Hi-Z	Keep-O
P403/GTADSM1	Hi-Z	Keep-O
P407/ADTRG0_B/AGTIO0_C/CMPREF1/GTOULO_B/GTIOC0B_B/GTCPP00/CTS0_RTSD0_D/SDA0_B	Hi-Z	[AGTIO0_C output selected] AGTIO0_C output <sup>*2</sup> [Other than the above] Keep-O <sup>*1</sup>
P408/GTIW_B/CTS1_RTSD1_D/SCL0_C/IRQ7_B	Hi-Z	Keep-O <sup>*1</sup>
P409/GTIV_B/IRQ6_B	Hi-Z	Keep-O <sup>*1</sup>
P500/GTETRGA_A/GTIOC2A_C	Hi-Z	Keep-O
P913/AGTIO1_F/GTOVLO_A/GTIOC1B_A	Hi-Z	[AGTIO1_F output selected] AGTIO1_F output <sup>*2</sup> [Other than the above] Keep-O
P914/AGTOA1_A/GTOVUP_A/GTIOC1A_A	Hi-Z	[AGTOA1_A output selected] AGTOA1_A output <sup>*2</sup> [Other than the above] Keep-O
P915	Hi-Z	Keep-O

Note: Hi-Z: High-impedance

Keep-O: Output pins retain their previous values. Input pins become high-impedance.

Note 1. Input is enabled if the pin is specified as the software standby canceling source while it is used as an external interrupt pin.

Note 2. AGTIO output is enabled while LOCO is selected as a count source.

## Appendix 2. Package Dimensions

Information on the latest version of the package dimensions or mountings is displayed in “Packages” on the Renesas Electronics Corporation website.

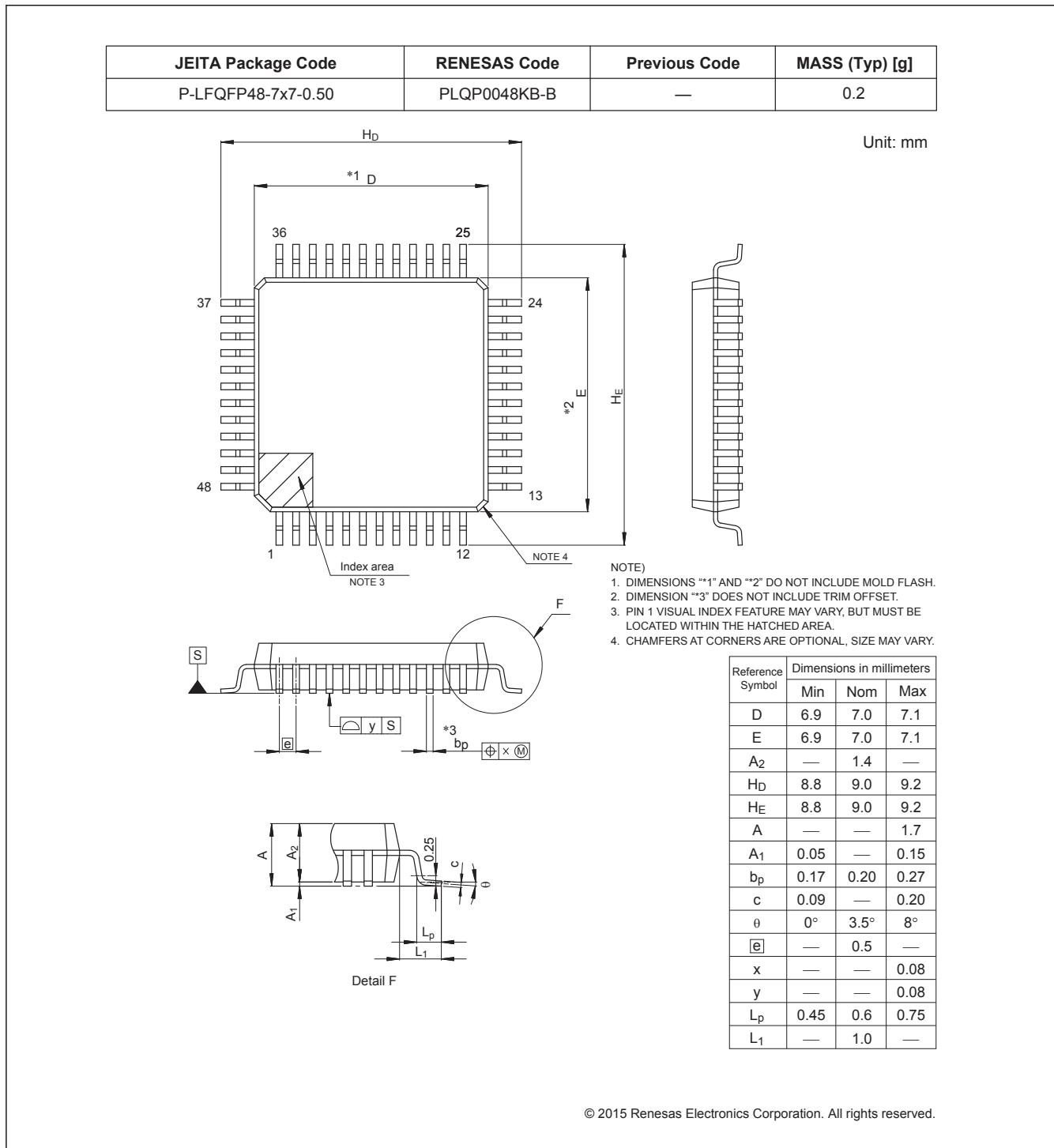
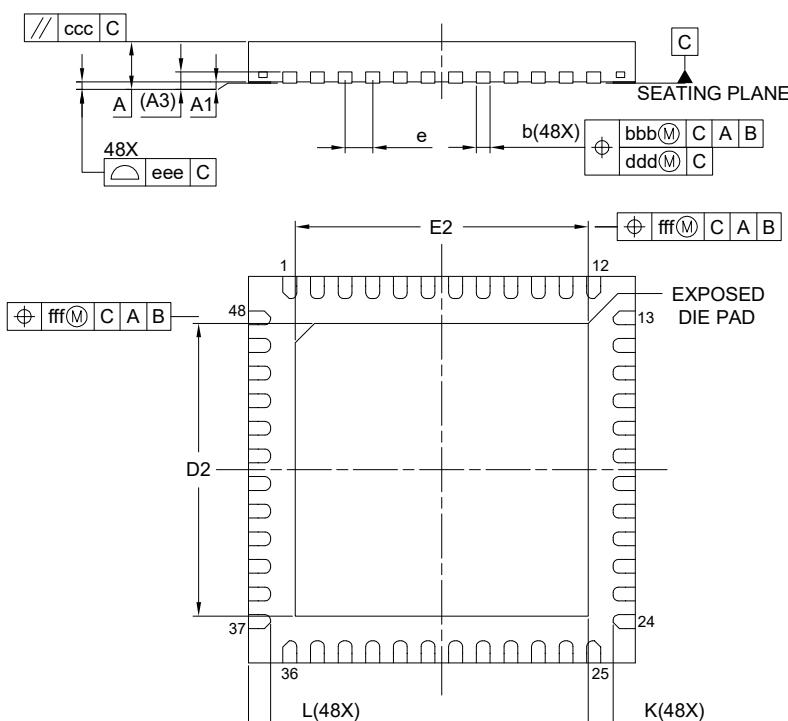
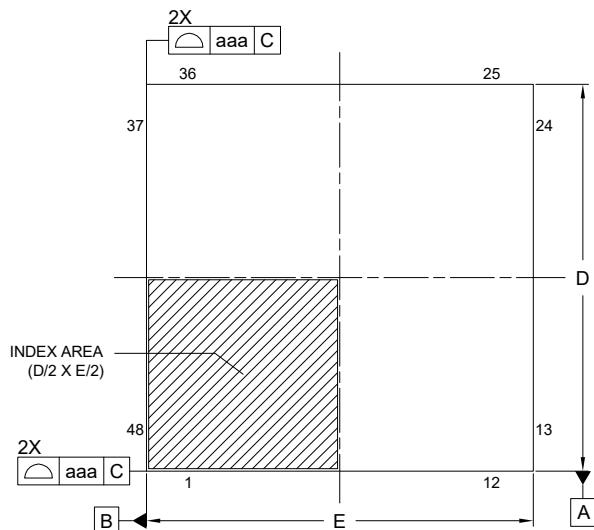


Figure A2.1 LQFP 48-pin

JEITA Package code	RENESAS code	MASS(TYP.)[g]
P-HWQFN048-7x7-0.50	PWQN0048KC-A	0.13 g



Reference Symbol	Dimension in Millimeters		
	Min.	Nom.	Max.
A	—	—	0.80
A <sub>1</sub>	0.00	0.02	0.05
A <sub>3</sub>	0.203 REF.		
b	0.20	0.25	0.30
D	7.00 BSC		
E	7.00 BSC		
e	0.50 BSC		
L	0.30	0.40	0.50
K	0.20	—	—
D <sub>2</sub>	5.25	5.30	5.35
E <sub>2</sub>	5.25	5.30	5.35
aaa	0.15		
bbb	0.10		
ccc	0.10		
ddd	0.05		
eee	0.08		
fff	0.10		

Figure A2.2 HWQFN 48-pin

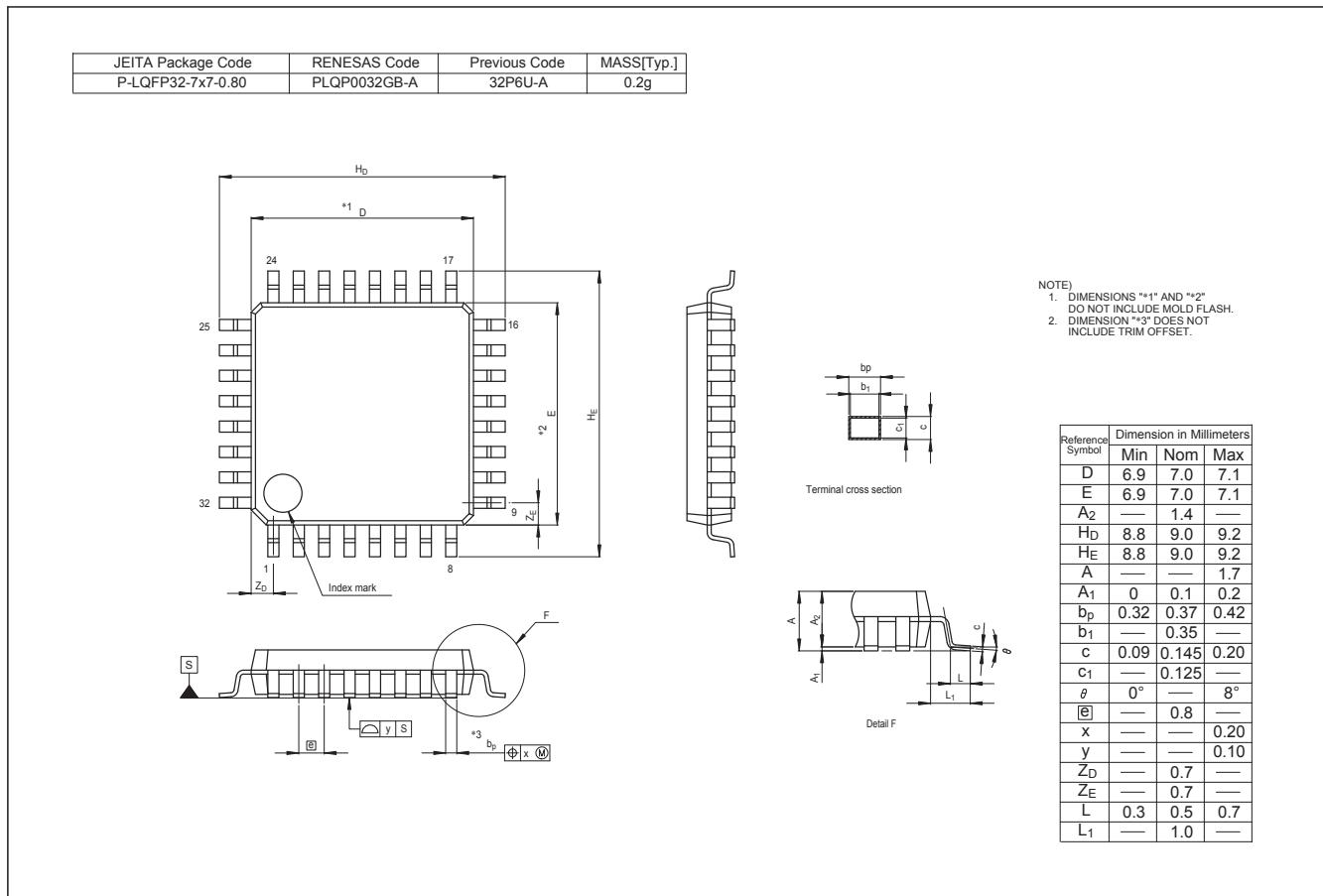


Figure A2.3 LQFP 32-pin

JEITA Package code	RENESAS code	MASS(TYP.)[g]
P-HWQFN032-5x5-0.50	PWQN0032KE-A	0.06

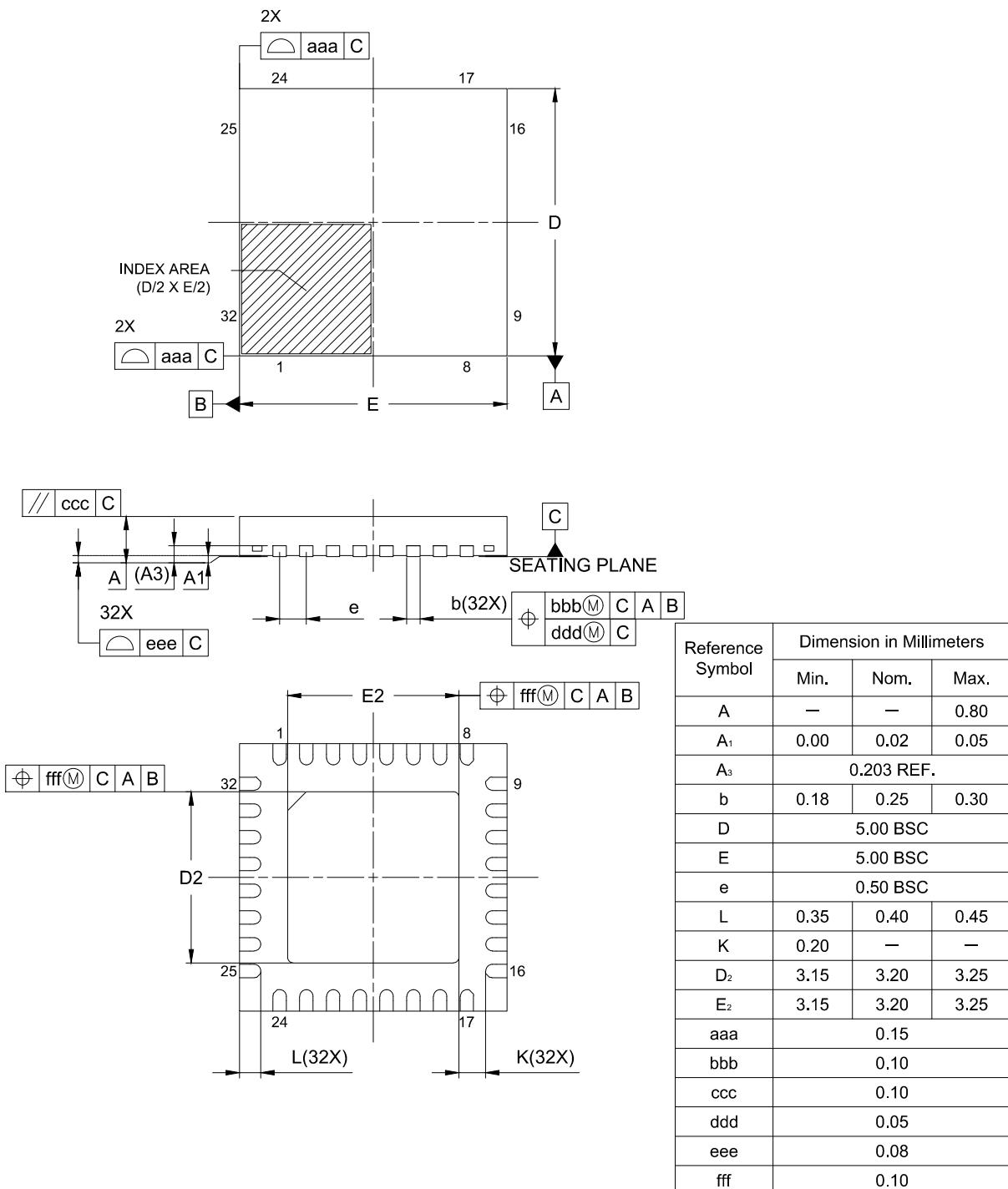
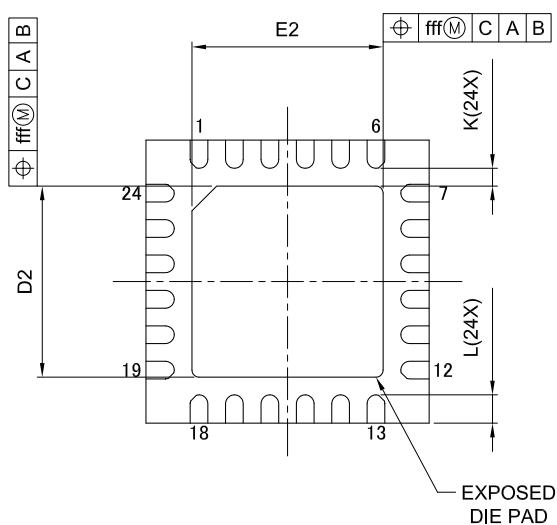
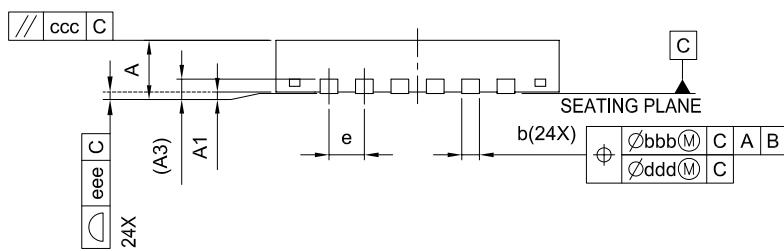
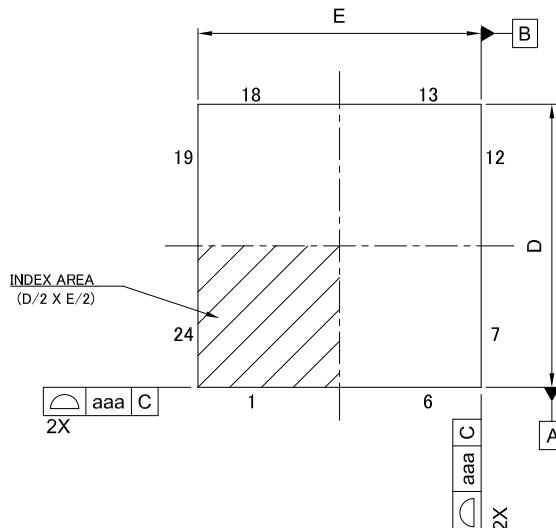


Figure A2.4 HWQFN 32-pin

JEITA Package Code	RENESAS Code	MASS (Typ.) [g]
P-HWQFN24-4×4-0.50	PWQN0024KG-A	0.04



Reference Symbol	Dimension in Millimeters		
	Min.	Nom.	Max.
A	—	—	0.80
A <sub>1</sub>	0.00	0.02	0.05
A <sub>3</sub>	0.203 REF.		
b	0.18	0.25	0.30
D	4.00 BSC		
E	4.00 BSC		
e	0.50 BSC		
L	0.35	0.40	0.45
K	0.20	—	—
D <sub>2</sub>	2.65	2.70	2.75
E <sub>2</sub>	2.65	2.70	2.75
aaa	0.15		
bbb	0.10		
ccc	0.10		
ddd	0.05		
eee	0.08		
fff	0.10		

Figure A2.5 HWQFN 24-pin

## Appendix 3. I/O Registers

This appendix describes I/O register addresses, access cycles, and reset values by function.

### 3.1 Peripheral Base Addresses

This section provides the base addresses for peripherals described in this manual.

[Table A3.1](#) shows the name, description, and the base address of each peripheral.

**Table A3.1 Peripheral base address (1 of 2)**

Name	Description	Base address
RMPU	Renesas Memory Protection Unit	0x4000_0000
SRAM	SRAM Control	0x4000_2000
BUS	BUS Control	0x4000_3000
DTC	Data Transfer Controller	0x4000_5400
ICU	Interrupt Controller Unit	0x4000_6000
DBG	Debug Function	0x4001_B000
SYSC	System Control	0x4001_E000
PORT0	Port 0 Control Registers	0x4004_0000
PORT1	Port 1 Control Registers	0x4004_0020
PORT2	Port 2 Control Registers	0x4004_0040
PORT3	Port 3 Control Registers	0x4004_0060
PORT4	Port 4 Control Registers	0x4004_0080
PORT5	Port 5 Control Registers	0x4004_00A0
PORT9	Port 9 Control Registers	0x4004_0120
PFS	Prmn Pin Function Control Register	0x4004_0800
ELC	Event Link Controller	0x4004_1000
POEG	Port Output Enable Module for GPT	0x4004_2000
WDT	Watchdog Timer	0x4004_4200
IWDT	Independent Watchdog Timer	0x4004_4400
CAC	Clock Frequency Accuracy Measurement Circuit	0x4004_4600
MSTP	Module Stop Control B, C, D, Low Speed Module R/W Disable Control	0x4004_7000
IIC0	Inter-Integrated Circuit 0	0x4005_3000
IIC0WU	Inter-Integrated Circuit 0 Wakeup Unit	0x4005_3014
DOC	Data Operation Circuit	0x4005_4100
ADC120	12-bit A/D Converter	0x4005_C000
SCI0	Serial Communication Interface 0	0x4007_0000
SCI1	Serial Communication Interface 1	0x4007_0020
SCI2	Serial Communication Interface 2	0x4007_0040
SCI9	Serial Communication Interface 9	0x4007_0120
SPI0	Serial Peripheral Interface 0	0x4007_2000
CRC	Cyclic Redundancy Check	0x4007_4000
KINT	Key Interrupt Function	0x4008_0000
AGTW0	Low Power Asynchronous General Purpose Timer 0	0x4008_4000
AGTW1	Low Power Asynchronous General Purpose Timer 1	0x4008_4100
ACMPHS	High-Speed Analog Comparator	0x4008_5E00

**Table A3.1 Peripheral base address (2 of 2)**

Name	Description	Base address
GPT160	General PWM 16-bit Timer 0	0x4008_9000
GPT161	General PWM 16-bit Timer 1	0x4008_9100
GPT162	General PWM 16-bit Timer 2	0x4008_9200
GPT163	General PWM 16-bit Timer 3	0x4008_9300
GPT_OPS	Output Phase Switching Controller	0x4008_9A00
FLCN	Flash I/O Registers, Memory Wait Cycle Control, Temperature Sensor Calibration Data	0x407E_C000

Note: Name = Peripheral name

Description = Peripheral functionality

Base address = Lowest reserved address or address used by the peripheral

### 3.2 Access Cycles

This section provides access cycle information for the I/O registers described in this manual.

The following information applies to [Table A3.2](#):

- Registers are grouped by associated module.
- The number of access cycles indicates the number of cycles based on the specified reference clock.
- In the internal I/O area, reserved addresses that are not allocated to registers must not be accessed, otherwise operations cannot be guaranteed.
- The number of I/O access cycles depends on bus cycles of the internal peripheral bus, divided clock synchronization cycles, and wait cycles of each module. Divided clock synchronization cycles differ depending on the frequency ratio between ICLK and PCLK.
- When the frequency of ICLK is equal to that of PCLK, the number of divided clock synchronization cycles is always constant.
- When the frequency of ICLK is greater than that of PCLK, at least 1 PCLK cycle is added to the number of divided clock synchronization cycles.

Note: This applies to the number of cycles when access from the CPU does not conflict with the instruction fetching to the external memory or bus access from other bus master such as DTC.

[Table A3.2](#) shows the register access cycles for non-GPT modules.

**Table A3.2 Access cycles for non-GPT modules (1 of 2)**

Peripherals	Address		Number of access cycles						Related function	
			ICLK = PCLK		ICLK > PCLK <sup>*1</sup>		Cycle unit			
	From	To	Read	Write	Read	Write				
MPU, SRAM, BUS, DTC, ICU, CPU_DBG	0x4000_2000	0x4001_BFFF	3		3		ICLK	Memory Protection Unit, SRAM, Buses, Data Transfer Controller, Interrupt Controller, CPU, Flash Memory		
SYSC	0x4001_E000	0x4001_E6FF	4		4		ICLK	Low Power Modes, Resets, Low Voltage Detection, Clock Generation Circuit, Register Write Protection		
PORTn, PFS, ELC, POEG, WDT, IWDT, CAC, MSTP	0x4004_0000	0x4004_7FFF	3		2 to 3		PCLKB	I/O Ports, Event Link Controller, Port Output Enable for GPT, Watchdog Timer, Independent Watchdog Timer, Clock Frequency Accuracy Measurement Circuit, Module Stop Control		

**Table A3.2 Access cycles for non-GPT modules (2 of 2)**

Peripherals	Address		Number of access cycles					
			ICLK = PCLK		ICLK > PCLK <sup>*1</sup>		Cycle unit	Related function
From	To	Read	Write	Read	Write			
IICn (n = 0), IIC0WU, DOC, ADC12	0x4005_0000	0x4005_EFFF	3		2 to 3	PCLKB	I <sup>2</sup> C Bus Interface, Data Operation Circuit, 12-bit A/D Converter	
SCIn (n = 0 to 2, 9 <sup>*2</sup> )	0x4007_0000	0x4007_0EFF	5		2 to 3	PCLKB	Serial Communications Interface	
SPI <sub>n</sub> (n = 0) <sup>*3</sup>	0x4007_2000	0x4007_2FFF	5		2 to 3	PCLKB	Serial Peripheral Interface	
CRC	0x4007_4000	0x4007_4FFF	3		2 to 3	PCLKB	CRC Calculator	
GPT16n (n = 0 to 3), GPT_OPS	0x4008_9000	0x4008_9FFF	See <a href="#">Table A3.3</a> .			PCLKB	General PWM Timer	
KINT	0x4008_0000	0x4008_2FFF	3		2 to 3	PCLKB	Key interrupt Function	
AGTWn	0x4008_4000	0x4008_4FFF	3		2 to 3	PCLKB	Low Power Asynchronous General Purpose Timer	
ACMPHS	0x4008_5E00	0x4008_6FFF	3		2 to 3	PCLKB	High-speed Analog Comparator	
FLCN	0x407E_C000	0x407E_FFFF	7		7	ICLK	Data Flash, Temperature Sensor, Capacitive Sensing Unit 2, Flash Control	

Note 1. If the number of PCLK cycles is non-integer (for example 1.5), the minimum value is without the decimal point, and the maximum value is rounded up to the decimal point. For example, 1.5 to 2.5 is 1 to 3.

Note 2. Regarding n = 0, when accessing a 16-bit register (FTDRHL, FRDRHL, FCR, FDR, LSR, and CDR), access is 2 cycles more than the value shown in [Table A3.2](#). When accessing an 8-bit register (FTDRH, FTDRL, FRDRH, and FRDRL), the access cycles are as shown in [Table A3.2](#).

Note 3. When accessing the 32-bit register (SPDR), access is 2 cycles more than the value in [Table A3.2](#). When accessing an 8-bit or 16-bit register (SPDR\_HA), the access cycles are as shown in [Table A3.2](#).

[Table A3.3](#) shows register access cycles for GPT modules.

**Table A3.3 Access cycles for GPT modules**

Frequency ratio between ICLK and PCLK	Number of access cycles			Cycle unit
	Read		Write	
ICLK > PCLKD = PCLKB	5 to 6		3 to 4	PCLKB
ICLK > PCLKD > PCLKB	3 to 4		2 to 3	PCLKB
PCLKD = ICLK = PCLKB	6		4	PCLKB
PCLKD = ICLK > PCLKB	2 to 3		1 to 2	PCLKB
PCLKD > ICLK = PCLKB	4		3	PCLKB
PCLKD > ICLK > PCLKB	2 to 3		1 to 2	PCLKB

## Revision History

**Revision 1.00 — Jun 25, 2025**

Initial release

# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

## 1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity.

Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

## 2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

## 3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

## 4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

## 5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

## 6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

## 7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

## 8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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